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RESEARCH AND DEVELOPMENT OF REFRACTORY OXIDATION RESISTANT DIBORIDES

Edward V. Clougherty David Kalish Edward T. Peters

ManLabs, Inc.

TECHNICAL REPORT AFML-TR-68-190

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Air Force Materials Laboratory
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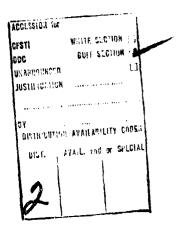
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FOREWORD

This report was prepared by the Research Division, ManLabs, Inc., with the assistance of Avco Space Systems Division and Battelle Memorial Institute, subcontractors on this program, under U. S. Air Force Contract No. AF33(615)-3671. The contract was initiated under Project 7350, "Refractory Inorganic Nonmetallic Materials", Task 735001, "Refractory Inorganic Nonmetallic Materials: Non-Graphite." The work was administered under the direction of The Air Force Materials Laboratory with John R. Fenter acting as project engineer.

This report covers the period from 15 March 1966 to 15 September 1967.

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Battelle personnel included D. E. Niesz and W. Duckworth.

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This technical report has been reviewed and is approved:

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ABSTRACT

The oxidation, mechanical and physical properties of zirconium diboride and hafnium diboride and composites prepared from these diborides with appropriate additives, have been determined as a function of composition, microstructure and test temperature. The composites were designed to enhance oxidation resistance, strength and thermal stress resistance without sacrificing high temperature stability; the principal additives were silicon carbide or graphite.

Several hundred diboride billets, in sizes from two inches diameter to six inches square, were fabricated by conventional hot pressing. All hot pressed billets were subjected to extensive nondestructive testing correlations and flaw identification criteria. A unique role for ceramic additives has evolved in enhancing the fabricability of diboride materials and producing fine grained crack free billets. All powder materials and hot pressed microstructures subjected to properties evaluations have undergone extensive characterization through qualitative and quantitative chemical analyses, phase analyses and grain size and density measurements.

An exploratory fabrication effort was initiated to develop alternate means to hot pressing for producing dense diboride materials; hot forging, plasma spraying and sintering are being studied. In addition, the hot pressing of diboride compositions containing additives such as SiC whiskers, carbon filaments or tungsten filaments is being studied.

Oxidation screening evaluations were performed in hot sample cold gas furnace tests in which low velocity air at a linear flow rate of 0.9 ft/sec is passed over specimens at temperatures from 1700° to 2200°C. The beneficial effect of SiC in reducing the rate of diboride oxidation and increasing the adherence characteristics of protective oxide coatings was confirmed and extended in temperature range and composition. The introduction of graphite, for improved thermal stress resistance, detracts from the oxidation resistance. Hafnium diboride compositions display superior oxidation resistance to analogous zirconium diboride compositions.

Mechanical properties screening evaluations, comprising bend strength measurements up to 1800°C and static elastic modulus measurements up to 1400°C, were performed for selected diboride compositions with variations in porosity and grain size. The fine grained fully dense diboride composite compositions possess the highest elevated temperature strengths; bend strengths of 40,000 to 60,000 psi at 1800°C are found in several compositions. Forosity and graphite substantially reduce the Young's modulus of HfB2 and ZrB2 from the 70 to 80 x 10° psi level whereas SiC does not significantly alter the composite modulus. The temperature and strain rate dependence for the onset of plasticity are being established; all compositions have shown limited plasticity in bending at 1800°C.

Preliminary steady state thermal stress resistance measurements were performed in which hollow cylindrical specimens are heated by a concentrically

ABSTRACT (CONT)

positioned carbon rod in order to induce thermal stresses sufficient to cause brittle failure. Transient thermal stress data of materials from this program are being obtained in a variety of hot gas/cold sample are plasma evaluations under a separate study.

The results of the current program provide an increased confidence in the choice of a diboride material as a monolithic ceramic body for applications in environments which will produce thermal stresses and surface oxidation.

Distribution of this report is limited for the protection of technology relating to critical materials restricted by the Export Control Act.

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I. INTRODUCTION AND SUMMARY

A. Introduction

The diborides of zirconium and halidum have been identified as excellent candidate materials for applications involving exposure to oxidizing environments at elevated temperatures. A previous investigation of diboride materials showed that the oxidation resistance of the refractory diborides decreased in the order HfB2<ZrB2<TiB2<TaB2<NbB2; extensive thermodynamic data were presented and reviewed (1*). Subsequently, extensive oxidation evaluations confirmed the superior oxidation resistance of HiB2 over ZrB2 and demonstrated that metal rich compositions of HfB2 or ZrB2 were more oxidation resistant and possessed higher thermal stability than boron rich compositions of the same diboride (2). More recently, the oxidation characteristics of polycrystalline microstructures of ZrB2 and HfB2 containing various additives were investigated; the oxidation behavior was studied in hot sample/cold gas furnace tests in which air was passed over the sample at low velocities (3). The addition of SiC as a second phase constituent substantially improved the oxidation resistance of ZrB2 and HfB2. Additional oxidation characteristics were obtained from a limited number of hot gas/cold sample, arc plasma tests in which hot air was passed over the sample at subsonic and supersonic velocities. In these arc plasma evaluations, the HfB2 was again more oxidation resistant than the ZrB2. No thermal stress failures were encountered in forty arc plasma tests. Bend strength data were also obtained for ZrB2 and HfB2 from room temperature to 1400°C.

The present program was undertaken to prepare a number of diboride materials containing either ZrB2 or HfB2 as the principal component with selected additives designed to enhance one or more of the following: oxidation resistance, mechanical properties and thermal stress resistance. Diboride materials, including ZrB2 and HfB2 with no additive, are being fabricated with microstructural variations of grain size and porosity. Billets are prepared by conventional hot pressing procedures suitable for the production of components such as nose caps, leading edges, vanes and similar objects anticipated for use in high velocity flight or re-entry conditions. The program is broadly divided into three phases: (1) composition and microstructure screening, (2) extensive properties testing and (3) simulated application evaluations and verification of properties in scaled-up fabrication. In Phase One, oxidation, mechanical and thermal screening tests of a wide range of compositions and microstructures are being used to select a limited number of particularly attractive diboride materials. In Phase Two, the selected compositions and microstructures are being fully characterized over a wide temperature range in terms of oxidation resistance, strength, elastic modulus, linear expansion, thermal conductivity and steady state thermal stress resistance. Finally, in Phase Three these properties will be redetermined for materials prepared in scaled up billet sizes and a leading edge configuration will be subjected to simulated hypersonic flight heating conditions of varying severity.

Underscored numbers in parentheses designate References given at end of report.

It is anticipated that at the completion of the program, sufficient powder material procurement and characterization information, fabrication technology, physical, mechanical and oxidation property data and thermal stress resistance performance data will be available so that future utilization or diboride materials for a particular application can be readily achieved with a minimum of additional required data. Appropriate information is being generated to ascertain property trade off consequences which may be utilized in developing optimized materials for specific applications, or which may be necessary if other fabrication techniques must be employed.

B. Summary

Zirconium and hafnium diboride powders were procured in several lots ranging from fifty to three hundred pounds. Additive material procurements included silicon carbide powders and fibers, hafnium silicide and boron silicide powders, hafnium metal, hafnium-tantalum alloy and chromium metal powders, tungsten filament, Poco graphite and Cabot Regal carbon powder and Thornel 25 graphite fibers.

Several hundred diboride billets were fabricated with and without one or more of the above additives by conventional hot pressing procedures. The diboride materials fabricated include the following basic compositions which are identified by roman numerals: Material I, ZrB2 with no additive; Material II, HfB2 with 20 v/o SiC; Material IV, HfB2 with 30 v/o SiC; Material V, ZrB2 with 20 v/o SiC; Material VI, HfB2 with 4 v/o Hf-Ta alloy; Material VIII, ZrB2 with 14 v/o SiC and 30 v/o C; Material X, ZrB2 with 20 v/o SiB6; and Material XII, ZrB2 with 50 v/o C. Additional billets having variations from the basic compositions were also fabricated. The majority of the billets were 2.0 inch diameter by 0.7 inch high, although several dozen 3.0 inch diameter x 1.0 inch high and about a dozen 5.75 inch square by 0.75 to 1.5 inch high billets were also prepared. All hot pressed billets were subjected to extensive non-destructive testing evaluations to provide sufficient data for subsequent development of property correlations and flaw identification criteria. These evaluations are being performed under a separate program (4).

Considerable difficulty was encountered in the fabrication of crack free billets of Materials I and II, which do not contain intentional additives. Furthermore, fully dense billets of Materials I and II could not be prepared without significant grain growth. A unique role for caramic additives in enhancing densification by hot pressing, heretofore not fully understood nor exploited, was found. The incidence of cracking was virtually eliminated for composite compositions based on either ZrB2 or HfB2; this effect is particularly well documented for additions of SiC, C or both SiC + C. High density fine grained diboride microstructures were hot pressed and characterized in terms of chemistry, density, grain size and phase analysis. The various intentional additives to the diborides also resulted in apparent reductions of the impurity phases found in the as-received diboride powders.

An exploratory fabrication effort was undertaken to develop alternate means to hot pressing for producing dense diboride materials; hot forging, plasma spraying and sintering are being studied. In addition, the hot pressing of composite

compositions containing additives not in powder form has been attempted; the materials that were prepared include Material V with SiC whiskers, Material XII with Thornel 25 yars and a Material XIII centaining ZrB₂ with W filaments.

Phase One screening evaluations were performed on diboride compositions representing variations in porosity, grain size and chemical composition. Specimens were subjected to thermal, oxidation and mechanical tests in order to select a limited number of microstructures for more extensive properties measurements in Phase Two.

Thermal screening evaluations were performed in argon and at 10⁻⁵ torr vacuum at temperatures up to 2300°C. Screening evaluations at 2300°C for 15 minutes in argon revealed no change in the initial microstructures of Materials I, II, III, IV, V and XII. Surface depletion zones of additive phases at depths of 15 to 50 mils were found for Material VIII and second phase melting was observed in Material X. Melting data obtained on hot pressed samples from several different lots of ZrB₂ and HfB₂ powders indicated incipient melting temperatures consistent with identified oxide and carbide impurity phases. Complete melting was observed at 3075° to 3095°C for three different high purity ZrB₂ materials and at 3345°C for one high purity HfB₂ material.

Oxidation screening evaluations are performed in hot sample/cold gas furnace tests in which low velocity air at a linear flow rate of 0.9 ft/sec STP is passed over the specimen (0.35 inch diameter by 0.35 inch high) at temperatures from 1700° to 2200°C for 30 or 60 minutes. Oxidation characteristics are determined by post oxidation metallographic analysis which yields measurement of the depth of conversion of diboride to oxide, observation of adherence characteristics of oxide coatings and determination of high temperature limit for the formation and retention of a protective oxide for 30 to 60 minutes. Hafnium diboride displayed better oxidation resistance than zirconium diboride at all temperatures in agreement with earlier results (2); the high temperature limit for protective oxide formation was 1875°C for ZrB₂ and 2050°C for HfB₂. Previously reported (3) enhancement of diboride oxidation resistant characteristics by the introduction of SiC were confirmed and extended in Materials III, IV and V. The adherence characteristics of the oxide produced in the latter materials is improved relative to ZrB2 and HfB2 with no additive and protective oxide formation is extended to a temperature limit of 2000°C for Material V and was observed up to 2100°C for Materials III and IV. Preferential oxidation of SiC was observed at all temperatures; this phenomenon leads to the occurrence of three discreet zones in an oxidized specimen: the outer oxide, the diboride plus void zone and the unaltered diboride plus SiC matrix. The introduction of C detracts from oxidation resistance, as in Materials VIII and XII, which were formulated to maximize thermal stress resistance. Material VIII with 14 v/o SiC and 30 v/o C is more oxidation resistant than Material I but less than Material V. Material XII with 50 v/o C is substantially less exidation resistant than Material I; reduction of C to 20 and 5 v/o renders Material XII competitive with Material I. Addition of SiB to ZrB2, Material X, extended the range of protective oxide formation to 1925°C but did not improve oxidation resistance at lower temperatures; addition of Cr to ZrB2, Material XI, lowered the oxidation resistance of ZrB2. Addition of Hf-27Ta to HfB2, Material VI, showed no appreciable effect on the oxidation resistance of HfB2.

Mechanical acreening evaluations, comprising transverse bend strength measurements from room temperature to 1800°C and static elastic modulus measurements from room temperature to 1400°C, are being performed for selected diboride compositions of several microstructural variations in grain size and porosity in Phase One. The effects of grain size ranges of 6 to 40 microns, for Materials I and IL and 5 to 10 microns for Materials III, IV and V and porosities from 0 to 15 per cent have been evaluated. Materials I and II display peak strengths at 800°C; Materials III, IV and V show relatively flat temperature bend strength curves up to 1800°C. Bend strengths of 40,000 to 55,000 psi have been obtained with the fully dense fine grained compositions of Materials III, IV These strengths are substantially higher than those of Materials I and II at 1400°C and 1800°C. Young's modulus values of 70 to 80 x 106 psi were obtained for the fully dense diboride materials. Porosity substantially reduces the elastic modulus, whereas additions of SiC do not significantly alter the diboride modulus. Currently, the temperature and strain rate dependence for the onset of plasticity are being established; all compositions have shown limited plasticity in bending at 1800°C.

Preliminary steady state thermal stress resistance measurements were initiated to obtain experimental data on the response of several of the diboride materials to the selected evaluation technique in which hollow cylindrical specimens are heated by a concentrically positioned carbon rod to induce thermal stresses sufficient to cause brittle fracture. The initial results suggest that sufficient plastic strain occurs during the slow heating cycle at temperatures as low as 1275°C to prevent fracture due to the thermal stresses. Transient thermal stress data for many high temperature materials including the diborides developed in this study are being obtained in a variety of hot gas/cold sample are plasma evaluations under a separate investigation (5).

The combined results of the current program strongly suggest increased confidence in the choice of diboride material as a monolithic ceramic body for applications in environments which will produce thermal stresses and surface oxidation. Such materials can be recommended for aerospace applications, particularly when the application requires retaining a specific geometry such as the radius of leading edge or nose tip for long periods of time. Diboride materials can now be considered for nonaerospace applications for which oxides, boron carbide and silicon carbide have been the leading candidates. Such applications include extrusion dies and liners for working of aerospace alloys and stainless steel, drawing dies, turbine engine parts or other components subject to combinations of abrasive wear, thermal stress and elevated temperature. The success of the ceramic additive approach has eliminated the need for the consideration of low melting metal additives as a means of enhancing consolidation; material fabricated with metallic binders would of course have limited high temperature properties and be less oxidation resistant than the base diborides. Ceramic additives can now be considered for other ceramic systems to enhance fabricability, improve properties and adjust chemical composition.

II. OPERATIONAL PROCEDURES AND PROGRAM MANAGEMENT

This program is a materials research, development and evaluation effort directed and co-ordinated by a prime contract to ManLabs, Inc., Dr. Edward V. Clougherty, Principal Investigator. ManLabs, Inc. provides technical and administrative management and is also responsible for materials procurement and several experimental tasks. Subcontracting services and evaluations are being obtained, or planned, from Avco Space Systems Division, Battelle Memorial Institute, Bell Aerosystems Company, Atomics International Division of North American-Rockwell Corp., The Carborundum Company and the Raytheon Research Division.

Technical management responsibilities at ManLabs are provided by Drs. Edward V. Clougherty and David Kalish. This task includes direction of materials procurement, initiation and supervision of subcontracting efforts and co-ordination and integration of program results with other directly related current Air Force programs. A breakdown of organizational responsibilities is provided in Table 1.

Individual responsibilities for specific tasks and subcontract descriptions are as follows:

Dr. Edward T. Peters of ManLabs supervises materials characterization, thermal and oxidation evaluations and complementary service support for the entire program which includes among other things chemical analyses, X-ray diffraction and electron microprobe analyses.

Avco/Space Systems Division subcontract is directed by Dr. Russell J. Hill and William H. Rhodes; Dr. Thomas Vasilos provides technical consultation. An extensive fabrication effort is being expended which includes hot pressing as the principal method and several other methods including plasma spraying, hot forging and sintering. Avco performs complete metallographic analysis of all billets fabricated. Nondestructive testing services are also provided by Avco under AF33(615)-3942, "Nondestructive Methods for the Evaluation of Graphite and Ceramic Type Materials", Russell C. Stinebring, Supervisor. Mechanical property measurements and emittance determinations are also performed. Dr. David Kalish of ManLabs provides technical liason for the Avco subcontract.

Pyrolytic deposition procedures for boride materials will be pursued in a subcontract to the Raytheon Research Division under the direction of Dr. James Pappis.

Thermal diffusivity data will be obtained in a subcontract to Atomics International under the supervision of Dr. C. A. Smith.

Steady state thermal stress resistance evaluations are being performed at Battelle Memorial Institute under Dr. Dale E. Niesz.

Transient thermal stress behavior are being obtained from dynamic air oxidation evaluations performed in arc plasma tests under a concurrent

ManLabs' program, AF33(615)-3859, "Stability Characterization of Refractory Materials Under High Velocity Atmospheric Flight Conditions", Dr. Larry Kaufman, Principal Investigator.

Simulated leading edge evaluations will be performed in a subcontract to Bell Aerosystems Co. under the direction of Mr. Frank Anthony.

III. MATERIALS PROCUREMENT, CHARACTERIZATION AND IDENTIFICATION

A. Introduction

The zirconium and hafnium diboride materials for this program were generally procured as powder in fifty to several hundred pound lots with realistic purity specifications set in accordance with the required quantities, the anticipated contaminant materials, the state of the art of diboride powder production and cost factors. Powder production processes employ the metal oxide as a starting material and boron carbide, crystalling boron, or a combination of boron oxide and carbon as the source of boron. Accordingly, the price and availability of hafnium diboride are determined by availability of and requirements for hafnium oxide for preparing this and other hafnium-base materials such as hafnium metal alloys. In general, one hundred pound lots were purchased at prices from \$75 to \$120 per pound for hafnium diboride and \$8 to \$10 per pound for zirconium diboride. The latter is readily available and has been prepared in larger batches than hafnium diboride. Considerable variation was found in different lots from the same manufacturer allegedly following the same production process. Some powder variations were found to influence certain material properties including thermal stability and hot pressing characteristics.

A limited number of diboride materials were procured as hot pressed billets to provide a comparison for materials fabricated in the program. Diboride powders for these pressings were either taken from the fabricator's stock or supplied by ManLabs.

B. Material Identification

A number of diboride compositions based on zirconium and hafnium diboride were designed with various additives to improve one or more of the following properties or characteristics: oxidation resistance, mechanical properties, thermal stress resistance. Compositions selected for evaluation in the Phase One screening are provided in Table 2. Roman numerals are used to identify phase constitution and a base composition. The latter was changed for some materials as the program developed.

C. Material Characterization

1. General Powder Characterization Procedures

Physical and chemical characterizations specifically obtained for zirconium and hafnium diboride, but generally applicable in entirety or in part to other refractory materials include the following:

(a) Emission spectrographic analyses are obtained to check qualitatively the presence of metallic impurities which can in turn be related to raw materials, powder processing or particle size reduction. The presence of hafnium in sirconium compounds and particularly, of sirconium in hafnium compounds is generally expected as 1 to 3 per cent; careful interpretation of emission spectra is needed to distinguish these very similar metals and estimate their relative contents.

- (b) Quantitative chemical analyses are obtained for the principal metal (Hf or Zr), boron, oxygen and carbon. In addition, quantitative analyses are also obtained for any impurity qualitatively indicated at 0.1 per cent or higher by the emission spectra. A phase assay is calculated for the powder on the basis of the chemical analyses and other characterization results.
- (c) X-ray diffraction analyses are used to identify the diboride phase and major impurity phases such as metal oxides and metal carbide. Light element-containing phases such as boron carbide, although possibly present in relative large amounts, are difficult to identify in the presence of metal borides, carbides and oxides.
- (d) Powder density determinations are generally performed with an air pycnometer. The powder density of relative high density materials such as hafnium compounds is a sensitive measure of low density impurities, but is a less sensitive measure of metal oxide and carbide impurities in a metal boride powder, as such impurities have similar densities. The powder density is also important for comparison with the measured density of billets fabricated from these powders.
- (e) Powder particle size analyses are determined for as-received and milled materials. The principal particle size reduction method used thus far is fluid energy milling in air. The particle size distribution is determined with U. S. Standard Series Screens and with a Rollar Particle Size Analyzer. The latter is used for the range 40 to 1μ.
- analysis of resulting consolidated billets are obtained. The minimum conditions of time and temperature (and to a lesser extent pressure) in the range 1,000 to 4,000 psi reflect the presence of various impurities which are known to enhance the densification processes. The metallographic phase assay interpreted in the light of possible reactions between the consolidation powders and the hot pressing atmosphere and container material provide a comparison to the phase assay of the starting powders. Quantitative chemical analyses for metal (sirconium or hafnium) boron, carbon and oxygen and X-ray phase identification of the hot pressed billet provide an indication of any reactions which occurred during consolidation. High pressure hot pressing can be employed to provide dense billets for metallographic phase assay and X-ray analysis for direct comparison with powder characteristics.
- (g) Melting point and solidus temperatures and/or impurity phase melting temperatures for samples obtained from the hot pressed billets are determined by a direct observation method. The solidus temperature and/or the melting temperature of the impurity phase is a particularly good technique to confirm minor phase identification. The melting point of the matrix phase provides an indication of composition.

2. Diboride Materials

Zirconium and hafnium diboride powders have been obtained from several supplier-producer companies in fifty to several hundred pound lots to provide an adequate supply of a given lot for a series of fabrication

experiments. Several sources were considered for both ZrB2 and HfB2 in order to both select the most suitable powder and to gain information about the relative capabilities of these producers. Capabilities of particular interest include, but are not limited to, adherence of produced materials to purchase order specifications, maintainance to delivery schedules and reproducibility of production runs.

Request for quotations for 100 pound lots of ZrB2 and HfB2 were issued to U. S. Borax Research Corp., The Carborundum Company, Wah Chang Corp. and Shieldalloy Corp (U. S. distributor for H. C. Starck Berlin). Powder procurements were initiated with 100 pound orders of ZrB2 to U. S. Borax Research Corp. and Shieldalloy Corp., 100 pounds of HfB2 to Wah Chang Corp. and 50 pounds of HfB2 to Shieldalloy. In addition, samples weighing less than 10 pounds were ordered for special lots of 27B2 and for production runs of HiB2 from U. S. Borax Research Corp. Subsequently, a second 100 pound lot of ZrB2 and a 400 pound lot of ZrB2 were procured from U. S. Borax Research Corp. A three hundred pound lot of HfB2 was ordered from Wah Chang Corp. Extensive delays in the delivery of latter has required that the order to the Wah Chang Corp. be changed to 100 pounds and another 100 pound order has been placed with The Carborundum Company. Some delays have also been encountered in the preparation of acceptable ZrB2 and HfB, by H. C. Starck. These delays were caused in part by the attempts of this producer to rigidly follow an early set of diboride powder specifications which restricted the boron to metal ratio to the range 1.7 to 1.9. The initial materials produced did in fact have a boron to metal ratio of 1.6 but such material could not be synthesized without considerable amounts of cubic phase boride. After this specification was relaxed, an acceptable shipment of ZrB2 was prepared and delivered. The original 50 pound order of HfB2 is now being reprocessed. A tentative powder specification is illustrated in Table 3. A complete powder identification chart and a summary of procurement status are provided in Table 4.

Detailed characterization results are presented in Tables 5 through 9 for the four lots of ZrB, and one lot of HfB2 which have been used extensively in the program. Appendix I contains a summary of characterization results for the lots of diboride powders which were obtained in sample quantities, but not used extensively in the program; appropriate discussion of the results and the reasons for rejecting the extensive use of these materials are presented therein. Inspection of the results in Tables 5 through 9 reveals that oxygen and carbon are the principal impurities in the diboride powders. The oxygen is present in the metal oxide, and the carbon is present as metal carbide for metal rich, over-all composition or as boron carbide for boron rich, over-all composition. The ZrB2 obtained from U. S. Borax Research Corp. contained only minor quantities of hafnium; the material from Shieldalloy contained a normal amount of hafnium (1 to 3 per cent) for a relatively high purity powder. All the kafnium diboride material examined contained 1 to 3 per cent zirconium. Other metallic impurities generally conformed to the powder specification, viz., less than 0.1 per cent.

3. Additive Materials

The additives required to formulate the compositions shown in Table 2 include silicon carbide powder and fibers, hafnium metal powder,

hafnium-tantalum alloy powder, hafnium silicide powder, boron silicide powder, Poco graphite powder and Thornel 25 graphite fibers, amorphorous submicron carbon powder, chromium powder and tungsten filament. Procurement information for the additive materials is presented in Table 10. Characterization results are provided in Tables 11 through 14.

D. Procurement and Characterization of Hot Pressed Materials

The procurement of hot pressed billets independent of those prepared in the research and development program at Avco, originally planned for a later stage of the program, was initiated in order to gain earlier assessment of the commercially available material fabricated from a particular supplier's diboride powder. In addition, the relatively high incidence of cracking in unalloyed hot pressed ZrB₂ and HfB₂ experienced in the present program (see Section IV) dictated an investigation of the hot pressing characterisities of the same powders in another hot pressing apparatus. Accordingly, two six inch diameter billets of ZrB₂ were ordered from U. S. Borax Research Corp. and twelve two inch diameter billets of ZrB₂ were ordered from The Carborundum Company. The diboride powder materials for these billets were specified as high purity materials to be supplied by the respective fabricator. In addition, The Carborundum Company agreed to hot press powder from the IO2 and IO3 lots of ZrB₂ powder according to specified conditions of pressure, time and temperature (optical).

One hot pressed billet of ZrB₂, six inch diameter by two inch high, was received from U. S. Borax Research Corp. and forwarded to Avco for NDT confirmation of the visually observed crack-free surface and for radiographic inspection. The latter evaluations confirmed the absence of surface cracks and showed no indication of gross density variations. Subsequently, the NDT measuring techniques were refined and re-examination failed to show any irregularities.

The conditions employed by Carborundum for the fabrication of the two inch diameter billets are presented in Table 15. Characterization results for the billets are also provided. The results of the NDT evaluations show no incidence of cracking for the first group of billets prepared from the IO2 and IO3 powders; circumferential cracks were observed in two of 92% dense billets prepared from the Carborundum powder. Both single billet and triplicate billet pressings were performed by Carborundum. The six billets prepared from the Carborundum powder were fabricated in two triplicate pressings; the six billets prepared from IO2 and IO3 were fabricated by individual pressings. Two final triplicate pressings were performed using conditions to produce fully dense billets of IO2 and IO3 material. All six billets contained radial cracks of varying severity; two billets showed cracks running across the entire diameter. The significance of these results is discussed in Section IV.

IV. HOT PRESSING

A. Fabrication Conditions and Results

Diboride specimens for Materials I through VI, VIII, X and XII were fabricated using graphite die hot pressing techniques described in Appendix II. The hot pressing conditions and results for each material are discussed below.

Air pycnometric powder densities were measured on all as-received powders; these values were used as the theoretical densities or as a basis for calculating theoretical densities for powder mixtures. However, for certain compositions, the powder theoretical density was not equivalent to the observed maximum billet density apparently due to phase changes during hot pressing. In those cases where densities higher than the powder theoretical density were observed in fabricated billets, the maximum experimental density was employed for calculating relative densities. Table 16 presents a summary of powder densities, calculated densities for Materials III through VI, VIII, X and XII and maximum densities obtained to date for all materials examined.

1. Material I

Table 17 lists the fabrication conditions and results for billets fabricated from six different ZrB₂ powders.

The microstructure of Material I fabricated from the 03A powder exhibits a marked difference from that fabricated from 02A powder. The hot pressing characteristics of the two powders are also different. The dominant impurity phase in billets of the 03A powder is a dark gray zirconium dioxide with a reflectivity similar to that shown by the 5 v/o ZrO2 additive in billet 102A D0302. The oxide impurity phase in 103A billets is distributed in two ways: small 1 to 5 micron singularities and large grains closely approaching the grain size of the ZrB₂ matrix, Figure 1. An orange zirconium carbide phase is observed in both the 102A and 103A materials. This carbide phase is distributed as isolated patches in billets of either powder.

A quantitative metallographic phase distribution was conducted on sample 103A D0308. The gray and black phases were counted together because of the tendency for the gray oxide phase to pull out during polishing; it is difficult to metallographically distinguish between residual porosity and pulled out impurity phases. The bulk density of this sample was 6.05 gm/cc which was slightly greater than the pycnometric density for 103A powder (6.038 gm/cc). Accordingly, it was assumed that essentially zero pore phase was present. The combined concentration of the ZrO₂ and ZrC phases are higher by approximately 2% in billet 103A D0308 than in billet 102A D0283, Table 18.

A number of fabrication runs with roughly equivalent time cycles at temperature and pressure are compared in terms of relative density as a function of temperature for Materials 102A and V02A, Figure 2 and Materials 103A and V03A, Figure 3. The fabrication time for the 103A and 102A pressings was 60 minutes at each indicated temperature. The data in these figures show that the

103A powder densifies more rapidly than the 102A powder; this behavior may be attributed to the higher impurity phase content. The impurity phases could act as a high diffusivity or plastic phases for enhanced densification by either of the two most probable pressure sintering mechanisms; stress directed diffusion or plastic flow. (The densification of Material V will be discussed in a subsequent section.)

Four additional experiments were conducted to verify the effect of second phases on the densification behavior of Material I, Table 19. Billets 102A D0302 and 102A D0303 containing intentional 5 w/o additions of ZrO₂ and ZrC, respectively, were consolidated to essentially theoretical density under conditions which resulted in 90% relative density for the as-received 102A powder (cf., 102A D0613). It appears that increased oxide or carbide content in ZrB₂ powder facilitates consolidation by hot pressing.

Two pressings of Material IO2A were made with ZrO2 additions as a means of assessing the possible effects of the crystal structure of the ZrO2 phase which is often present in Material I compositions. Pure ZrO2 undergoes a monoclinic to tetragonal phase inversion at approximately 1000°C which is accompanied by a large volume change. The occurrence of this inversion within a diboride matrix could be the source of cracking or high residual stresses. Stabilization of cubic ZrO₂ can be effected by additions of 6 to 12 mole per cent of certain materials of which Y2O3 is one of the more common. Stabilized ZrO2-Y2O3 was added to pressing 102A D0504 while pure ZrO2 was used in 102A D0505. By a visual inspection both billets appeared uncracked after processing, but during the course of the NDT inspection, the billets were heated in an oven at 200°C to drive off some cleaning solvent. At this time billet 102A D0505 crack I which indicates that high residual stresses were present. These limited experiments suggest that the crystal form of the ZrO2 phase could be an important factor in controlling the incidence of cracking and possibly even the strength of the fabricated billets. It is important to note that the HfO2 phase undergoes an analogous transformation. Accordingly, the impurity phase structure could also be a source of residual stresses in HfB2 base materials.

Several other Material I powders were employed to a limited extent in Phase One of the program. Billets using powders I04 from U. S. Borax, I05 from Shieldalloy, I06 from U.S. Borax and I07 from U.S. Borax were hot pressed and are included in Table 17. The I07 powder is being used as the major source of zirconium diboride for Phases Two and Three. The effect of fluid energy milling is demonstrated by comparing billets I07 D0628F and I07 D0589; the particle size reduction effected through the milling led to enhanced densification. The fluid energy milled I07 powder achieved 100% density at a lower temperature and shorter time than the unmilled powder. Similar effects of particle size reduction were noted for fluid energy milled I02A and I03A powders, e.g., billets I02A D0345F and I03A D0314F. It is not clear whether the milling fractures single crystal diboride grains or breaks up polycrystalline agglomerates in the as-received powders.

Metallographic phase analyses were performed on the additional material microstructures. Material 104 contains the smallest amount of second phase of all the ZrB₂ fabricated; about 7 volume per cent of a light gray

phase. Material 105 contains two impurity phases, between 3 to 9 volume per cent gray ZrO₂ and 11 to 14 volume per cent orange phase; these phases appear as well dispersed grains smaller than the boride grains. The 105 powder was reprocessed by Shieldalloy with the result that 105A material has no measurable second phase. Material 106 exhibited a gray second phase which was distributed as in the 103A microstructure. Not pressed Material 107 often shows a grain orientation such that the length of the tabular grain is orthogonal to the direction of pressing. Otherwise, Material 107 appears similar to 103A, but contains a little more of the orange phase and less gray phase. In terms of the hot pressing behavior the 107 is easily densified to 100% density at conditions comparable to those employed with the 103A powder.

2. Material V

Billets of Material V (ZrB₂ + SiC) were fabricated with the conditions and results listed in Table 20. The ZrB₂ and SiC powders were dry mixed in a shaker mill.

Typical microstructures developed by hot pressing are shown in Figures 4, 5, 6 and 7. Figure 4 illustrates the extent of mixing of the SiC phase. In general, the phases are well dispersed, but several small patches rich in SiC or ZrB_2 are apparent. Figure 5 demonstrates that very few SiC particles are trapped within the ZrB_2 grains. Some SiC agglomerates are apparent, but it is doubtful that this feature could be avoided at this high level of additive concentration (20 v/o). Figures 6 and 7 show the reduced amount of the impurity phases in Material V relative to the amounts observed in the unalloyed Material I. It is thought that the impurities are 'gettered' by the SiC phase; a similar result was found for the HfB2-SiC system as is discussed in Section IV. A7. There was little tendency for radial cracking in the pressed billets of this material.

The base composition studied in Material V contains 20 v/o SiC. However, a series of billets were fabricated where the composition of the silicon carbide was varied from 5 to 50 v/o in a mixture with the 02A ZrB₂ powder. The amount of impurity phases present after hot pressing was determined metallographically. The 9 to 10 v/o impurity phases in the 102A powder were reduced to less than 2 v/o by hot pressing the diboride powder with SiC additions. The quantity of diboride impurity phase remaining as a function of the volume per cent SiC is given in Figure 8; a minimum is observed at 10 to 15 v/o SiC.

The impurity phases remaining in Material V do not appear to wet the SiC, but are generally observed as partially penetrating the diboride grain boundaries, Figure 6. Since the impurity phases are nonwetting with respect to the SiC it is assumed that the reduction in the impurity phase content is due to a chemical reaction (gettering) rather than a physical change such as the formation of a thin film surrounding the SiC grains. A higher per cent of impurity phases is found in V03A, Figure 7, as compared to V02A, Figure 5, due to the higher impurity content of 103A compared with 102A. A special series of billets were hot pressed containing large amounts of the presumed impurity phases, ZrO₂ and ZrC, in an effort to understand the phase changes occurring during the fabrication of Material V. The compositions and pressing conditions of these billets are

given in Table 21. The two component mixtures of SiC-20 v/o ZrC and SiC-20 v/o ZrO₂ were hot pressed to study possible analogous impurity phase-SiC carbide reactions in Material V compositions. X-ray diffraction patterns confirmed the absence of extransous impurities in the powder mixtures in Table 21. After hot pressing, the zirconia phase was not detected by X-ray analysis. However, ZrSi₂ and ZrC phases were identified in billet D0624; this billet did not contain these phases in the starting powders.

The incrostructures of the hot pressed billets listed in Table 21 were analyzed by microhardness measurements and metallographic techniques and the results are given in Table 22. Billet D0624 prepared from ZrO₂ and SiC powders contains three distinct phases identified as ZrSi₂, ZrC and SiC. A dark gray high hardness phase present as the major phase is SiC. The hardness values on the two other phases indicate that the white phase is ZrSi₂, but the value for the third phase of gray color does not agree well with the accepted values for ZrC. Etching helped to confirm the identification since ZrSi₂ and SiC do not react in concentrated nitric acid whereas ZrC is etched. Similar results were obtained with concentrated sulphuric acid as the etchant. When a mixture of hydrofluoric and nitric acid was used on billet D0624, both the ZrC and SiC phases were etched leaving the ZrSi₂ still unaffected.

Billet D0626 prepared from the high purity 05A ZrB2, ZrO2 and SiC produced the same type of reactions as billet D0624 during hot pressing. The resulting microstructure contains four phases, ZrC, ZrSi2 and SiC with ZrB2. The microstructures of billets D0624 and D0626 are shown in Figures 9 and 10. The ZrSi2 phase morphology suggests molten phase formation during fabrication.

Billet V03A D0473 was examined for the silicide phases by electron diffraction using an extraction replication technique. Two phases were identified, Zr₂Si and a Zr-B-Si ternary D8₈ phase as reported by Brukl (6). The lower silicide could be expected to form in the CO reducing atmosphere of hot pressing in the presence of SiC with a small concentration of ZrO₂. Furthermore, it is reasonable that a ternary could be formed when ZrB₂ is present. These compounds with ZrB₂ have minimum incipient melting temperatures of 2312°C(6). The ternary silicide may be the phase which is found when billets have 'reacted' during hot pressing due to exceeding the temperature of 2312°C. In addition to the silicides, ZrC should be formed due to the CO rich hot pressing atmosphere; the special compositions substantiate this supposition.

The orange phase often found in Material I was never observed in any of the special materials, D0623 through D0627. This orange phase is believed to be a zirconium carbide containing some boron. The lack of consistancy in observing the orange phase may be attributed to a high dependence of color on stoichiometry. It has also been suggested that the orange phase is a complex zirconium boride with oxygen (7). The electron beam microprobe analyses performed by ManLabs contradict this latter assumption, but supports the monocarbide containing boron theory.

The influence of the 20 v/o addition of SiC on the hot pressing characteristics of ZrB₂ is illustrated in Figures 2 and 3. The relative densities of hot pressed 02A and 03A powders with and without SiC additions are compared for similar fabrication conditions. The data demonstrate that the addition of SiC enhances the densification of zirconium diboride during hot pressing.

Several problems were encountered during the early fabrication of the large plates (5-3/4 inch squares) of Material V; billet V02A Q2206 cracked during extraction from the die although the billet is fully dense and the SiC phase is uniformly dispersed; billet V02A Q2221 is less dense than was desired, 92.5% and contains a low density 2 inch diameter central core; the edge of the billet V02A Q2225 was contaminated by the BN mold wash. In this last case, the BN wash must have scraped off the die wall during the initial compaction and mixed with the loosely packed V02A powder. These early problems have been overcome and fully dense large plates of Material V are now made reproducibly. Table 20.

3. Material VIII

The Material VIII hot pressing conditions and results are listed in Table 23. Two lots of ZrB_2 were used, the 02A and the 07 powder and the graphite was introduced in one of three forms, Poco graphite, Regal carbon or Aquadag carbon. In many instances the billet density exceeds the theoretical density for the powder mixture indicating that a change in the chemistry has occurred. However, no attempt has been made to determine the identity of the phases in the hot pressed microstructure, Figure 11. The small grain size, about 4 μ and the relatively poor mixing of the SiC with the ZrB_2 , shown in Figure 11 is typical of Material VIII. Figure 12 shows the microstructure of Material VIII containing Regal graphite; an impurity phase reminiscent of that found in Material VO3A, Figure 8 is observed.

Billets 3 inches diameter and 5-3/4 inches square were fabricated from this material. A variable density in the large plate VIII07 Q2301L was indicated radiometrically suggesting that there is a segregation of the phases during handling as powders.

4. Material X

The hot pressing conditions and results for the four billets of Material X are listed in Table 24. The limited availability of suitable SiB₆ powder required for this material has precluded further fabrication. As in the case of Material VIII the high density of billet X07 D0635 indicates that the SiB₆ has reacted with the ZrB₂; theoretical density of Material X is 5.25 gm/cc. The microstructure of billet X07 D0596, Figure 13 shows a third phase present which appears to have been liquid during hot pressing; a homogeneous distribution of phases was developed in this billet. However, the microstructure of billet X07 D0597, Figure 14 contains large aggregates of both the matrix and additive phases. Additional billets are scheduled to be hot pressed and phase analyses of Material X will be performed.

5. Material XII

The Material XII hot pressing conditions and results are listed in Table 25. It was found that the Poco graphite powder could be mixed more easily than the Regal grade. The microstructure of billet XII(20)07 D0608, Figure 15 with segregation of the phases is typical of a billet made with Regal carbon. In comparison, Figure 16 indicates how the Poco powder mixes well to form evenly distributed phases throughout the material. At 2100°C, the powder mixture was found to react forming a liquid phase clearly visible in the resulting microstructure as a gray third phase. After hot pressing at 2050°C only a few areas can be found containing a gray phase. It has been reported (8) that ZrB2 forms eutectic type, pseudo binary with graphite at 2390°C. A fine grain material is produced at 2050°C, the smallest obtained for any material in the program. Comparatively longer pressing times are required for complete densification. The material containing Poco graphite is more difficult to densify than the Regal carbon material.

6. Material II

The Material II hot pressing conditions and results are listed in Table 26. Several hafnium diboride powders were employed for hot pressing experiments; powder lot II05, from Wah Chang, has been the principal source of powder for Material II fabrications. Pressing II05 D0316, 99.3% dense, contains at least one and possibly two impurity phases shown in Figure 17. The major gray impurity phase which tended to pull out during metallographic polishing, occurred in both irregular and spherical shaped grains between 2 and 30 microns in size. A minor grain boundary impurity phase, which was apparently liquid during fabrication was observed in billets fabricated at 2200°C. The quantitative metallographic phase analysis of billet II05 D0316 is presented in Table 27. The hot pressed microstructure contains about 8 v/o of impurity phases principally consisting of a cubic hafnium borocarbide.

The H06 powder, from Shieldalloy, had a high impurity content which was manifested by approximately 31 v/o impurity phases in the hot pressed billet. A finely divided gray phase (17 v/o) and large areas of a very dark gray to black phase (14 v/o) which had a grain size of the same order as the boride phase was observed. The high level of impurities in the H06 powder aided the densification of the material; full density could be obtained at 1950°C compared with 2160° to 2200°C required for the H05 powder. The high impurity phase content correlates with the high carbon and oxygen levels in both the H06 powder and the fabricated billets.

The II07 powder, from U. S. Borax, was used for one hot pressing and there were indications that a reaction occurred during the fabrication. The microstructure was examined and the billet contained approximately 15 v/o of a nonwetting grain boundary phase.

The II08 powder, also from U.S.Borax, gave a microstructure with approximately 5 v/o second phase located at the grain boundaries. This powder was hot pressed to high density under comparable conditions to those employed with the II05 powder.

7. Materials III and IV

The hot pressing conditions and results for the HfB_2 -SiC compositions, Materials III and IV are presented in Tables 28 and 29 respectively. These powders were dry mixed in a shaker mill.

The microstructures produced for fully dense billets of Materials III and IV are shown in Figures 18 and 19. The impurity phases in Materials III and IV have decreased from the 8 v/o level present in the II05 billets. This phenomenon is verified in the quantitative metallographic data reported in Table 27. The impurity phase still remaining, occupies a position adjacent to the SiC phase, and from the apparent contact angle (>90°), it appears to be nonwetting. There is further evidence that the impurity phases are gettered by the SiC rather than occupying some other position such as surrounding the SiC in a thin film which would require a contact angle of $\leq 90^{\circ}$. Similar to the observations on Material V, this gettering of the oxide and carbide impurity phases by the silicon carbide addition may be significant in enhancing the mechanical properties. The SiC phase in Material IV is well dispersed, but because of the high percentage of additive involved there are many aggregates containing several SiC grains.

It is possible to determine the effect of the SiC on the hot pressing characteristics of HfB₂ by comparing hot pressing results for Materials II and III. The relative densities of these materials hot pressed at equivalent temperatures and pressure and similar times are presented in Figure 20. The SiC significantly aids the densification of HfB₂ as well as acting as a getter for the impurities. One striking feature of microstructures of the SiC alloys of both ZrB₂ and HfB₂, that may account for the enhanced densification behavior over the unalloyed materials, is their much smaller grain size. Diffusion models for densification during hot pressing (including Nabarro-Herring creep) are favored by a small particle size. The SiC phase may serve to restrict grain growth and thereby promote densification.

Finally, it is interesting to note that the decrease of the impurities in Materials III, IV and V is accompanied by enhanced densification whereas in Materials I and II impurity phases appear to enhance densification. There are evidently several factors which affect the rate of densification and the addition of SiC to the base materials may serve to influence more than one of these factors.

8. Material VI

The first hot pressings of Material VI were performed with a powder mixture of 96 v/o HfB₂ and 4 v/o of an Hf-27Ta alloy, Table 30. The component powders were dry mixed in a tungsten carbide ball mill at ManLabs. The air pycnometric density of this composition is 10.89 gm/cc. However, one of the first three hot pressings prepared had a density of 10.97 gm/cc. The three

pressings of Material VI gave relative densities of 100, 91 and 62%. fabrication conditions, produce equivalent densities for Material II. The 4 v/o addition of the hafnium-tantalum alloy does not improve the hot pressing characteristics of hafnium diboride, H05. Billet VI05 D0462 (fully dense) contains three phases as shown in Figure 21. The major gray impurity phase normally found in Material II05 is present, although the minor grain boundary phase is not observed. A quantitative metallographic phase determination for sample VI05 D0462 is given in Table 31. The hafnium-tantalum alloy addition lowered the gray phase concentration from 7.8 to 1.7 v/o; this is similar to the effects of the &C additions to ZrB2 and HfB2. Billets VI05 D0461 and VI05 D0462 exhibited different hafnium-tantalum alloy phase morphology. In billet VI05 D0462 the Hf-Ta phase was located as isolated widely spaced grains of about the same size as the matrix, whereas in specimen VI05 D0461, this phase possessed a similar spacing and size, but contained fine precipitates. Knoop microhardness values (100 gram load) of the HfB2 matrix phase and the gray Hf-Ta phase (no apparent precipitates). were measured in billet VI05 D0462 with resultant values of 2380 and 2650 Kg/mm^2 , respectively. The high hardness of the phase produced by the additive indicates that the Hf-Ta has undergone a chemical conversion during fabrication, probably to a boride or a borocarbide of these metals.

B. Furnace Variables and Process Control

The hot pressing furnace used for the fabrication of the 2 and 3 inches diameter billets is described in detail in Appendix II. The fabrication of larger billets in the program is conducted on a scaled-up version of the same apparatus.

Below about 2000°C the operating parameters, including temperature, pressure, and rate of densification can be controlled adequately so that reproducible materials can be obtained. However, when 2000°C is exceeded, the lowering of the creep resistance of graphite now makes close control more difficult to obtain. It is precisely within this range of temperature (above 2000°C) where borides can be successfully hot pressed: this explains why some specimens are not reproducibly densified even within a series of seemingly identical hot pressings. To add to the difficulty, the temperature of the material being hot pressed cannot be measured directly and optical sightings are made on a point within the graphite mold away from the sample. Temperature is measured continuously, however, to monitor power input. It is important to note therefore that the temperatures recorded for hot pressing can only be used for comparisons between the hot pressing characteristics of various materials. Even this relationship is in question when different furnace configurations have been used. However, the hot pressing temperature must be regarded as only an approximation when compared to the true temperature of the billet, or the temperatures measured in the various tests performed in the program,

Finally, it has been found that in a typical graphite hot pressing assembly the atmosphere found in the region of the billet is reducing above 1000° C and consists of a CO rich CO/CO₂ mixture. Carbon rich phases are likely, therefore, to predominate in an equilibrium environment.

C. Nondestructive Testing

Billets fabricated in the first 45 hot pressings of Materials I and II showed a high incidence (15%) of cracking. Consequently, a crack detection screening program was initiated through the Avco Nondestructive Testing Section under a separate program (4). The primary purpose of this NDT program is to identify the presence of cracks in the hot pressed billets in order to allow particular materials and billets to be chosen for the mechanical and oxidation screening programs. Approximately 90% of the billets fabricated were tested in the following manner:

- 1. fluorescent dye penetrant for crack detection and surface inhomogeneities;
- 2. ultrasonic freon bath cleaning for removal of dye penetrant to check for open porosity and
- 3. radiography for density gradients (with either the Avco 150 KV machine or the A. Green Company 1 MEV machine).

Almost without exception, the compositions containing SiC for both ZrB₂ and HfB₂ base materials exhibit no cracking. The graphite die wall/diboride and BN wash/diboride reactions that often occur appear to be associated with the high density rim detected by radiography.

Information concerning the source of cracks was obtained by making correlations with Materials I and II. The parameters considered and the corresponding incidences of cracking are given in Table 32. Certain powders show a greater incidence of cracking, namely, the IO3A and the IIO6 pressings. This indicated that within each material category the powder with the most impurities has the higher tendency for billet cracking. An etched microstructure of IO3A DO415, Figure 22, exhibits cracks radiating from an oxide inclusion. The strong indications of the importance of powder chemistry on the tendency for cracking is supported by the results in Materials III, IV and V. The addition of SiC reduces the volume of impurity phases to less than 2% and virtually eliminates the cracking.

It was not possible to make any other correlations between processing parameters or microstructure and the incidence of cracking; primarily due to the small sampling within each powder lot. The data for the different powder lots could not be combined (for example, to study the effect of billet density on cracking) due to the complicating effects of powder chemistry.

The nondestructive testing program was extended on billets examined after number D0599 in the following ways. A small ground V-mark notch was ground on one edge of each billet and all subsequent tests were referred to this datum mark. If an area of anomalous density showed during radiography, the billet could be cut accurately to show what caused the discrepancy. During the machining for metallography, another cut was added to the billet so that a bar is

cut across the diameter and a view through the billet can be made radiographically as shown in Figure 23. In addition to the radiography and die penetrant, each billet is examined by conductometric, radiometric and ultrasonic velocity measurements to assess variations in these parameters at different locations within each billet. A fixed array of points shown in Figure 24 was oriented with respect to the notch datum point for each billet and the measurements were taken for each indicated point. The array of points used was taken along four diameters spaced at regular intervals of 45°. This fine structure in density, velocity and conductivity was plotted for all billets subsequent to D0597 as indicated in Figures 25 and 26. These results were used in the analysis of a particular billet and will not be reported in detail here.

V. EXPLORATORY FABRICATION

Hot forging, plasma spraying, sintering and the fabrication of filament composite studies were initiated in order to explore the utility of these methods for consolidating diboride materials.

A. Hot Forging

Two hot forgings were conducted in a hot pressing furnace identical to that utilized for billet fabrication except that Poco graphite pistons were used. A previously hot pressed specimen was core drilled to 1.5 inches diameter and forged with the conditions and results listed in Table 33.

The first experiment, billet I05 D0463, was not a true forging because the starting billet was only 79% dense, thus, much of the forging reduction may be attributed to further densification. However, billet I03A D0466 was fully dense and subsequent forging resulted in a 16% height reduction. This height reduction did not show any microstructural texturing and probably would not effect properties; additional hot forging work has been scheduled for several diboride compositions.

B. Plasma Spraying

Preliminary plasma spraying of diborides was accomplished using an Avco Model PG-100 spray gun. Argon carrier gas was used and a variety of substrates were employed. Nine sprayings of Material I and one spraying of Material II were performed with the conditions and results given in Table 34.

The metal substrate surfaces were prepared for plasma spraying by grit blasting with 0.062 inch steel shot. The bonding between coating and substrate remained intact for all runs except 102A P0162 where the coating readily peeled off the substrate. Poor surface cleaning could give rise to a low joining efficiency. The strainless steel substrates were cylindrical and were rotated at approximately 300 rpm during spraying. The other substrates were flat and the gun was traversed during the operation.

The coatings made with a 5 inch gun distance exhibited poor self bonding as demonstrated by a qualitative abrasion test. The shorter gun to substrate distance greatly improved the self bonding and this was apparent in the metallographic examination. Many of the specimens were extremely porous and they all exhibited an impurity phase, presumably an oxide, which was present in a larger volume percentage than in the hot pressed billets of the same material. The microstructure in Figure 27 is a typical dry plasma sprayed layered structure of Material I and contains a high quantity of second phase.

Further plasma work is scheduled and will involve spraying in an argon atmosphere to reduce the impurity level in the coating. Measurements will be made of the bond strength of the coating to substrate and the strength of the sprayed diboride.

C. Sintering

Compression franchis

A sintering program was initiated with the objective of producing diboride specimens with a minimum density of 90%, which could be characterized and tested for comparison with hot pressed material. Initial sintering runs were conducted in a tungsten mesh element vacuum furnace. Temperature was read optically by sighting directly on the sample and correcting for absorption through the sight windows. The processing conditions and results are summarized in Table 35.

The 1/2 inch diameter samples were cold pressed without a binder whereas the 1 inch diameter samples required a polyvinyl alcohol binder to promote adequate green strength for die extraction and handling. Several presintering experiments were conducted to find the correct temperature for binder removal; 400°C for two hours in air was chosen.

The vacuum sintering resulted in significant weight loss, so subsequent experiments were conducted in argon. Sample I03A B005 was quite dense in areas, Figure 28 and had an over-all density of 89%. This structure demonstrates a marked anisotropy of grain size. Small regions of high porosity were macroscopically apparent which may have originated from the accompanying evaporation. Laminations were encountered in specimens B0001 to 5 which were thought to be caused by excess cold pressing pressures. Green densities measured for ZrB₂ pressed at 10,000 and 20,000 psi, were 56.1 and 56.9 per cent. These green densities were considered adequate for sintering to high density. Consequently, the 1 inch diameter specimens were pressed at less than 20,000 psi and with one exception this avoided further cracking.

In general, argon sintering resulted in low density specimens for conditions where 90% relative density was previously attained (2). This could be due to either the chemistry of the ZrB_2 (relative to that previously used) or oxygen contamination and oxide formation from the argon. A purer argon source and lower flow rate will be used to reduce the oxygen content in the chamber.

D. Reinforced Diboride Composites

The use of fiber reinforcing procedures are often considered to enhance the ability of brittle ceramic materials to sustain stresses induced by mechanical and thermal environments which would be produced in various applications. Ceramic bodies reinforced with metal fibers should display improved mechanical properties and thermal stress resistance. Krochmal's review of fiber reinforced ceramics and summary of possible matrix fiber combinations (9) shows that present technology has been unable to capitalize on this approach to achieve improved thermal stress resistant ceramic materials with predictable mechanical integrity. Among other things, thermochemical interaction, matrix cracking and preferential reinforcement oxidation have prohibited the application of this concept to technologically interesting materials.

Earlier work under Tinklepaugh at Alfred University which is summarized in Krochmals review (9) showed that suitably prepared metal reinforced oxide composites failed in bending only after the outer fiber stress was increased several hundred per cent over that of specimens without reinforcement. Deviations from linear stress strain behavior were noted for these ceramic matrix composites where the onset of the deviation was coincident with the stress required to fracture the unreinforced ceramic. The ceramic matrix actually fractured at this stress, but the specimen was held together by the reinforcing metal fibers. The stress applied after the noncatastrophic matrix fracture effected a gradual removal of the fibers across the fracture and eventually complete failure ensued.

Three types of reinforcing agents were employed in an attempt to prepare reinforced diboride composites for evaluation in the Phase One screening tests. Composite compositions are identified and designated as follows: (I) Material V, ZrB₂ with five and twenty volume per cent SiC whiskers, Vf(5) and Vf(20) respectively; (2) Material XII, ZrB2 with five volume per cent Thornel 25 carbon filaments, XIIf(5) and (3) Material XIII, ZrB2 with 5 volume per cent W filaments. These composites represent three different approaches to the utilization of reinforcing agents to effect improvement over the inherently brittle behavior of diboride materials. The Material V composition is a ceramic whisker reinforced ceramic matrix which would not be subject to failure by oxidation of the reinforcement material. The over-all mechanical property enhancement and the improvements in fabricability of the diboride base materials derived from the addition of SiC powder in Material V compositions suggested the examination of the SiC whiskers as a reinforcing agent for ZrB2. Thornel 25 was chosen as a reinforcing agent in Material XII to provide crack arresting particles and to improve mechanical properties. Polycrystalline compositions of Material XII with particulate graphite additions were designed to enhance thermal stress resistance by increasing the strength to modulus ratio, O/E. However, the relatively high modulus of Thornel 25 carbon, $E \sim 20 \times 10^6$ psi, coupled with the low percentage addition is not expected to provide any significant reduction in \mathfrak{O}/\mathbb{E} for Material XIIf(5). Tungsten filament was selected as a reinforcing agent in Material XIII on the basis of its thermochemical compatability with ZrB₂ and HfB₂ and its availability. This composite is representative of the conventional metal reinforced ceramics. Successful fabrication of this material would provide improved mechanical behavior and thermal stress resistance at the expense of decreased oxidation resistance. The characterization of the selected reinforcing agents was presented in Section III.

Conventional hot pressing procedures were employed to attempt to prepare the chosen composite compositions. The fabricating conditions and results are summarized in Table 36. The preliminary experiments appear to be characterized by experimental difficulties common to spinforced composite fabrications. Mechanical difficulties were encountered with the SiC whiskers while thermochemical instability was observed with the Thornel 25 carbon. The behavior of the latter is probably associated with interaction of the additive with the oxide impurity in ZrB₂. Mechanical difficulties and chemical reaction with the hot pressing atmosphere were observed for the W filament - ZrB₂ system. Partial success in fabricating Material XIIf(5) was obtained in billet XIIf(5) D0644 by winding the continuous yarn on a mandrel and cutting round mats of the windings. Each mat was held together at its ends with

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Duco cement to facilitate handling. Mats were loading consecutively with layers of boride resulting in continuous aligned layers of Thornel yarn in the pressing. Reaction was reduced at least in the center of the Thornel yarn by not separating the yarn into its constituent filaments. A representative microstructure is provided in Figure 29. The average room temperature bend strength measured from three specimens of billet D0644 was 30,000 psi indicating no improvement in properties as compared to 100% dense Material 107 which has a bend strength of 40,000 psi.

Full co-operative effects typical of functional composites was not realized almost certainly due to the stresses not being transferred fully to the graphite filaments. This is because each filament of the yarn is not in contact with the boride. This would only be possible if the yarn were separated into its filament constituents. However, under such circumstances the filaments are degraded under the hot pressing conditions. Thus, the principal problem in forming filament boride composites revolves around chemical compatibility of the filament material and the diboride during hot pressing. It is clear that processes employing lower fabricating temperatures must be developed.

A summary of possible diboride matrix fiber reinforced composite systems taken from Krochmal's review (9) is presented in Table 37; thermal stability and other pertinent remarks are included. The results obtained to date and the information in Table 37 will be used as a basis for the continuing effort on liber reinforced diborides in the current program.

VI. THERMAL SCREENING

A. Introduction

Thermal screening procedures have been carried out on representative structures of each material prepared during Phase One. Cylindrical specimens (about 0.35 inch diameter by 0.35 inch high) of the hot pressed material are initially subjected to metallographic examination to characterize grain size and shape, phase distribution and porosity. The specimens are then subjected to high temperature anneals in argon after which they are re-examined to determine changes in both gross and microscopic features.

B. Experimental Procedure

Screening runs at temperatures up to 2200°C (optical pyrometer) were carried out in a belljar with a resistance heated tantalum tube furnace. A series of tantalum radiation shields were employed to maintain a uniform hot zone of 2.5 inches diameter by 5 inches long. The specimens were contained in tantalum wire baskets for screening at 1800° to 2000°C. In operation the furnace was twice evacuated to ~1 torr and back filled with argon; specimen degassing was promoted by initially heating the specimens to ~1000°C in a vacuum of 10-5 torr followed by cooling to room temperature. After introducing argon to provide an operating pressure of ~650 torr, the furnace was heated to temperature by a manually controlled power supply at a rate of 5 to 10°C per minute. Temperature was measured periodically with a micro-optical pyrometer, accurate to +10°C. After the test, the specimens were slowly cooled to room temperature.

For temperatures above 2000°C, where the diborides alloy with tantalum to form a liquid phase, the specimens were placed on a HfB2 plate supported on a ZrO2 pedestal. Temperatures in excess of 2200°C (optical) could not be obtained because of contamination of the heating element by vapor transport from the specimens. To overcome this difficulty, thermal screening anneals were carried out in flowing argon at 2300°C (color temperature) in the oxidation furnaces (Section VIII).

C. Experimental Results and Discussion of Results

A summary of the thermal screening experiments is given in Table 38. Except where noted by a remark, there was no evidence for any localized melting or for second phase coalescence, redistribution or dissolution. Line intercept analyses of initial and annealed structure photomicrographs yielded on the average, a small increase in grain size. The following microstructural features were observed.

1. Material I (ZrB₂)

Specimens of pressing IO7 D0589 were observed to have a number of microstructural variations in both the as-pressed and annealed conditions.

Figures 30(a) and 30(b) present photomicrographs of two areas within the hot pressed billet; the variations in microstructure are clearly evident. Both sections contain a gray phase and pores, some of which appear as having previously contained a secondary phase which was pulled out during metallographic preparation. In contrast, a section of the specimen screened at 2200°C (optical) contains a different porosity distribution and contains large amounts of an orange second phase, Figure 30(c).

Structural variations in the specimens thermally screened at 2200°C (optical) and 2300°C (color) are depicted in Figure 31; the structures include a) large, elongated grains with a considerable amount of grain boundary precipitation and porosity, b) large pores, c) small pores and d) small pores and large amounts of an orange precipitate. Complete evaluation of the specimens indicates that the structural variations that have been noted are characteristic of the billet and have not been affected by the annealing treatments.

2. Material VIII (ZrB₂ + 30 v/o Graphite + 14 v/o SiC)

Two formulations of Material VIII were thermally screened, including preparations from Regal 330R carbon powder (D0498) and Poco graphite powder (D0592); microstructures of these billets are presented in Figures 11 and 12. After thermal screening treatments, transverse section microstructures of both pressings exhibited a peripheral ring depleted of additive phase. Pressing D0498, treated at 2200°C (color temperature) for 15 minutes exhibited an average additive phase depletion of 50 mils, whereas pressing D0592, treated at 2300°C (color temperature) for 15 minutes exhibited an average depletion of about 10 mils. Photomicrographs of both specimens, including an over-all view of the transverse section and microstructures of both the depleted and matrix zones, are presented in Figures 32 and 33. In both cases, the matrix zone structures are identical to those of the original materials. It is of interest to note that heat treatment in argon at about 2200°C produces about five times greater additive phase depletion in the material prepared from Regal 330R carbon compared to preparation from Poco graphite.

3. Material X $(ZrB_2 + SiB_6)$

Exposure at 2200°C (color temperature) for 15 minutes resulted in SiB, -phase melting in specimen D0596. The original and heat treated microstructures are presented in Figure 34. The SiB, phase, which originally is quite uniformly dispersed, is observed to be present as a grain boundary phase. The rounding of the ZrB2 grains is characteristic of the past presence of a liquid grain boundary phase. As one traverses from the center to the surface of the sample, the extent of porosity and ZrB2 grain size is observed to increase and the amount of SiB6 phase is observed to decrease. Further experiments are planned to determine the necessary conditions (temperature, time and atmosphere) for SiB6-phase melting.

D. Melting Points

In addition to the foregoing, melting point measurements have been carried out on six hot pressed specimens by E.Rudy, Aerojet General Corporation.

The specimens, in the shape of right cylinder dumbbells, were melted under a positive helium pressure of 2 atm. Apparent temperatures were corrected for the black body sighting hole configuration and for transmission through a quartz furnace window. Incipient melting is generally associated with a visual observation of liquid infiltration by melting of secondary phases. The observed results are presented in Table 39.

The melting results of the Carborundum, 102A and 103A structures are consistent with the X-ray finding that the major impurity phase is ZrO_2 (melting point ~ 2600° C). The diboride melting at ~ 3085° C is in reasonable agreement with the melting point of ZrB_2 (1). The Norton ZrB_2 , containing ZrC as the major impurity phase, yields incipient melting at a higher temperature than zirconium borides containing ZrO_2 as the impurity phase.

The melting behavior of the Material II (HfB₂) samples are also consistent with second phase impurities. The II05 material, containing very little second phase impurity, shows no evidence of melting to 3235°C; complete melting was observed at 3345°C. The II06 material, which contains large amounts of HfO₂ and HfC, showed incipient melting at 2697°C and complete melting at 3085°C, considerably lower than the II05 material.

Additional melting point evaluations are scheduled for specimens prepared from Materials III, V, VI and VIII.

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VII. MECHANICAL SCREENING

A. Bend Testing

Bend tests at Avco were conducted within an inductively heated graphite four point bending cell, Figure 35. The load was applied at a constant rate (24 lb/min) from a constant head water tank and the loading was terminated by a microswitch operated selenoid water valve at the instant of fracture. A W-5% Re vs. W-26% Re thermocouple was located directly under the specimen. This couple was checked against a Pt-5% Rh vs. Pt-20% Rh thermocouple for accuracy. The specimen was allowed to thermally equilibrate several minutes prior to the application of load. The graphite cell was constructed so that alignment of the specimen throughout assembly and testing was assured. Specimens were 0.875 inches long by 0.150 inches wide by 0.050 inches thick and the moment arm was 0.187 inches giving a span to height (1/2 thickness) ratio of 7.5. Three tests per temperature were performed for each microstructure.

1. Temperature Effect on Bend Strength

The results of the bend test measurements at Avco which were performed at temperatures from 23°C to 1800°C are given in Table 40 for Phase I structures and Table 41 for Phase II structures. The average results for Materials I to V are plotted as a function of test temperature in Figures 36 to 40. Several microstructures are not represented graphically as only limited comparative data were available.

Almost all Material I microstructures tested display a strength peak at 800°C with the strength falling sharply at 1400°C, Figure 36. This agrees with previous results on high pressure hot pressing ZrB2 and HfB2 (3). At 1800°C, the maximum average strength for one microstructure was 31,000 psi and this occurred for a 90% dense billet. An increase in porosity does not appear to decrease bend strength of the material at any temperature. However, it was not possible to independently vary the porosity and grain size of Material I microstructures. Consequently, the dense Material I microstructures generally have a larger grain size than the more porous ones. The beneficial effect of the smaller grain size of the less dense microstructures may compensate for the detrimental effect of the porosity producing the somewhat ambiguous results in Figure 35. This suggests that it would be desirable to fabricate fine grained dense materials, but this was difficult with the 102A powder. Relatively fine grained materials could be made from 03A powder at the 95% and 100% density levels, but these samples were not appreciably stronger than coarser grained 02A materials of equivalent density. The fact that a strength increase was expected from the finer grain size, but was not observed may be attributed to impurity phase differences between the two powders.

The role of grain size and porosity in determining the strength of ZrB₂ may be clarified by comparing the results for Material I with the bend strengths of two additional lots of ZrB₂ material. The strength properties as a function of test temperature for ZrB₂ materials supplied by the Norton and Carborundum Companies were determined for temperatures from -196°C to 1800°C, Table 42. The testing at temperatures up to 1400°C was performed at ManLabs

using a three point bending apparatus. Tests at 1400°C and 1800°C were performed at Avco with the four point apparatus being employed in mechanical screening studies of the other boride materials. The strengths measured on the Norton material were comparable to those determined in the previous boride program (3). However, the new results for the Carborundum ZrB₂ show higher strengths than the earlier measurements. The discrepancy may be due to the different sample preparation technique; the earlier specimens were cut by electrical discharge machining whereas the recent material was cut by diamond tools. Other work has shown that EDM of TiC was detrimental to the bend strength due to the creation of microcracks (10).

The Carborundum ZrB2, low in metallic impurities behaves similarly to the Avco microstructures of Material I. The major decrease in strength occurs between 1200° and 1400°C. The Norton material shows an unusual behavior in that the strength declines gradually up to 1400°C and then at 1800°C drops to the lowest value observed for any of the diboride material. The unusually low strength at 1800°C is attributed to the combination of a relatively large grain size and the high porosity which is unlike the Material I microstructures where the 90% dense materials are all fine grained.

Specifically, the Norton material with a porosity of 11% and grain size of 18µ has a bend strength at 1800°C of 5,000 psi; Carborundum's ZrB₂ was 95% dense with a grain size of 16µ and had a strength at 1800°C of 15,000 psi. These lower strengths as compared with other Material I microstructures may again be due to impurity differences. However, at their respective porosity levels, these data support a grain size dependence in the bend strength. If the data for the Norton and Carborundum materials are compared with the data in Figure 36 for 90% and 95% dense materials, respectively, a trend for decreasing strength with increasing grain size emerges.

Consequently, within a given powder lot, the fine grained dense microstructure will display the highest strength, but among powders of different chemistry the impurity phase content and morphology may be the dominating factor in determining the strength.

It should be mentioned that the limited number of tests per microstructure and temperature also complicates the problem of determining the role of microstructure and chemistry on the strength of Material I. This factor may be most important in the brittle fracture range at temperatures up to 800°C as opposed to conditions where limited plasticity is observed at 1400° to 1800°C.

A preliminary series of experiments were performed on the Norton ZrB₂ and Carborundum ZrB₂ where an oxide layer was developed prior to bend testing at 23° and 1000°C. The specimens were preoxidized at 1600°C for 30 minutes; this temperature is in the region where the oxide is coherent to the diboride matrix. The oxide layer produced was about 0.007 inch thick. Examination of the oxide boride interface at high magnifications revealed that the oxide preferentially penetrated the diboride grain boundaries to a depth of 1/2 to 1 grain beyond the general interface. However, at no point was a diboride grain completely surrounded by grain boundary oxide nor were any microcracks found to be generated from the penetrating oxide. The bend test results were analyzed from two

standpoints: first, it was assumed that the diboride matrix supported the entire load; second, it was assumed that the matrix plus the oxide supported the load. These calculated stresses are compared to the range of strengths measured on the unoxidized matrix for each material in Table 43.

The results indicate that the oxide layers do not detract from the strengths of the ZrB₂ matrices. However, the oxide does not appear to have the strength of the diboride matrix. Future plans include preoxidizing structures of all the materials and using preoxidization conditions in the different regions of oxide formation (coherent, semicoherent, incoherent). In addition, the studies will be extended to include the effect of SiC depletion on the strength of the alloyed materials.

Fully dense Material V microstructures were fabricated with 02A, 03A and 07 ZrB₂ powders. In both Materials V and I the chemistry effects seem to be most important at low test temperatures, 25° and 800°C, whereas at 1400° and 1800°C the grain size dominates. In Material V, for fully dense and comparable grain size microstructures, there is essentially no difference among the three base powders in the bend strength at 1800°C. Residual stresses introduced by impurity phases in the base materials due to thermal contraction differences may influence the strength at the lower test temperatures. At the higher test temperatures these stresses could be relieved thus minimizing the effect of powder chemistry.

Comparison of Material V with Material I, Figures 36 and 37 indicates that the SiC addition suppresses the strength maxima at 800°C and increases the strength at 1800°C. The strengthening effect of SiC for the 02A ZrB₂ and 05 HfB₂ base materials at 1800°C is shown in Figure 41, only data for billets 98-100% dense are plotted. The 1800°C data for both ZrB₂ and HfB2 base materials suggests a significant increase in strength with the addition of SiC. There is a substantial difference in grain size for the microstructures with and without SiC and this must be kept in mind when comparing strength values. The morphology of the SiC does not allow for strengthening by dispersion hardening since the SiC grains are of the same order of size as the matrix. However, the two phase aggregate may be more resistant to deformation than the boride alone and thereby contribute to the elevated temperature strengthening. The ZrB, base compositions do not show any dependence on SiC content for compositions between 10 and 35 v/o SiC. Alternately, the HfB2-SiC composite strength continues to increase with increasing SiC content. This discrepancy is not understood at this time, but may be due the chemistry changes induced by the additions of SiC. This problem will receive further consideration from the standpoints of phase analyses and strength measurements; the latter will include the definition of the stress strain curves for samples tested at 1800° and 2200°C.

The lin ited bend strength data for Material II, Figure 38 indicates that a fine grain size is more important than low porosity for obtaining a high strength. The addition of SiC to HfB2 greatly socilitated the densification of Material III and allowed fine grained microstructures to be produced at all porosity levels, Section IV. The bend strengths at functions of test temperature for Materials III and IV, Figures 39 and // demonstrate that porosity is detrimental to the strength although this effect does not persist at all test

temperatures, Figure 39. The general effects of the SiC additions are believed to be similar to those for ZrB₂ base materials as discussed in the previous paragraphs. The strength level at 1800°C, 59,600 psi, is thought to be the highest strength—ever reported for an exidation resistant material.

Limited testing was performed on Materials VI, VIII and XII. Material VI exhibited strength values at 23°C and 1800°C comparable to those of an equivalent density Material III. Material VIII possessed moderate strength values at 23°C, but excellent elevated temperature strength was attained in a similar manner to other SiC containing diboride compositions. Material XII, with 20 v/o C high temperature values no better than Material I.

An additional point of interest with respect to Materials III, IV and V was revealed in the etched microstructures. Fine linear features are observed within the matrix grains; these facets being as much as half a grain diameter in length. It is unknown at this time whether these features are microcracks or a precipitate. However, it should be noted that even the highest strength microstructures of these materials contained these hairline features, Figures 18 and 19.

2. Surface Finish Effect on Bend Strength

Surface finish could be important in determining the level of fracture stress in brittle materials because fracture is thought to often originate from pre-existing flaws. The surface placed in tension in a bend test would be most critical and thereby control the fracture stress. In the case of catostrophic brittle fracture, the crack length and fracture stress are related by the Griffith relation

$$\sigma_{f}^{2} = \frac{2\gamma_{f} E}{\pi C} \tag{1}$$

where 0_f = the fracture stress, γ_f = fracture surface energy, E = elastic modulus and C = crack length. If the fracture surface energy is the true chemical surface energy, which would be about 1 to 2 x 10^3 ergs/cm², then the critical crack length would be of the order of 1 to 5 microns (using E = 51.7 x 10^{11} dynes/cm² and 0_f = 44.8 x 10^8 dynes/cm²). Bend tests on a series of surface finishes were conducted to test the importance of the starting surface on determining fracture stress.

A number of bend specimens were machined from the 100% dense billet V07 D0576; the NDT report indicated that this billet was uniform in density and was uncracked. Various surface finishes were prepared by grinding the tensile surface with 220, 400 and 500 grit wheels. A fourth surface condition was prepared by obtaining essentially a metallurgical finish with a final 0.25 micron diamond polish. The structure of the surfaces was characterized in two ways; Talysurf (Taylor-Hobson) surface contour traces and electron microscope surface replica examination.

Sections of the Taylsurf traces are shown in Figure 42 for the four surfaces tested. Associated with each tracing is the vertical magnification and the C.L.A. (intergrated average deviation of the ridges and grooves from the centerline). As can be noted, many grooves have total depths much deeper than twice the C.L.A.; 180µ inch in the case of the 220 grit finish, 100µ inch for the 400 grit finish, 100µ inch for the 500 grit finish and 3µ inches for the polished surface. The 400 and 500 grit finishes appear very similar.

The electron microscope examination showed surface structures represented by Figures 43 to 45. The 400 and 500 grit finishes appeared quite similar, so the structure for only the 400 grit is shown, Figure 44. The 220 grit finish reveals the microstructure since many grains were completely pulled out. Evidence for possible intergranular surface cracking is also shown in Figure 43. The 400 grit surface has resulted in a greatly increased surface cutting although some grain pull out also took place. Possible surface cracks are shown in Figure 44 for this finish. The finely polished surface shown in Figure 45 reveals very little structure or scratches. The pits that are present show no well defined structure at higher magnification; they are apparently areas where polishing did not completely remove the results of rough grinding. However, no cracks were observed on the polished surface.

The room temperature stringth data for the four surface finishes are reported in Table 44. There was a trend for increased mean strength with the finer surface finishes; however, the standard deviation for each population was large, except for the 500 grit finish. The "Student's T" test was utilized to investigate the significance of the variation be ween the mean strength of the 220 grit and the polished surface. The probability of Egnificance was 38.9% and this shows that from statistical considerations they essentially belong to one strength group.

The insensitivity of the fracture strength to the surface condition may be attributed to slow growth of the existing flaws by localized plastic flow process is at a resses below that for catostruphic failure. Room temperature slip in polyc: ystalline TiB, has been observed (:1). All the surface finisher produced cracks and could be subcritical up to stress levels where slow crack grewth initiates. Ar alternate mechanism for slow or edgeror in could involve stress corrosion of the diboride, both static and dynamic stress corros on effects have been reported for alumina (12). In either case pre-existing cracks could now to derincreasing stress until the Griffith-O owan criteria for fructure is reached and then rapid crack propagation ensues. Independent measurements at ManLabs of fracture energies a conventionally hot pressed ZrB2 and obtained values of 71,000 and 134,000 rgs/cm2 1 r two different grades of material. (The materials studied were the Norton and Carbonundum grades.) Using thes, numbers for twice the surface fracture energy in the Griffith-Orow. . equation, crack lengths of greater than 90 microns could be tolerated without initiating fracture at the observed fracture stresses. Fracture stress insensitivity to surface condition coulded with the fracture energy measurements lends considerable support to the prospect that localized plastic deformation processes are knowled in the fracture of the diborides.

There are two alternatives to the assumption that slow crack growth occurs prior to fracture. First, other defects may be present in the material from the fabrication and these defects are larger than any flaw created by the rough surface finishes. Metallographic studies do not support this assumption; cracks of several grain diameters would easily be detected by light microscopy. Second, the flaws introduced by the surface finish techniques do not have a morphology that creates a critical stress concentration. For example, pre-existing atomically sharp cracks of less than a grain diameter may provide a more severe condition than deep, but relatively blunt grinding grooves. Microstructural features have been observed in Materials III, IV and V that could be transgranular cracks although they have not been positively identified as cracks. However, the surface grinding in these brittle materials does not create blunt grooves, but removes material by chipping and pulling out grains thereby providing high stress concentrations.

B. Elastic Modulus

Dynamic measurements of Young's Modulus (E) were made by the sound velocity technique at 23°C . High density half billets of Materials I to V were employed in order to measure both the compressional pulse velocity (V_{L}) and the transverse pulse velocity (V_{T}). The results of these measurements on seven billets are listed in Table 45. Considerable disagreement is found among the calculated values of Poisson's Ratio. It is believed that the primary source of error in the calculations is in the measurement of V_{T} . Therefore, a value of $\sigma = 0.145$, as previously used (3) will be adopted in future calculations of Young's Modulus until accurate determinations can be made for each material in this program.

Static measurements of Young's Modulus were made using a four point bending and a single point probe strain measuring apparatus, Figure 46. At present, the measurements are being conducted in argon, so the spring support of the load cell cage is unnecessary. The schematic also shows three tungsten probes positioned against the sample. This design was intended to bring the strain reference point directly to the sample. This would eliminate errors due to knife edge interactions, etc. Ilowever, the early work with this design has been inaccurate, so at present, the outer two probes are fixed to the lower knife edge block. A W-5% Rp vs. W-26% Ro thermocouple is placed next to the lower graphite pedestal and is positioned directly under the sample. A Mo furnace is being used. As extremely small strains are measured $(4-9 \times 10^{-4} \text{ inches})$ for the specimens which are the same size as used for bend tests, the LVDT was calibrated with a series of four gage blocks having height differences of 25×10^{-6} inches, as well as a micrometer reading to 1×10^{-4} inches. Also three standard modulus materials were used to check the accuracy of the apparatus; they were 9Ni-4Co-0.45C steel $(28.5 \times 10^6 \text{ psi})$, 99.5% dense alumina $(58 \times 10^6 \text{ psi})$ and WC-5.75% Co $(88-92 \times 10^6 \text{ psi})$.

The static Young's Modulus measurements are summarized in Table 46. Also included in this table a e a limited number of dynamic modulus measurements and static measurements conducted at ManLabs. The different measurements served as further checks on the accuracy of the equipment. Furthermore, data

are included which were collected both prior to and after several equipment modifications, so varying levels of accuracy are represented.

It will be necessary to collect additional self-consistent data in order to separate the effects of composition on the elastic properties; however, at this time it is possible to relate porosity to Young's Modulus in the diborides.

MacKenzie (13) analyzed the effect of small amounts of porosity on elastic moduli in an isotropic body. This relation is given as

$$1 - \frac{G}{G_o} = \frac{5(1-\rho)(3K_o + 4G_o)}{(9K_o + 8G_o)} + A(1-\rho)^2$$
 (2)

where G = modulus of rigidity, $\rho = relative density$, $K_0 = bulk modulus$, A = constant and the zero subscript refers to the full density value. Cable et al., (14) calculated the constant A by setting $G/G_0 = 1$ at $\rho = 0$ and found this equation accurate for several materials. For Poisson's ratio G = 0, 145 for C = 1, and C = 1. The curve for Eq. (2) is plotted in Figure 47 along with Young's Modulus data for Materials I through V at various porosity levels. The data plotted is thought to be self-consistent in that apparatus design and calibration was constant throughout the measurements. Several interesting features emerge; the SiC alloys of the diborides fall on the same curve as their respective base materials, the C = 1 base materials agree with the predicted relation and Young's Modulus for the C = 1 base materials is much more sensitive to porosity than predicted. Rossi et al. (15) have shown that anisotropic geometry for porosity or second phase inclusions can account for marked deviations from predicted behavior. The C = 1 and C = 1 base materials must be carefully re-examined for differences in these microstructural features which may be responsible for the behavior shown in Figure 47.

In order to determine the accuracy of the elastic modulus measurements at Avco, a sample exchange study with ManLabs, Inc. was instituted. The room temperature Young's Modulus values obtained at Avco (four point bending single deflection probe) were approximately 7 to 10 per cent lower than those obtained at ManLabs, Inc. (three point bending single deflection probe). Both laboratories also tested a series of standard materials (steel, Al_2O_3 and WC-5.75Co) with the same discrepancy between test techniques. A comparison of the measurements on the standards with published values revealed that the ManLabs, Inc. measurements were within 5 per cent of the absolute values. It was concluded that the static Young's Modulus measurements on the diborides at Avco obtained as of this report are up to 10 per cent lower than the ManLabs numbers. The measurements at 800° and 1400°C at Avco have the same accuracy as those obtained at 23°C.

The elastic moduli of the Norton and Carborundum lots of hot pressed sirconium diborides were determined by a three-point bending, single-point deflection probe technique at ManLabs, Inc. The results are presented in Table 47 with some dynamic measurements for another hot ressed ZrB₂ (16).

There is excellent agreement between the static and dynamic measurements and the 5 data points for modulus vs. density form a curve which extrapolates to a value of about 7 to 79 x 10^6 psi for fully dense ZrB_Z .

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C. Post-Mortem Examinations

1. Visual Examinations

All specimens were examined after testing with respect to the location of the fracture. Single and double asterisks appear after certain specimens in Tables 40 and 41 and these denote primary and secondary knife edge fractures, respectively. The incidence of such knife edge fractures is common in transverse rupture tests utilizing four-point bending; the origin of this phenomena is still a matter of some controversy (17). Compressive stresses are anticipated in the areas under the knife edge, hence, tensile failures should be prevented in these regions. However, there has been at least one investigation (13) in which knife edge failures did originate in tension surfaces, so that the actual stress distribution under a knife edge is probably far more complicated than previously supposed. In addition, the incidence of knife edge failures could be correlated in one case (18) with absorbed surface moisture, the frequency of such failure increasing on dry surfaces and this is also a factor which has not previously been recognized.

It was not possible in this study to correlate the incidence of knife edge fractures with any microstructural or testing parameters, although the frequency of such failures was much higher in certain materials. Similar information will be recorded in the future and trends may become apparent when more data are available.

Plastic bending was observed in many of the samples tested at 1800°C as evidenced by curvature on the fragments when placed against a flat plate. In all cases, however, the amount of plastic bending was estimated to be less than 1%. The notations N.B., S.B. and B in Tables 40 and 41 denote no plastic bending, slight plastic bending and plastic bending of less than 1%, respectively. Again, it was not possible to correlate these observations with either microstructural parameters or strengths. Much more information will be forthcoming when high temperature stress strain curves are generated.

2. Fractography

Replicas were taken from a selected number of fractured samples, for Materials I to V and examined in the electron microscope. The fracture mode was predominantly transgranular in samples tested at room temperature, while the percentage of intergranular fracture increased with increasing test temperature. Figures 48 to 51 show fractographs of a Material V microstructure tested at four different temperatures. It can be seen that a limited amount of transgranular fracture occurred even at 1800°C.

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The main fracture in these cases was within the gage length, but an additional fracture occurred at one of the loading points, resulting in three fragments.

It is difficult to differentiate between the ZrB2 matrix and the SiC addition, as the fracture mode was similar for both phases. However, light microscopy of polished surfaces shows that the SiC phase is generally smaller than the ZrB2 matrix. The smaller grains visible in Figures 48 to 51 are almost certainly the SiC phase. The terraces visible in the 1800°C fractograph are probably due to thermal etching.

The increase in the amount of intergranular fracture with increasing temperature occurred even when the fracture strength increased. Previous observations on fine grained ZrB₂ and HfB₂ showed that the percentage of transgranular fracture paralleled the strength peak (9). This difference in behavior is not understood.

3. Optical Microscopy

One aspect of the post-mortem studies is to determine the relative stability of the microstructure to the testing environment. The grain sizes for specimens tested at 1800° C are given in Table 48 and reveal that significant grain growth only occurred in one ZrB₂ structure. The IO2A DO338 specimen shows an apparent anomaly, undoubtedly due to grain size variability within the billet itself. The unalloyed HfB₂, Material II and the diboride-SiC mixtures, Materials III, IV and V show little or no grain growth during the 1800° C test (at temperature approximately 5 minutes). The SiC second phase evidently inhibits movement of the diboride grain boundaries as it does during fabrication. The thermal stability of impurity phases in the HfB₂ (solidus 3235°C) relative to those in the ZrB₂ (solidus 2560-2630°C) may also contribute to the observed increased grain size stability for HfB₂. The grain sizes determined from the electron fractographs agreed with the grain size measurements by light microscopy.

The specimen from billet 102A D0305 showed an increased concentration of orange carbide phase relative to the gray oxide impurity phase, compared with the starting billet, but the over-all second phase content remained constant. All other specimens examined possessed structures that appeared identical to the as-fabricated material. The edge of specimen 102A D0338, Figure 52 (tested at 1800°C) shows no evidence for oxidation during testing in argon.

In several cases, anomalously weak specimens were encountered and examined. There was nothing unusual in the fractographs which could explain the low strengths at room temperature and the fracture mode was still predominantly transgranular.

Although plastic deformation occurred at 1800°C as manifested by permanent specimen curvature there were no details on the fractographs which could be correlated with the limited amount of macroscopic plasticity.

4. Density Checks

Post-testing density checks on bend specimens fractured at room temperature are shown in Table 49.

In order to measure the geometric density, the fracture face of the test fragment was squared off and the radius on the tension face was removed by grinding. When a discrepancy between the air density and the water displacement density occurred, the geometric density was always lower. It was also possible to correlate the differences between original billet density and the true (water displacement) specimen density. X-radiographs were available for billets IO2A DO345, IIIO5 DO386 and IVO5 DO410. Billet DO386 had a high density rim and this was the reason for the higher density of the billet compared to the bend specimen. Billets IO2A DO345 and IVO5 DO410 had low density areas on the edge, therefore, the higher density of the bend specimens is to be expected. The density variations on the exterior of certain billets is attributed to the chemical reaction of the billet with the BN mold wash or the graphite liner. Clear examples of reaction zones were visible metallographically in several billets.

VIII. OXIDATION SCREENING

A. Introduction

Furnace oxidation screening experiments have been carried out on hot pressed specimens of Materials I through VI, VIII, X and XII and on high pressure hot pressed (HPHP) specimens of Materials VI, X and XI. In addition, oxidation comparisons have been made between commercially hot pressed ZrB₂ (obtained from two sources) and Material I and also between Boride Z (Carborundum Corporation) and Materials I, V and VIII. The oxidation characteristics of selected diboride compositions containing rare earth and alkaline earth additives were also determined. These materials were fabricated under a separate Air Force program investigating boride coating compatibility for graphite. The results are summarized in Appendix III.

B. Experimental Procedure

The oxidation exposures are carried out in a furnace depicted schematically in Figure 53. Cylindrical specimens, which are generally 0.35 inch diameter by 0.35 inch high, are placed coaxial with the furnace tube and are mounted on zirconia knife edge supports. The specimens are heated by radiation from a zirconia liner which in turn is heated by a carbon tube resistance furnace. Four identical furnaces, each having an inside tube diameter of 0.75 inch, are being used.

The specimens are heated to the desired test temperature in argon having an effective flow rate of 0.9 ft/sec STP; heating times are generally 30 to 40 minutes. After the desired temperature is stabilized, air is admitted for a fixed time interval, usually one hour. Then argon is readmitted to displace the air and the specimen is cooled; 60 to 90 minutes are required to reach room temperature.

Several experiments were carried out to determine satisfactory air flow rates to sustain reaction (or diffusion) controlled oxidation. Figure 54 presents a hypothetical oxidation experiment in which a protective oxide is formed. The amount of oxygen required to sustain equilibrium oxidation as a function of time is indicated by line 1. The amount of oxygen supplied to the specimen is linear with time; two air flow rates are represented with $\mathbf{v}_2 > \mathbf{v}_1$. For any given time, the supply of oxygen (v) must exceed the oxygen requirement (line 1). Thus, a 60 minute experiment requires an amount of oxygen corresponding to point (a); either air flow rate would be satisfactory. For a 30 minute experiment, however, flow rate \mathbf{v}_1 would supply an amount of oxygen corresponding to point (c), whereas a quantity corresponding to point (b) is required; a 30 minute experiment employing flow rate \mathbf{v}_1 would be oxygen supply limited. For a given specimen material, temperature and time, the critical flow rate \mathbf{v}_C corresponds to the rate which supplies just the amount of oxygen required for specimen oxidation.

Flow rate dependencies have been determined experimentally for Material I (ZrB₂, 1800°C, 15 minutes) and Material III (HfB₂ + 20 v/o SiC, 2120°C, 60 minutes); pertinent data are presented in Table 50 and Figure 55. In both cases which represent the severe extremes of short time and high temperature, the critical flow rates were determined to be 0.4 ft/sec STP. The oxidation experiments reported upon were all carried out at an air flow rate of 0.9 ft/sec STP.

The specimen surface temperature is measured and recorded continuously by means of a two color pyrometer. The pyrometer is calibrated weekly against an NBS certified tungsten filament to detect and correct for calibration changes. The temperatures reported in this section are color temperatures which, for tungsten are 20° and 50° C higher than true temperatures at 1500° and 2000° C, respectively.

After oxidation, a quantitative metallographic procedure is employed to measure the extent of material recession; post-mortem metallographic inspection also provides morphological information about the diboride matrix, the oxide and the matrix oxide interface region. Initially, a low magnification photograph of the specimens obtained to provide a record of the shape of the specimen and of the physical condition of the outer oxide layer. The specimen is mounted longitudinally and is polished to reveal the oxide diboride interface; the final specimen height (and height of undepleted additive phase zone, if present) is measured on a traveling stage microscope. A reticule photograph of the longitudinal section is taken for future reference. The specimen is then remounted and polished in the transverse direction to provide a measure of final diameter. Reference photomicrographs are obtained of the transverse section, the diboride matrix and the matrix oxide interface. The conversion of diboride (and additive phase) to oxide is calculated from the difference between initial and final dimensions.

C. Experimental Results and Discussion of Results

The experimental results of oxidation screening are presented in Tables 51 to 62 and are shown graphically in Figures 56 to 65. A discussion of the results for each of the materials is given below.

l. Material I (ZrB₂)

The oxidation screening results for zirconium diboride over the temperature range 1550° to 1850°C are provided in Table 51 and are shown graphically in Figure 56. All of the selected specimen structures were subjected to one hour screening runs at 1700° and 1800°C and to 30 minute runs at 1850°C; additional data were collected on representative structures between 1550° to 1650°C and at 1770°C.

The data presented in Figure 56 yield a logarithmic variation of the one hour recession values with temperature for the range 1550° to 1800°C; average one hour boride recessions are 8, 13 and 22 mils at 1550°, 1700° and

1800°C, respectively. These data are consistent with previous findings (3) and are comparable with results obtained in another study (2) for the temperature range 1550° to 1850°C. Above 1800°C, the rate of oxidation was found to increase substantially so that it was necessary to reduce oxidation times to 30 minutes. By assuming a parabolic dependence for oxidation kinetics, the one hour boride recessions at 1850°C are within the range 25 to 75 mils and average 50 mils.

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The ten selected screening structures of zirconium diboride, representing IO2A, IO3A, IO5A and IO7 powders exhibiting variations in grain intercept of 6 to 40 microns and relative densities of 89 to 100 per cent, yield equivalent oxide conversions to within +2 mils at 1700°C and +4 mils at 1800°C. Furthermore, there is no particular trend in the 1850°C data. Consequently, the selected structures cannot be rated by means of the oxidation screening tests. Representative photographs of the oxidized specimens are presented in Figures 66 through 76. The photographed specimens are fully dense structures prepared from the four ZrB2 powders having grain intercepts of 20 microns (102A D0345 and 103A D0309), 40 microns (102A D0326 and 105A D0590) and 70 microns (107 D0589). The outer oxide of these specimens, Figures 66 to 69, is dense and adherent after one hour exposures at 1550°, 1700° and 1770°C, but becomes somewhat puckered at 1800°C; a very porous outer oxide is observed after a 30 minute exposure at 1850°C*. Oxide matrix interface pictures at several temperatures are presented in Figures 70 to 72. The oxide formed at 1550°C is characterized by columnar grains whereas oxides formed at higher temperatures have an equiaxial grain morphology. The oxides are adherent to the matrix after one hour exposures for all temperatures up to 1800°C**. The grain size of the oxide is smaller than that of the diboride at 1700°C, but becomes larger than that of the diboride at 1800°C. Oxide porosity is observed to increase at higher temperatures.

Longitudinal and transverse section reticule photographs of specimens oxidized at 1700°C are shown in Figures 73 and 74; the uniformity of the boride recession is clearly evident. Matrix photographs of 102A and 103A structures after one hour oxidation exposures at 1700°C are presented in Figure 75. Similar photographs of 105A and 107 structures after 30 minute exposures at 1850°C are presented in Figure 76. The chemical characterizations of these structures were presented in Sections III and IV.

The letter F appearing in the macrophotographs indicates the leading face exposed to the air stream; in addition, several of the macrophotographs (including Plates 1-3042, Figure 66 and 1-2074, Figure 67) include the zirconia mount which has fused to the specimen.

The oxide layer on OX335, Figure 70 was inadvertantly broken off during metallographic preparation.

2. Commercial Zirconium Diboride

Oxidation data have been obtained for hot pressed billets of zirconium diboride obtained from the Norton and Carborundum Companies in order to compare the oxidation behavior of commercially available material to that prepared in this program. The results of oxidation tests over the range 1550° to 1900°C are presented in Table 52 and Figure 57.

The particular lot of Carborundum ZrB₂ that has been tested possesses oxidation behavior comparable to that of Material I. On the other hand, the Norton ZrB₂ exhibits a somewhat higher and more random rate of oxidation for temperatures up to 1800°C. It was noted that a black or dark gray oxide formed on those specimens of the Norton material which yield the greatest oxidation. For example, the uppermost point at 1700°C, Figure 57, was obtained for a specimen having a very dark gray oxide. X-ray diffraction analysis of the black oxides yields monoclinic ZrO₂; no additional phases could be detected. Electron probe microanalysis was carried out for a representative black oxide from a Norton ZrB₂ sample oxidized at 1700°C for 60 minutes, OX272. In addition to Zr, trace quantities of Cr and Ti were detected in the matrix and metallic particles rich in Fe, Cr and Ti were observed in the oxide. A few isolated positions in the diboride matrix were found to yield very high chromium contents; these areas were not metallographically distinguishable from the diboride matrix. It is concluded that the enhanced and variable oxidation behavior of Norton ZrB₂ is related to rather high impurity levels of iron and chromium.

Typical microstructures of oxidized Norton and Carborundum ZrB₂ are presented in Figures 77 through 80. The outer oxides of the commercial materials, Figures 77 and 78, are observed to become porous at lower temperatures than for the Material I screening structures, Figures 66 to 69; above 1800°C, the commercial materials are very porous and quite distorted. The boride oxide interface pictures of the Carborundum ZrB₂, Figure 79, reveal structures that are comparable to the screening materials. The Norton ZrB₂, however, is characterized by considerable porosity which results in the formation of a boride oxide band at the higher temperatures; this behavior is exhibited in Figure 80. Complete characterization data for the commercially hot pressed ZrB₂ materials has previously been presented (3).

3. Material V (ZrB₂ + 20 v/o SiC)

The effectiveness of silicon carbide additions in promoting the oxidation resistance of the diborides was first reported in an earlier study (3). Boride compositions containing a SiC additive undergo preferential oxidation of the additive phase at elevated temperatures leading to zones of outer oxide, boride plus voids (formed by preferential oxidation of SiC) and a core of boride plus SiC. The results of oxidation screening experiments carried out for six structures of Material V for the temperature range 1800° to 2100°C are presented in Table 53 and Figure 58. The structures represent pressings prepared from IO2A, IO3A and IO7 powders. The results presented in Figure 58 show a larger spread in the

recession values as compared to Material I; it should be noted, however, that a higher than average boride recession for a given temperature is accompanied by a lower than average SiC recession and vice versa. No particular distinction can be made between the screening structures in regards to the level of protection afforded.

The oxide recession results are somewhat lower than those obtained in the previous boride program (3). The addition of 20 v/o SiC is found to increase the oxidation resistance of ZrB₂ about 20 times for one hour exposures at 1800°C. Average one hour diboride to oxide conversions are 2.5, 6, 20 and 60 mils at 1800°, 1900°, 2000° and 2100°C, respectively. Typical post oxidation microstructures are presented in Figures 81 to 85. The outer oxide, Figure 81, is smooth and glassy after a one hour exposure at 1800°C, becomes roughened and less glassy after one hour at 1960°C and is very rough and porous after one hour at 2100°C. The macrophotograph of the 2100°C specimen reveals several blow holes which presumably are the result of silica loss from the oxide during the exposure.

Oxide matrix interface pictures are presented in Figure 82. The oxide is adherent after exposures up to 1960°C and exhibits a grain size and porosity distribution comparable to the silicon carbide depleted matrix. The oxide is nonadherent at room temperature after oxidation at 2100°C; it is probable that oxide separation occurred during cooling as a result of differences in the thermal expansion coefficients between the oxide and the depleted diboride. In one case, after oxidation at 2100°C, the voids near the surface (caused by the preferential oxidation of SiC) were observed to be partly filled with oxide. Photomicrographs of this oxide intrusion are presented in Figure 83.

The 1800°C interface picture, Figure 82, clearly defines three zones; these are (1) the oxide, consisting of ZrO₂ and probably SiO₂, (2) the diboride matrix, where SiC has been preferentially oxidized, leaving voids and (3) the original diboride SiC matrix. The corresponding zones in a specimen oxidized for one hour at 1960°C are presented in Figure 84 which also presents the specimen microstructure consisting of essentially discontinuous grains of SiC within a ZrB₂ matrix.

Reticule photographs of the 1960°C exposure specimen are presented in Figure 85. The longitudinal section reveals a dark outer band corresponding to the oxide, a light intermediate band corresponding to the SiC depleted matrix and a central core of the $ZrB_2 + SiC$ matrix. The oxide has become detached during preparation of the transverse section; the two matrix zones are apparent. Several radial cracks are observed within the SiC depleted zone of the transverse section. It is suggested that the ZrB_2 -SiC composite matrix might have a lower coefficient of thermal expansion than does the ZrB_2 matrix which is depleted in SiC, resulting in circumferential tensile stresses within the depleted band; stress relief would occur by the formation of radial cracks within the SiC depleted zone.

4. Commercial Boride Z

The oxidation of samples of Boride Z, a commercial ZrB₂ MoSi₂ composite which contains SiC and Mo dissolved in the ZrB₂ lattice, was evaluated over the temperature range 1550° to 1950°C for comparison to Material V. The oxidation data are presented in Table 54 and Figure 59. The commercial material is found to have oxide recessions of 3, 6, 12, 25 and 32 mils after one hour exposures at 1600°, 1700°, 1800°, 1900° and 1950°C, respectively. These values are about half as large as for Material I (ZrB₂) and 5 to 10 times larger than for Material V (ZrB₂ - 20 v/o SiC).

Typical photographs and microstructures of the oxidized Boride Z specimens are given in Figures 86 to 89. The macrophotographs are generally comparable to those of Material V; there is less evidence for the formation of a glassy oxide phase and the outer oxide is observed to become very porous at 1950°C.

Microstructures of the oxide matrix interface are given in Figure 87; the oxides are adherent after exposures up to 1900°C. Some difficulty was encountered in the metallographic preparation of the interface region, accounting for the apparent oxide detachment from the matrix. Representative reticule and matrix photomicrographs are shown in Figures 88 and 89, respectively.

5. Material VIII ($ZrB_2 + 30 \text{ v/o Graphite} + 14 \text{ v/o SiC}$)

Oxidation screening has been carried out on two pressings of Material VIII. The first (D0498) employed Regal 330R carbon having a particle size of 200Å. The second (D0592) employed Poco graphite milled to 325 mesh; microstructures of this pressing reveal a graphite particle size of 5 to 20 microns. The screening results are given in Table 55 and Figure 60; the latter also contains oxidation data for Material XII to be discussed in the following section.

The pressing prepared with Regal carbon exhibits recessions considerably lower than Material I and corresponding to 8 mils per hour at 1800°C and 12 mils per hour at 1980°C. The latter value is comparable to those obtained for Material V. A specimen run at 2180°C was completely oxidized. Further oxidation screening runs have been scheduled to provide a more complete evaluation of this material.

In contrast, the pressing prepared from Poco graphite yields oxidation data comparable to Material I up to 1800°C. Some improvement over Material I is observed at higher temperatures where a one hour recession of 75 mils is obtained at 1970°C; this is about six times greater than for the pressing containing Regal graphite. A specimen run for one hour at 2000°C was completely oxidized.

Representative post oxidation microstructures of the two pressings are given in Figures 90 to 92. The Regal graphite containing material yields a

glassy outer oxide at 1820°C, Figure 90 and a tight, uniform oxide at 1980°C. The Poco graphite containing material yields a slightly puckered outer oxide at 1800°C and a distorted persus exide at 1970°C. The interface pictures presented in Figure 91 depict a very porous depletion zone (between the original matrix and the oxide) in the Regal graphite material and a uniform depletion (much like observed for Material V in Figure 82) in the Poco graphite material. Representative matrix photographs of the two screening materials are presented in Figure 92.

6. Material XII (ZrB₂ + X v/o Graphite)

Three pressings of Material XII have been screened. The oxidation results are given in Table 56 and Figure 60. The pressings represent the following formulations:

 $D0561 - ZrB_2(I02A) + 50 \text{ v/o Poco graphite}$

D0572 - ZrB2(I03A) + 5 v/o Thornel 25 graphite yarn

 $D0585 - ZrB_2(107) + 20 \text{ v/o Poco graphite}$

In the ensuing discussion, these will be referred to as the 50, 20 and 5% mixtures. The 50% mixture yields very high oxidation rates at all temperatures over the range 1600° to 2000°C. It is likely that the oxidation experiments carried out were either air supply or diffusion limited; the data points presented in Figure 60 therefore represent minimum values. The 20% and 5% mixtures yield oxidation data which is essentially the same as Material I. The presence of graphite in these specimens does not appear to have an effect on oxidation behavior.

Representative photomicrographs of the various oxidized specimens are presented in Figures 93 to 96. The macrophotograph of the 50% mixture after exposure at 1800°C. Figure 93, shows a uniform outer oxide containing numerous pits or blow holes. This oxide proved to be very fragile and could easily be crumbled away from the matrix core. The outer oxides of the 20% and 5% mixtures are similar in appearance and exhibit a somewhat flakey oxide; in addition, that corresponding to the 5% mixture contains some large blow holes. The interface photographs of the 20% mixture, presented in Figure 94 show a tight adherent oxide matrix interface. The specimen treated at 1860°C for 30 minutes exhibits a much larger oxide grain size with considerably more porosity than does the specimen treated at 1800°C for one hour. In both cases, the matrix exhibits a band adjacent to the oxide which is depleted in graphite. The oxide is detached from the 5% mixture specimen and is definitely nonadherent in the case of the 50% mixture.

The extent of oxidation at 1800°C for the 50% and 20% mixtures is shown in the longitudinal reticule photographs presented in Figure 95. The zone depleted in graphite is clearly evident in the 20% mixture photograph. Representative matrix photographs of the three pressings are presented in Figure 96. The second phase observed in the 5% mixture specimen (Plate 1-5962) is believed to be an impurity phase present in the ZrB₂ powder.

7. Material X ($ZrB_2 + 20 \text{ v/o SiB}_6$)

Oxidation screening of 7 rB2 with a SiB6 additive phase expected to improve oxidation resistance was screened over the temperature range 1700° to 1900°C. The results are given in Table 57 and Figure 61; the latter also includes data obtained for selected high pressure hot pressed specimens of Material X and for Material XI to be described later. The oxidation data for the high pressure hot pressed materials is given in Table 58.

The oxidation behavior of the conventionally hot pressed material is essentially the same as for Material I. The high pressure hot pressed material presents a slightly lower level of oxidation and also exhibits preferential oxidation of the additive phase resulting in a depleted band between the oxide and the matrix.

Typical microstructures of the oxidized specimens are given in Figure 97. The outer oxide is dense and uniform. The oxide forms an adherent interface with the matrix. The grain size and distribution of the additive phase is shown in the matrix photograph.

8. Material XI (ZrB₂ + 8 v/o Cr)

A limited amount of oxidation data was collected on high pressure hot pressed specimens of Material XI, in which the chromium was expected to act as a grain boundary binder phase. The oxidation results are given in Table 58 and Figure 61. At 1700°C, the one hour oxidation of Material XI is twice that of ZrB₂; the two materials have approximately equivalent oxide recessions at 1850°C. It was determined that the oxidation behavior of Material XI did not fulfill original expectations and no further screening was carried out.

9. Material II (HfB₂)

Specimens of hafnium diboride prepared from three separate powders were tested over the range 1600° to 2050°C; the experimental results are presented in Table 59 and Figure 62. Samples from the three powders (II05, II06 and II07) all yielded equivalent oxidation results; furthermore, the various screening structures prepared from II05 powders all yielded comparable behavior, precluding a ranking in order of oxidation resistance.

The data yield a logarithmic variation of the one hour recession values with temperature over the entire range of testing. One hour boride recessions of 5, 12, 28 and 70 mils were observed at 1700°, 1800°, 1900° and 2020°C, respectively. These values are very similar to data obtained in another current study for the entire temperature range investigated (5). Two experiments carried out near 2000°C involved air flow rates of 0.2 and 0.5 ft/sec STP. The boride recessions were lower than average in both cases, indicative of air supply limited oxidation behavior. For comparable temperature ranges (1550° to 1800°C), the oxidation resistance of HfB2 is about twice that of ZrB2.

Representative photomicrographs of the oxidized specimens are presented in Figures 98 through 103. The outer oxides shown in Figure 98 are tight, dense and adherent for exposures up to 1800° C; at 1900° C, the oxide becomes very porous. The interface pictures in Figure 99 show adherent oxides for specimen exposures up to 1800° C; the oxide consists of equiaxial grains at all temperatures with a grain size comparable to that of the diboride matrix. Oxide porosity increases with temperature and is especially pronounced after 1900° C. Reticule pictures of a specimen oxidized at 1810° C are shown in Figure 100; diboride conversion to oxide is very uniform. The matrix structure of the same specimen is shown in Figure 101. For comparison, various pictures of an oxidized specimen prepared from the evaluation lot of II06 powder are given in Figures 102 and 103. The latter specimen exhibits smaller matrix and oxide grain sizes than does the equivalently screened specimen prepared from II05 powders. Other metallographic features of the two materials are comparable.

10. Materials III (HfB₂ + 20 v/o SiC) and IV (HfB₂ + 35 v/o SiC)

The oxidation screening results for the temperature range 1800° to 2100°C are presented for formulations of HfB2 and SiC in Tables 60 and 61, Figures 63 and 64. These data show a 15 to 20 times improvement of oxidation resistance over that of unalloyed HfB2. On the average, the oxidation data for Material III show a slightly lower recession than was obtained in studies carried out in a concurrent program (5). This slight difference is not considered to be significant. A limited number of tests carried out for Material IV show an increased protection above 2000°C relative to Material III. The HfB2 + SiC materials are about twice as protective as previously reported (3) and exhibit 3 to 4 times the protection that is afforded by Material V (ZrB2 + SiC). Silicon carbide recessions of Material III and IV as well as V are equivalent. As with the previous materials, it is not possible to rate the effectiveness of protection for the selected screening structures.

Representative microstructures of the oxidized specimens are presented in Figures 104 to 111. The outer oxides, Figures 104 and 108 are dense and adherent at all temperatures examined; the oxides are definitely glassy at the lower temperatures but lose this characteristic and become somewhat roughened at 2100°C. In contrast, Material V loses the glass forming property and becomes roughened at 1960°C, Figure 81. The interface pictures show good adhesion between the oxide and the matrix, which in all cases is depleted of SiC. The oxide is detached from the matrix in the case of Material IV at 2100°C, Figure 109. This separation probably occurred as a result of differences in thermal expansion between the oxide and matrix. The matrices of Material IV show more porosity than can be accounted for by SiC depletion alone; the additional porosity is a result of grain pullout during metallographic preparation.

Reticule photographs of the longitudinal and transverse sections of specimens oxidized at 1950°C are presented in Figures 106 and 110. Radial type cracks are observed in the photographs of the Material III specimens which, as described previously, are attributed to circumferencial stresses developed in the SiC depleted matrix zone during specimen cooling. Matrix photomicrographs of the same specimens are shown in Figures 107 and 111. The excessive grain pullout

within the depleted zone of Material IV, which is believed to occur during metallographic preparation, is clearly evident in the low magnification interface picture presented in Figure 111. Since Material IV contains 35 v/o SiC, it is likely that there are localized interconnections of SiC grains enhancing the likelyhood of grain pullout.

11. Material VI (HfB₂ + 4 v/o Hf-27Ta)

Oxidation screening was carried out over the temperature range 1750°C to 1950°C; the results are presented in Table 62 and Figure 65. The oxidation results yield slightly higher conversion values than for unalloyed HfB2. For comparison, a few additional oxidation runs were carried out on high pressure hot pressed specimens. The results, which are given in Table 58 and Figure 65 are exactly comparable to the conventionally hot pressed material.

The characteristics of the outer oxide shown in Figure 112 are very similar to those observed for unalloyed HfB2 at equivalent temperatures. Selected microstructures of the oxidized specimens are shown in Figures 113 to 115. Oxide adherency to the matrix is maintained at room temperature in specimens exposed at temperatures up to 1875°C; the oxides of the 1875° and 1960°C test specimens are very porous. The distribution of the additive phase, believed to be a carbo-boride of the original Hf-27Ta alloy phase, is shown in the matrix photographs, Figure 115. No evidence was found for preferential oxidation of the converted additive phase.

12. Effect of SiC Content on Boride Oxidation

To determine the effect of silicon carbide content on boride oxidation, a series of oxidation experiments have been carried out at 1800°, 1950° and 2100°C on Material III specimens containing 10 v/o SiC and Material V specimens containing 5, 10, 15, 35 and 50 v/o SiC. The results are presented in Table 63.

The boride and SiC depletions of Material III specimens containing 10 v/o SiC are two times greater than for specimens containing 20 v/o SiC at 1800°C and are approximately the same at 2100°C; these data are presented in Figure 116. In the case of Material V, Figure 117 the one hour boride recession is lowest in specimens containing 35 v/o SiC; observed recessions are 2, 3 and 33 after one hour exposures in air at 1800°, 1950° and 2100°C, respectively. The specimens containing 50 v/o SiC yield low one hour recessions (3 and 6 mils) at 1800° and 1950°C, but are completely oxidized at 2100°C. Addition of 15 v/o SiC show behavior comparable to the data presented for Material V while the 5 and v/o additions are less oxidation resistant.

It is concluded that additions of 35 v/o SiC to both ZrB₂ and HfB₂ provides the greatest protection for the temperature range 1800° to 2100°C while reasonable good protection can be maintained with SiC contents as low as 15 v/o for ZrB₂ and 10 v/o for HfB₂.

13. Occurrence of Gross Cracks in SiC Depleted Zones in Materials III, IV and V

Several of the reticule section photographs of Materials III, IV and V (for example, Figures 85 and 106) exhibit cracks within the SiC depleted matrix zone; the cracks are generally normal to the oxide matrix and SiC depleted - undepleted matrix interfaces. It has been suggested that the cracks form as a result of circumferential tensile stresses within the depleted matrix which are generated during the specimen cooldown after an oxidation exposure due to differences in thermal expansion between the depleted and normal matrices. In this event, cracking would be expected only for the cases where a diboride plus SiC core is still present in the oxidized specimens.

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The interpretation is supported in part by an examination of the longitudinal and transverse section photographs of all oxidation specimens of Materials III, IV and V for the presence of cracks. Pictures requiring a marginal judgement were disregarded. The following results were obtained.

a. Specimens Partially Depleted in Silicon Carbide

	Material		
	$\overline{\mathbf{n}}$	<u>ıv</u>	<u>v</u>
Total Number	29	4	28
Number Cracked	15	8	14
Frequency of Crack			
Formation - %	52	50	50

b. Specimens Completely Depleted in Silicon Carbide

	<u>Material</u>			
	111	IV	<u>v</u>	
Total Number	15	2	4	
Number Cracked	3	0	0	
Frequency of Crack				
Formation - %	20	0	0	

Half of the specimens of each material were found to have cracks in the depleted matrix zone when a diboride SiC core is present, but only 3 of 21 specimen sections were found to have cracks when SiC depletion was complete.

D. Summary

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A summary of the observed screening material recessions after one hour exposures in flowing air is given in Table 64. Three distinct levels of oxidation resistance are represented. The first, including Materials I, VIII (Poco graphite) X, XI, XII and the commercial zirconium diborides have good resistance in comparison to other refractory materials and are useful for one hour exposures to 1800°C. A second level is represented by Materials II, VI, VIII (Regal graphite) and by commercial Boride Z which are twice as protective as ZrB2 and can be employed up to temperatures of about 2000°C. Finally, ZrB2 and HfB2 containing SiC present in amounts of 20 to 35 v/o (Materials V, III and IV) provide an order of magnitude reduction in oxide conversion compared to HfB2. These mate ials can be used for one hour exposures at temperatures up to 2100°C or higher for shorter times.

IX. THERMAL STRISS RESISTANCE

A. Introduction

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The failure of ceramic materials under stresses induced by thermal gradients is well known. One of the objectives of the present investigation of diboride materials is to develop a thermal stress resistant material without significant loss of high temperature thermal and mechanical stability and exidation resistance.

Laboratory thermal stress resistance measurements under steady state heat flow conditions are being performed to provide an experimental relative rating of the materials and microstructures under evaluation in Phase Two of this program. Such data will be used to assist in the selection of the microstructures which will be fabricated as six inch diameter discs in the final phase of the program. The thermal stress resistance data will also be useful in the selection of the materials to be evaluated in transient heating conditions of simulated hypersonic flight leading edge specimens (19).

Additional dynamic thermal stress resistance data for materials developed in this investigation are being generated under a concurrent Air Force program at ManLabs, Inc. (5). A variety of candidate high temperature materials are being characterized by performance in hot gas/cold sample are plasma evaluations over a wide range of stream conditions and time exposures. Extensive background information is needed to fully understand the significance of these evaluations; consequently, the results are not presented herein, but are described in detail in the reports of the other program.

B. Experimental Evaluation of Steady State Thermal Stress Resistance

1. Introduction

A primary consideration in the use of brittle materials in high temperature applications is the resistance of the material to thermal stress fracture. These stresses arise from the requirement for displacement accommodation of body elements when they undergo different thermal dilations due to temperature variations in the body. In a ductile material, accommodation of thermal stresses result from a combination of plastic and elastic strain; fracture does not usually occur since the induced plastic strain is normally only a small percentage of that needed for fracture. On the other hand, in brittle materials, the accommodation can only result from elastic strain and catastrophic failure will result when strains of the order of 0.01 to 1 per cent develop, depending on the mechanical properties of the material. However, as temperature is increased, a point is reached where formerly brittle materials will exhibit enough plastic flow to significantly increase their ability to accommodate thermal strain. This tendency will first appear under slow heating or low strain rates and as temperature is further increased, it appears at increasingly higher strain rates (20).

When significant plastic flow does occur, simple thermoelastic theory will underestimate the thermal stress resistance of the material. In order to completely define the potential of a material under conditions where such stress relaxation occurs, the stress strain behavior of the material as a function of temperature and strain rate must be known. Although such an approach is desirable, its use in a materials development program is usually prohibited by the time and cost involved in obtaining the property data required. For materials that behave elastically, the resistance of a material to thermal stress can be calculated much more readily from the thermal and mechanical properties of the material, but measurement of the thermal stress resistance greatly reduces the number of measurements that must be made and gives a more reliable result.

Two general types of tests for the resistance of materials to thermal stress are commonly used. In one, the extent of damage (e.g., spalling or strength loss) is measured after application of thermal exposures standardized as to severity and number. These tests provide a measure of the characteristic referred to as "thermal-shock-damage resistance" (21). In the other type of test, the exposure conditions necessary to initiate fracture are measured directly. This type of test yields data on a characteristic referred to as the "thermal-shockfracture resistance" or thermal stress resistance (21). The first type of test involves the tacit assumption that fracture may occur. However, the extent of damage measured is governed by those physical properties of the material which affect the propagation of cracks once nucleated. Such a test is limited in value to specific applications and is quite unsuited for general evaluations of structural materials in which even a small crack can act as a stress concentrater and must be avoided. Thus, a thermal stress test which is to provide quantitative data for structural materials must be one that measures the conditions for crack initiation. This type of test can have broad utility and can provide data having clear significance.

By considering simple shapes in a variety of thermal stressing situations, analytical descriptions have been developed for the conditions to initiate fracture of a brittle material. These descriptions show that no single parameter or test value is a suitable index to rate a materials resistance for all conditions of thermal stressing. Material properties that affect thermal stress resistance are thermal expansion coefficient, Young's modulus, strength and, depending on the situation, Poisson's ratio, thermal conductivity, diffusivity and emissivity and where plastic strain occurs, the stress strain behavior as a function of temperature and strain rate. The shape and sometimes the size of the specimen also have significant effects.

Analyses for different conditions result in the following three parameters that can be used to rate the thermal stress resistance of material under conditions where plastic strain is insignificant:

$$R_1 = \frac{\sigma_f}{E \alpha} \tag{1}$$

$$R_2 = \frac{\frac{\sigma_k}{i}}{E\alpha} \tag{2}$$

$$R_3 = \frac{\sigma_1^a}{E\alpha} \tag{3}$$

Where

C = fracture stress

E = Young's modulus

a = linear coefficient of thermal expansion

k = coefficient of thermal conductivity

 $a = \frac{k}{\rho c_p} = \text{thermal diffusivity}$

 ρ = density

cn = specific heat

Conceptually, the critical conditions for fracture f is defined by the simple product relation, f = P. S, where R is the appropriate material parameter, R_1 , R_2 or R_3 and S is a corresponding parameter dependent only on specimen geometry or size. R_1 applies when fracture results from an extreme thermal shock, in which case f is the instantaneous surface temperature change, ΔT_f , of an object initially at uniform temperature and suddenly immersed in a medium at a different temperature. R_2 is the proportionality factor for the steady heat flow, W_{\max} , that will cause a sufficient temperature gradient to induce fracture. R_3 applies to the minimum constant rate of surface temperature changes, ψ_f , that will cause fracture.

These relations only apply when plastic strain does not occur and they do not cover all possible conditions. For example, in the case of a shape at a uniform temperature immersed suddenly in a medium at a lower temperature, the relation $\Delta T_f = R_1 S$ holds only when Biot's modulus' is greater than about 20 (22). If Biot's modulus is very small $\Delta T_f = R_2 S$ is applicable, but for intermediate values of β , ΔT_f is not directly proportional to any of the three material parameters. Manson (23) has developed an expression, however, for ΔT_f in terms of R_1 , R_2 and r_m h for all values of β .

$$\beta = \frac{r_m h}{k}$$

where

rm = normal distance from center, midplane or axis to surface of specimen

h = coefficient of heat transfer between surroundings and surface

k = coefficient of thermal conductivity

Biot's modulus is the surface heat transfer ratio defined by:

Poisson's ratio has not been included in the material parameters R₁, R₂ and R₃ even though it is a material property than can affect thermal stress resistance. The analyses indicate that the nature and extent of the influence of Poisson's ratio depends solely on the shape under consideration. Therefore, it has been considered as a property of the shape rather than of the material and is included in the shape parameter, S. This requires an assumption that Poisson's ratio does not vary significantly, which is a good approximation in the case of dense ceramic materials.

2. Experimental Methods

A simple experimental technique has been developed for quantitatively measuring the R_2 parameter directly; this method does not require prior knowledge of the thermal and mechanical properties of the test material (24-26). R_1 and R_3 values can be determined readily from R_2 from the following relations:

$$R_1 = R_2/k \tag{4}$$

$$R_3 = R_2/\rho c_p \tag{5}$$

Under conditions of steady radial heat flow through the wall of a hollow cylinder, the heat flow per unit length at fracture, W_{max} , is the product of the separable parameters R_2 (defined by properties of the material) and S (defined by the specimen shape) where:

$$W_{\text{max}} = R_2.S \tag{6}$$

 $R_2 = \frac{\sigma_{ik}}{E\alpha}$, as defined above

S = a dimensionless parameter describing the shape of the specimen

For a hollow circular cylinder with radii b and a and height h, S depends on b/a, h/a and in some cases also on Poisson's ratio.

The use of this relationship to assess quantitatively the thermal stress resistance of different ceramic materials, i.e., to measure values of R₂ requires the following:

- (a) an apparatus in which hollow cylindrical specimens can be fractured under a condition of radial steady heat flow and in which heat flow per unit length at fracture, W max, can be measured accurately;
- (b) a separate evaluation of the shape factor, S, for the specimens so that the desired material factor, R₂ can be obtained from the relationship:

$$R_2 = W_{\text{max}}/S \tag{7}$$

Past work at Battelle (24-26) has established the validity of the above product relationship and developed an apparatus to provide the required heat flow conditions and values of shape factors for a range of specimen shapes.

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In order to experimentally establish the validity of the product relation given by Eq. (6), groups of well controlled ceramic specimens of two different types (SiC and Al_2O_3) with significantly different shape factors were tested. One group of specimens had a circular inner boundary and a square outer boundary and samples in the other group were hollow cylinders. In both groups of samples, the ratio of the area between boundaries to that enclosed by the outer boundary was about 60 per cent. Some results obtained with specimens having lengths five times their inner radii are shown in Table 65. Failure was always marked by the appearance of a longitudinal crack, which was located at one of the places of minimum wall thickness in the square tubes.

The product relation is tested by computing the SiC to Al_2O_3 ratio for each geometry. If the product relation is valid, the two ratios should be equal. The ratios and their probable errors in the above case are listed in the final column of Table 65. Since the ratios are nearly equal, the results tend to support the theoretically derived product relation given by Eq. (6).

To obtain values of R_2 , the material factor of the ceramic, it is necessary that the shape factor, S, of the specimen be known. Theoretical and experimental analyses at Battelle have yielded values of S for a range of specimen shapes.

Figure 118 gives shape factor values for hollow circular cylinders having radius ratios of 1.5 and 1.7 and of any length. Similar data are available for circular cylinders having a radius ratio of 1.3. Although experimental data are not available for hollow circular cylinders having radius ratios of 2.0, calculation of the shape factor for a thin washer along with extrapolation of the experimental data for thinner walled cylinders gave the data shown for a radius ratio of 2.0. The curve for cylinders having a triangular (equilateral) outer boundary, a one inch diameter circular inner boundary and a solidity of 70 per cent was obtained by extrapolation between the theoretical (26) and photoelastic (27) results for a third washer and the experimental results for two inch long triangular samples of 60 per cent solidity with a 1 inch diameter inner boundary (26).

3. Experimental Apparatus and Procedure

A view of the experimental apparatus used to measure the material parameter, R2, is shown in Figure 119. A cross sectional view of the arrangement of the sample and guard rings around the graphite heater element are provided in Figure 120. This apparatus has been designed to provide a controlled, measurable radial heat flow through the wall of a hollow, cylindrical specimen.

Solidity is the solid cross sectional area divided by the area defined by the outer boundary.

The specimen is aligned concentrically on the heater rod between one or more upper and lower guard tubes. Upon applying power to the heating rod, heat flows radially through the specimen, producing a radial temperature drop and resultant thermal stresses. As the power delivered to the heater rod is increased, the critical tensile stress in the wall becomes greater. In testing, the stress is increased by increasing the power until fracture occurs. The temperature is measured by sighting an optical pyrometer on the outer surface of the specimen and by placing thermocouples near the inner and outer surfaces of the sample. The thermocouple outputs are fed into a two point recorder to obtain a record of the thermal history of the sample and to indicate when steady state conditions are established.

To obtain fracture under steady state conditions, the power to the heater rod is increased in small increments and it is retained after each increment until the outer wall temperature becomes constant. The heat flow (power) per unit length at which fracture occurs (W_{max}) is recorded. This value divided by the appropriate shape factor gives the R₂ parameter which quantitatively describes the resistance of the material to fracture due to thermal stress. No difficulty had been experienced in determining fracture; an axial crack opens which can be readily discerned because of the bright heater rod background. For circular cylinders, the maximum tensile stress occurs at the outer diameter. For a triangular sample, the maximum tensile stress occurs at the outer boundary at the center of the sides of the triangle.

For power measurements, small holes are drilled in the heater rod at points approximately opposite the ends of the specimen and the distance between these holes is measured accurately. A 4 mil tungsten wire is forced into each hole and passed through a small hole drilled in a guard tube. A connection is then made through the base to a Model 300G Ballantine electronic voltmeter which has an accuracy of 1 per cent and is relatively unaffected by high resistance in the measuring circuit. The heater current is passed through the primary of a type RT Westinghouse current transformer with a calibrated primary/secondary current ratio of approximately 800/5. A Model 1954 Weston ammeter with an accuracy of 1/2 per cent is used to measure the secondary current. The power (heat) dissipated per unit length at the gage section of the heater element is the product of the transformer ratio times the current reading times the voltage reading divided by the distance between the voltage leads.

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In past work, a major concern was whether the necessary conditions of radial steady heat flow could be met adequately in the apparatus. As a result, the heater element was made long compared with the specimen length so that the temperature of the center section of the heater rod shows little variation in the axial direction. This feature also minimizes axial conduction in the heater rod and axial heat flow by radiation. Axial conduction in through the guard rings was also found to be insignificant so long as the heat transfer characteristics of the guard ring are similar to those of the test specimen. If the tests are run in an inert atmosphere rather than in vacuum, axial heat flow by convection can also occur. However, heat loss is considered insignificant in the closed space between the heater rod and the sample.

4. Experimental Results and Discussion

The experimental work thus far has consisted of preliminary evaluations to determine the behavior of refractory diborides to thermal stresses resulting from steady state temperature gradients. The objective of these determinations is to define the sample geometry and test conditions necessary to cause brittle failure without appreciable plastic strain. Under these conditions, quantitative thermal stress resistance data can be obtained with measuring the materials properties which fix thermal stress resistance. For comparison purposes, KT-SiC has also been evaluated. The results of the preliminary evaluations are summarized in Table 66.

a. KT-SiC

The KT-SiC samples evaluated for comparison purposes were 1.7 inches outside diameter and 1.0 inch long. Calculation of the factor R2 from the best available property data (28) yielded a value of 4.87 cal/cm sec. Property data at 1315°C were used for this calculation, since strength and modulus data are not available at 1350°C. The range shown in Table 66 for the experimental values of R2 is due to the size of the incremental increases in heat flux. In each case, the lower value represents the highest R2 value at which the sample did not fail and the higher value represents the R2 value to which the sample was exposed when failure occurred. Thus, the actual experimental value of R2 lies somewhere between these values. As shown by the data in Table 66, the calculated and experimental values agree quite well for this material. Figure 121 shows one of the KT-SiC samples after thermal stress failure. The failure was catastrophic, as evidenced by the separation of the broken pieces by the kinetic energy imparted to them when failure occurred. It should also be noted in Figure 121 that some of the free silicon in KT-SiC has beaded on the inside diameter where the temperature was above the melting point of silicon, 1410°C.

b. 1.7 Inch Outside Diameter Diboride Samples

The samples in the first group of diboride samples evaluated were 1.7 inches outside diameter, 1.0 inch inside diameter and approximately 0.75 inches long. Evaluation of Material I, 102 D0364 revealed that the temperature at the inner wall of the sample at the heat flux required to cause failure was between 1700° and 1800°C. Since macroscopic plastic flow has been observed in mechanical tests conducted in this temperature range, it was apparent that lower sample temperatures would be required in order to produce brittle failure under the slow heating (strain) rates used in evaluating the materials under steady state conditions. Several techniques for lowering the sample temperature by increasing the rate of heat transfer away from the outer surface were evaluated. These included (1) coating the outer surface of the sample with colloidal carbon to improve its emissivity, (2) conducting the test in a helium atmosphere to get conductive and convective transfer away from the surface and (3) conducting the tests in a helium atmosphere with a water cooled, carbon coated cylinder near the outer surface to get increased conduction through the helium. The specimen temperature was lowered 100°, 75° and 150°C, respectively, for Techniques 1, 2 and 3 listed above. However, a greater temperature reduction was considered necessary to prevent stress relief due to plastic flow.

c. 2.0 Inch Outside Diameter Diboride Sample

The most convenient way to lower the specimen temperature is to use a geometry that gives a lower shape factor. Since lowering the shape factor lowers the heat flux required to create a critical stress, the specimen temperature is lowered. Therefore, a group of samples 2 inches outside diameter, I inch inside diameter and I inch high was evaluated. Since the shape factor for this size sample is 20, the heat flux required to create a critical stress is 33 per cent lower than for the first group of samples which had a shape factor of 26. Material I, 103A D0539 was evaluated in a helium atmosphere up to an R2 value of 15.0 cal/cm sec using the standard test procedure as described above. This R2 value is about twice the value calculated from thermoelastic theory, but no failure occurred. The sample must have experienced considerable plastic strain. However, the sample did fail while cooling after completion of the test. Since the sample experiences a much lower temperature gradient during cooling than during evaluation, failure probably did not occur as a result of thermal stress caused by a temperature gradient. Rather, failure must have occurred as a result of a stress reversal on cooling caused by plastic strain which occurred during the evaluation followed by elastic behavior on cooling. Such behavior would create a residual tensile stress at the inner wall and apparently this stress exceeded the fracture stress of the material. Since the outer wall temperature at the heat flux required to obtain the calculated R₂ value was approximately 1330°C and that of the inner wall approximately 1500°C; significant plastic strain must have occurred at temperatures of 1500°C and below. Figure 122 shows the sample after failure. As in the case of KT-SiC the pieces of the fractured specimen were displaced as a result of catastrophic failure.

In order to determine whether the creep rate was in a range where, because of strain rate sensitivity, failure could be induced by more rapid heating, sample 103A D0548K (2.0 inch o.d.) was heated at a faster rate. In this evaluation, the specimen was exposed to the heat flux necessary to obtain a material actor of 7.18 cal/cm sec (i.e., 143 cal/cm sec) instantaneously. Under this heating rate, failure occurred in just over 3-1/2 minutes at an outer wall temperature of approximately 1315°C which is approximately the equilibrium temperature for the heat flux employed. Figure 123 shows the sample after thermal stress failure. Failure was catastrophic as in the case of the KT-SiC sample. Although this sample was heated under transient conditions, he temperature gradient established was nearly the same as the one established in steady state heat flow, because of the high thermal conductivity of the sample. The fact that failure occurred on rapid heating is a further indication that significant stress relief due to plastic strain can occur at temperatures as low as 14000-1500°C under the heating (strain) rates normally used in the steady state test. Since sample I03A D0548K (2 inch outside diameter) failed when rapidly heated with the approximate heat flux calculated to cause failure under steady state conditions, the creep rate of this sample was considered insignificant for the resulting heating (strain) rate. A slight modification of this technique was employed in an effort to obtain some quantitative data. The modified technique involved slowly increasing the heat flux until a material factor of one half that calculated to cause failure was attained and then allowing equilibrium to be established. The heat flux was then increased in one increment to that required to give a material factor around three quarters of that calculated to cause failure. After establishing equilibrium, the heat flux was again reduced to the one half level and allowed to

equilibrate. In the absence of plastic strain, repeating this procedure at successively higher heat fluxes (material factors) would serve to bracket the material factor.

In order to evaluate this technique, a 2.0 inch o.d. specimen of Material V, V07 D0571K was tested in a helium atmosphere. The time allowed for equilibrium to be established was 2 minutes for the heating cycle and 2-1/2 to 3 minutes for the cooling cycle. The material factors evaluated and the corresponding temperatures are shown in Table 66. The heat flux was reduced to give a material factor of 3.5 cal/cm sec between each of the levels shown. Failure did not occur during the test nor did failure occur on cooling as a result of residual stress caused by plastic flow during the test. The fact that failure did not occur on heating indicates that significant plastic strain took place during the test and these conditions cannot be used for quantitative evaluation.

d. Triangular Samples

In order to further lower the testing temperature, equilateral triangular specimens with an outer boundary 2.5 inches on a side, 1.0 inch diameter circular inner boundary and 1.0 inch high were evaluated. This geometry reduces the shape factor to 15 which lowers the required heat flux 25 per cent of that for the above 2.0 inch outer diameter samples.

Material V07 D0582K was evaluated in vacuum under steady state conditions. Incremental heat flux increases were made every two minutes which represented a change of approximately 0.50 cal/cm sec in the material factor (R₂) up to 9.5 cal/cm sec; this value is approximately 125 per cent of the material factor where failure would be expected based on available property data and elastic theory. The heat flux was then increased in one increment to change the material factor from 9.5 to 11.1 cal/cm sec and, after 5 minutes, from 11.1 to 12.8 cal/cm sec. No failure occurred during this test, probably because of plastic strain. The sample temperatures at the outer boundary and at the center of the triangular sides were 1240°, 1330°, 1365° and 1475°C for material factors of 7.75, 9.5, 11.1 and 12.8 cal/cm sec, respectively. Since failure should occur at a material factor of approximately 7.75 cal/cm sec, significant stress relief due to creep must have occurred when the outer wall temperature was as low as 1240°C during the time the material was under stress in the experimental run. However, this temperature represents a considerable reduction from the outer wall temperatures of 1650° and 1325°C required to attain the same material factor for the 1.7 inch O.D. and 2.0 O.D. samples, respectively.

In order to further lower the testing temperature, Material V07 D0586K was evaluated under steady state conditions in a helium atmosphere. In this evaluation, the same procedure was used as for sample V07 D0582K except that the incremental increases in the heat flux were such that the change in the material factor was only 0.25 cal/cm sec. In this test, the sample temperatures were 1175°, 1235°, 1320°, 1385°C at material factors of 7.75, 9.5, 11.1 and 12.8, respectively. No failure occurred, probably as a result of plastic strain. At a material factor of 7.75 which is near the value where failure would be predicted based on elastic theory, the inner wall temperature was approximately 1275°C.

Material II05 D595K was also evaluated under steady state conditions in a helium atmosphere. In this evaluation, the same procedure was used as for sample V07 D0586K except that the incremental heat flux increases were made every minute. One other difference in this experiment was the use of samples V07 D0586K and V07 D0582K for guard rings instead of graphite. Since graphite has somewhat different heat transfer characteristics, this difference is probably significant. This sample failed when the material factor was increased from 11.1 to 12.8 cal/cm sec after a 2 minute hold at 11.1 cal/cm sec. Figure 124 shows this sample after catastrophic thermal stress failure and before removal from the test apparatus. Note the relative displacement of the pieces of the sample. The fractured specimen is shown in Figure 125. Since this failure occurred at about 1.5 times the heat flux where failure would be expected based on available property data and elastic theory, significant plastic strain probably took place before failure. However, the creep rate was too slow to prevent the build up of a critical fracture stress for the heating (strain) rate employed.

5. Conclusions and Future Plans

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Analysis of KT-SiC confirmed that steady state thermal stress failure occurs at a material factor near that calculated from property data providing the material behaves elastically while under test. However, preliminary evaluations of several diboride materials having several different shape factors revealed that significant plastic strain occurred at temperatures as low as 1275°C for heating (strain) rates normally used in the steady state technique, which prevented fracture due to thermal stress. This ability to relieve thermal stress by plastic rather than elastic strain is quite significant for these materials, as evidenced by the fact that some samples have withstood twice the heat flux calculated to cause failure in steady state (slow heating rate) evaluations.

In order to obtain thermal stress failure, lower sample temperatures or faster heating rates will be required to cause fracture of simple shapes of the materials to be evaluated. Of these alternatives, lower temperature tests where plastic strain is negligible for the times involved in making a run under essentially steady state conditions is more desirable for making quantitative evaluations of thermal stress resistance. The technique to be used for making lower temperature evaluations is as follows. A thin walled, tight fitting, rubber tube will be placed around the sample and guard rings. The rubber tube will be connected to a concentric brass cylinder and water will be passed between the brass and rubber cylinders to remove the heat conducted through the sample and guard rings. By this technique, outer wall temperatures below 200°C could be attained for the steady state heat lux required to cause failure due to thermal stress. Thus, the probability of brittle failure would be maximized. Aside from a minor change in the attachment of the voltage leads, the only experimental difficulty will be in detecting fracture, which should be detectable with an audio pick up placed on the guard ring below the water cooling jacket.

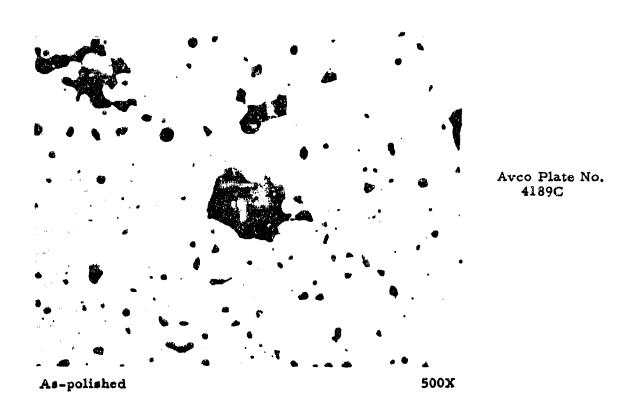
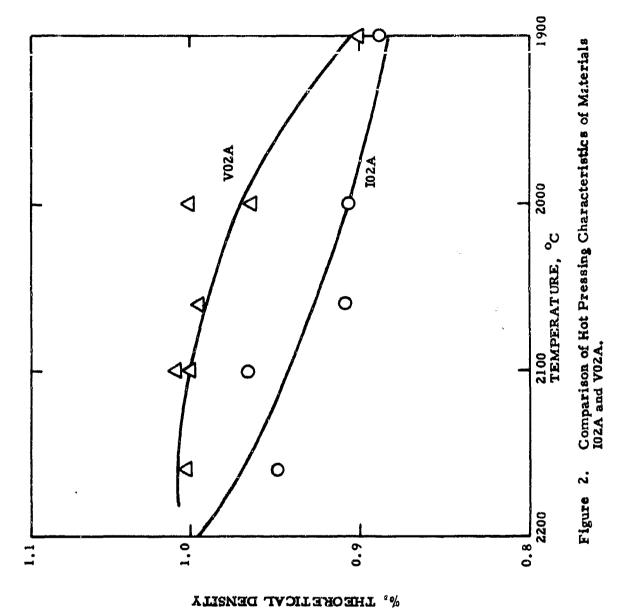
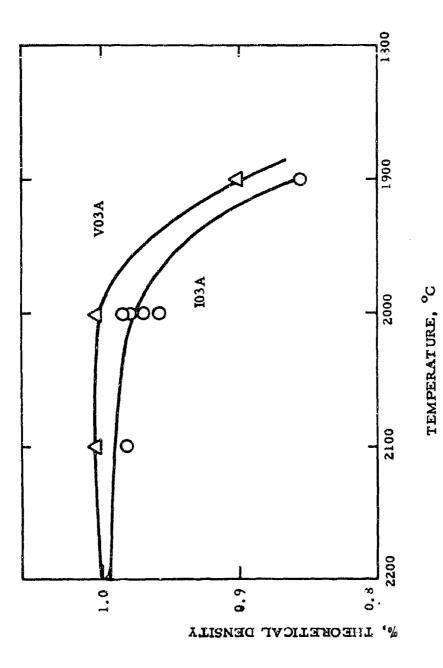
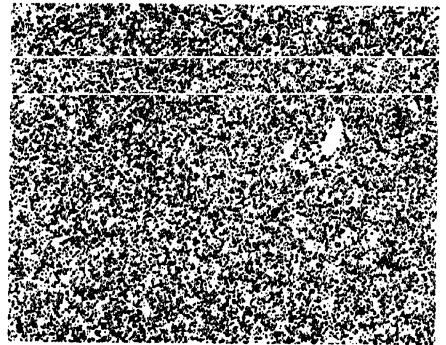


Figure 1. Second Phase Size and Distribution in Hot Pressed Material I. Billet 103A D0308.





Comparison of Hot Pressing Characteristics of Materials 103A And V03A. Figure 3.



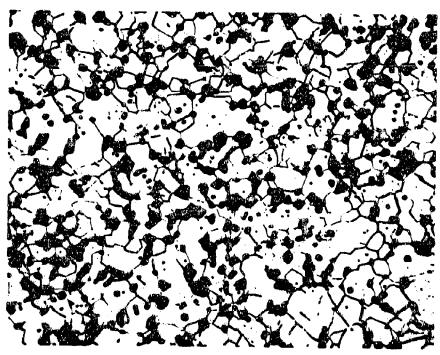
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Figure 4. Distribution of SiC Phase in Diboride Matrix of Material V. Billet V02A D0370.



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Figure 5. Location of SiC Relative to ZrB₂ Grain Boundaries in Material V. Billet V02A D0370.

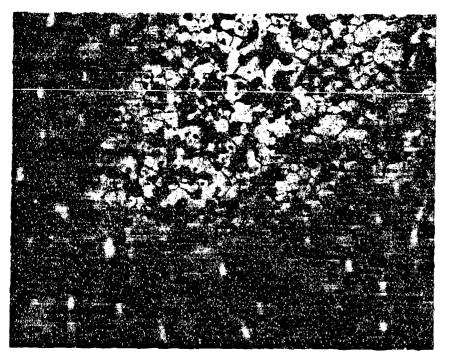


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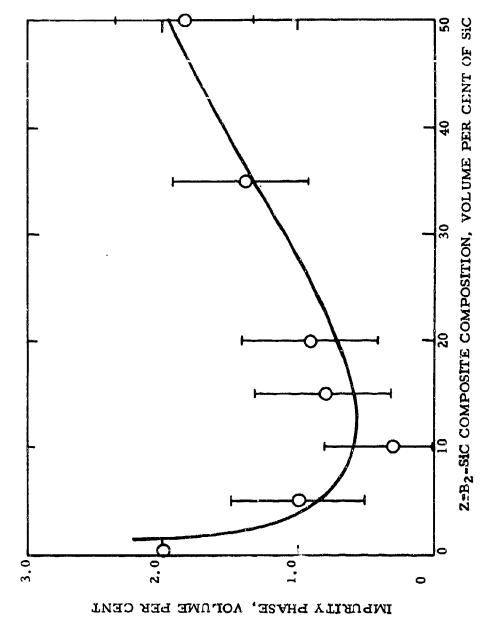
Figure 6. Morphology of Remaining Impurity Phases in Material V02A Demonstrating the Contact Angles Relative to the Other Phases. Billet V02A D0370



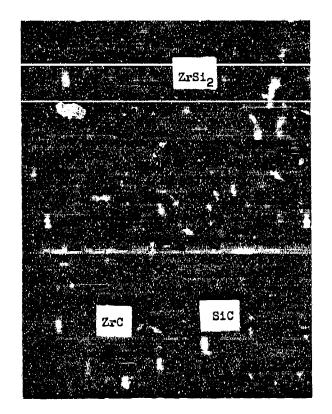
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Figure 7. Morphology of Remaining Impurity Phases in Material VO3A. Billet VO3A D0473.



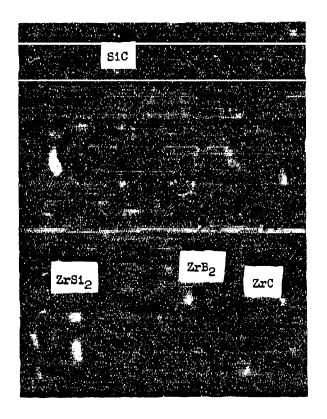
Variation of Impurity Phase with SiC Additions in Material V. Figure 8.



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Figure 9. Distribution of Phases in Special Material Hot Pressed with Starting Powders of ZrO₂ and SiC. Billet D0624.



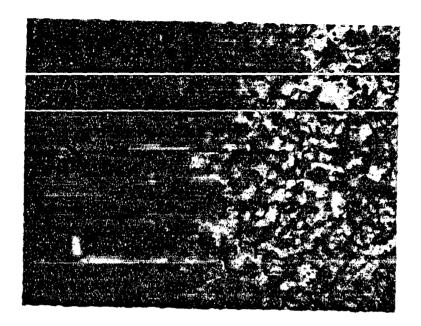
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Figure 10. Distribution of Phases in Special Material Hot Pressed With Starting Powders of ZrB₂, ZrO₂ and SiC. Billet D0626.

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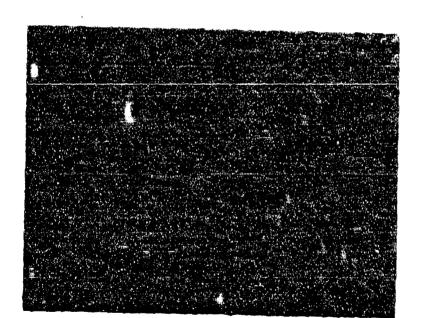


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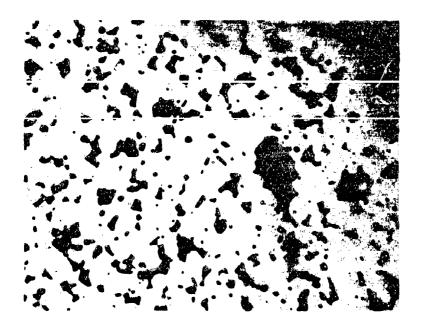
Figure 11. Microstructure of Material VIII Containing Poco Graphite. Billet VIII02A D0592.



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Figure 12. Microstructure of Material VIII Containing Regal Carbon. Billet VIII(17)(15)07 D0620.

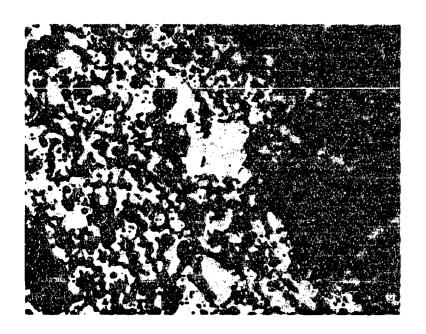


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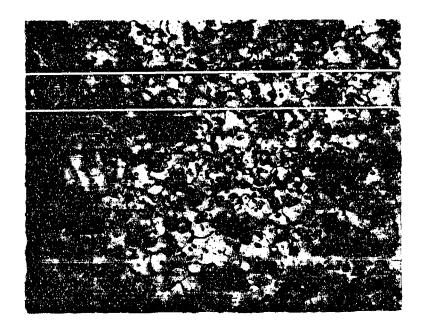
Figure 13. Microstructure of Material X Hot Pressed at 1900°C. Billet X07 D0596.



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Figure 14. Microstructure of Material X Hot Pressed at 1800°C. Billet X07 D0597.

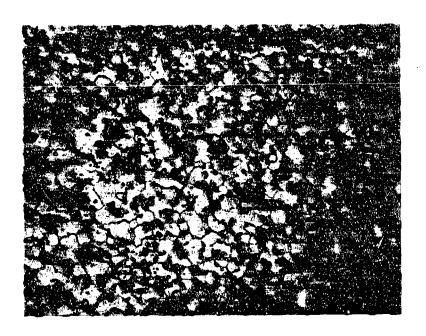


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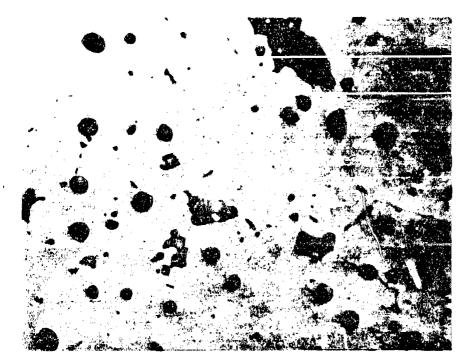
Figure 15. Microstructure of Material XII Containing Regal Carbon. Billet XII(20)07 D0608.



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Figure 16. Microstructure of Material XII Containing Poco Graphite. Billet XII(15)07 D0603.



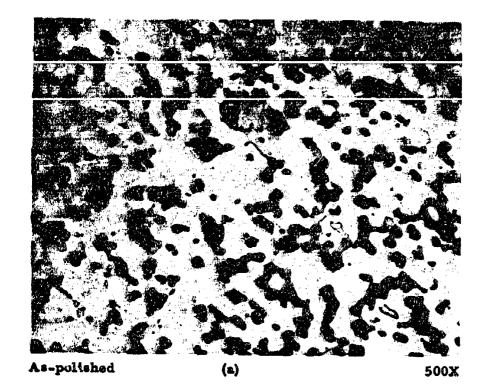
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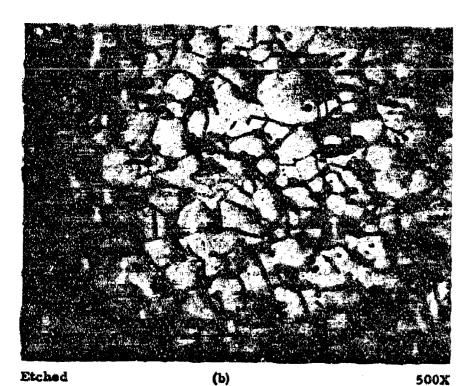
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Figure 17. Microstructure of Material II. Billet II05 D0316.

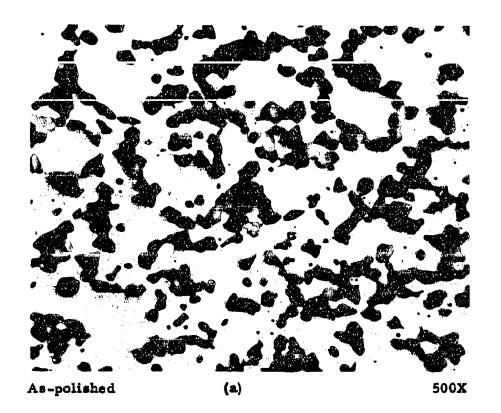


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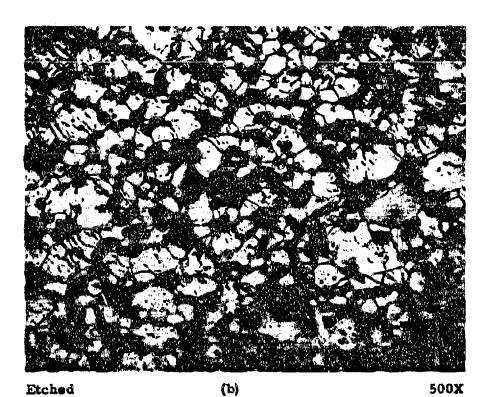


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Figure 18. Microstructure of Material III. Billet III05 D0377.

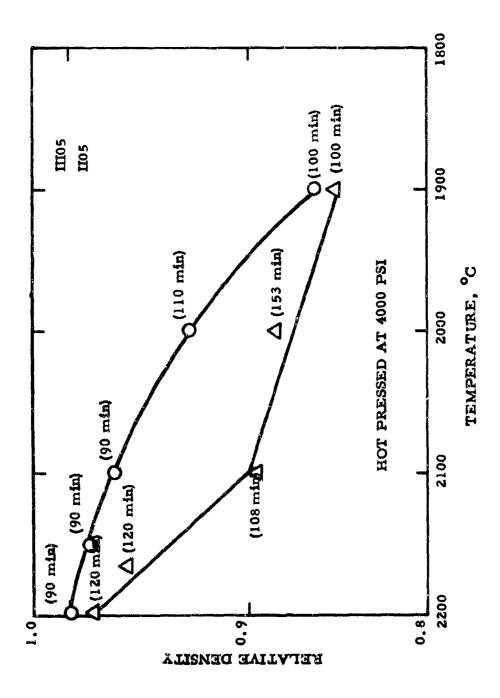


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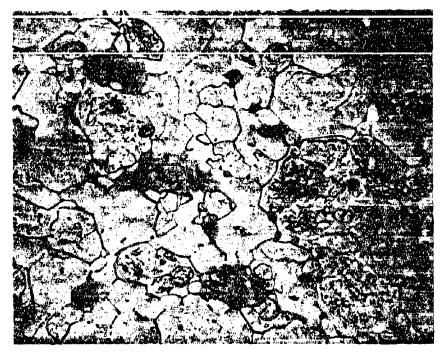
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Figure 19. Microstructure of Material IV. Billet IV05 D0405.



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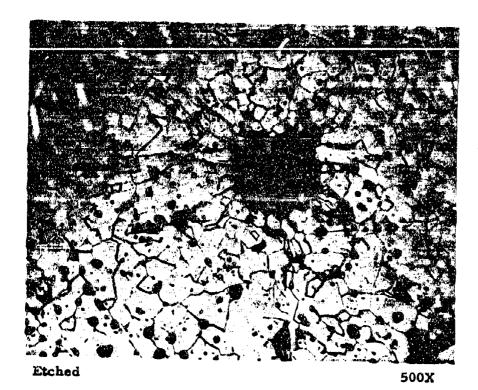
Comparison of Hot Pressing Characteristics of Materials II and III. Figure 20.



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Figure 21. Microstructure of Material VI. Billet VI05 D0462.



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Figure 22. Material Showing Cracks in the Matrix Radially Distributed Around Oxide Inclusion. Billet 103A D0415.

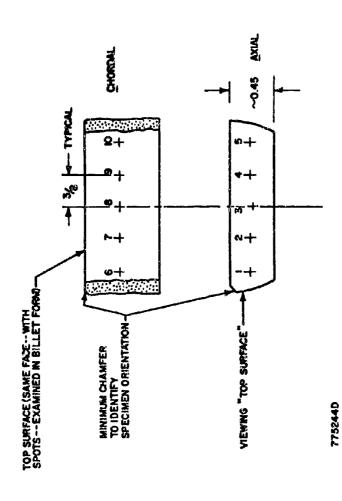
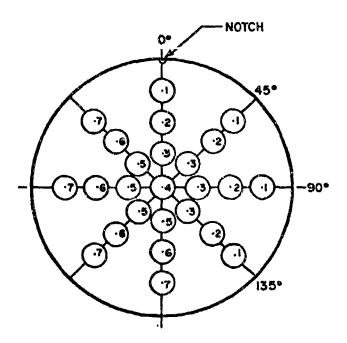
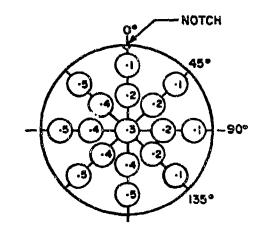


Figure 23. Location of NDT Measurements on Diametrical Slab.





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Figure 24. Location of NDT Measurements on 2-Inch and 3-Inch Diameter Billets,

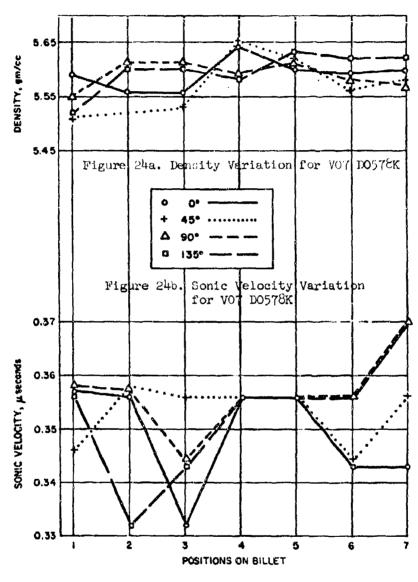


Figure 25. Density and Sonic Velocity Variations in Billet V07 D0578.

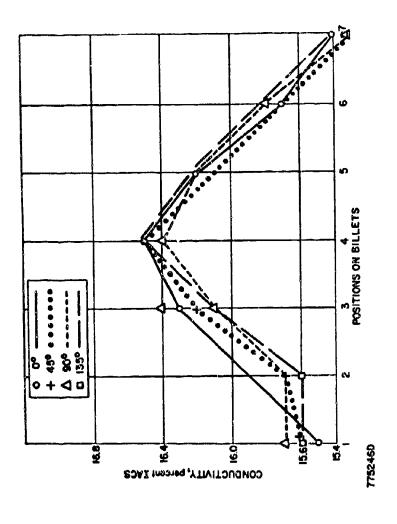
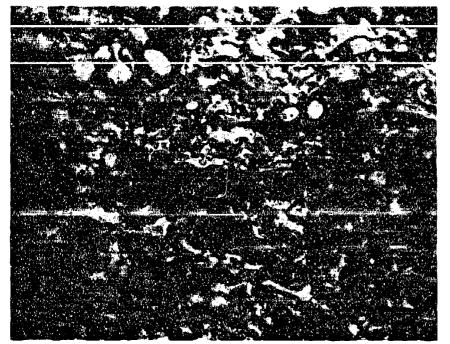


Figure 26. Variation of Electrical Conductivity for VO7 DO578K.



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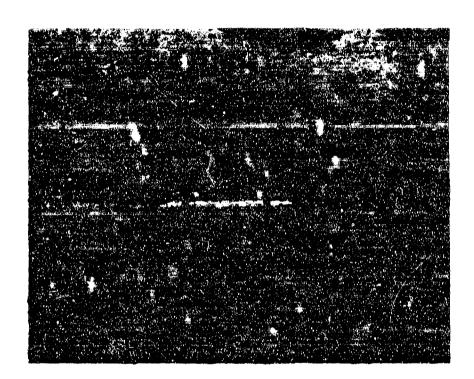
Figure 27. Material I Plasma Sprayed on Stainless Steel. Billet I02A P0162F.

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500X

Etched

Figure 28. Microstructure of Dense Area In Sintered Specimen 103A B0005.



Avco Plate No. 4678-A

As Polished

Figure 29. Representative Microstructure of ZrB₂ Reinforced with Thornel 25 Carbon Fiber, Billet XIIf(5) D0644.

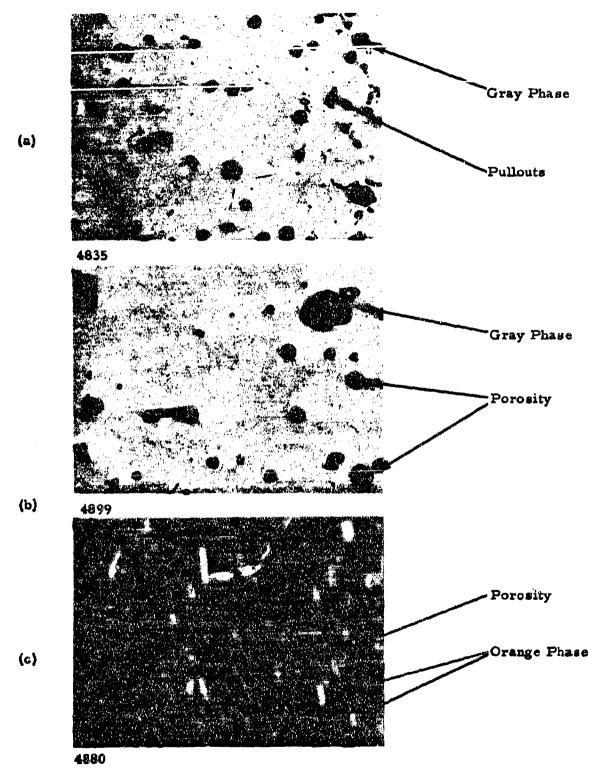


Figure 30. Photomicrographs of Material IO7 D0589, As Polished, 500X:
(a) Original Structure-Area 1, (b) Original Structure-Area 2,
(c) Annealed at 2200°C (Optical) for 15 Minutes.

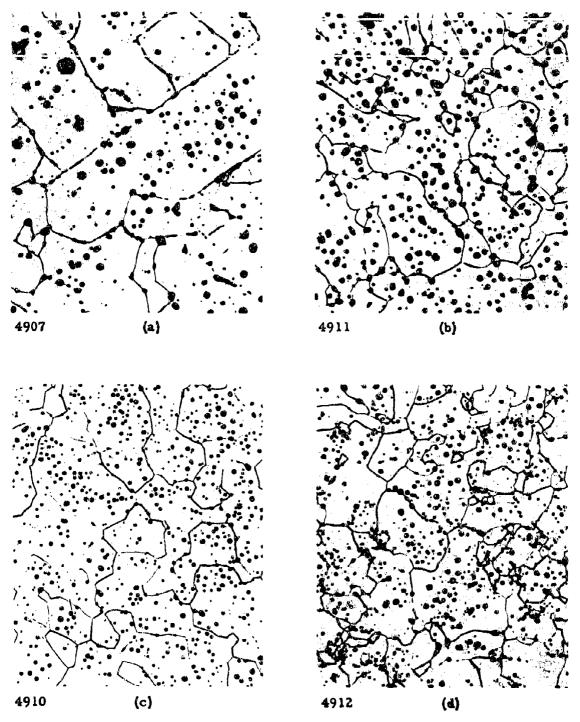


Figure 31. Photomicrographs of Material 107 D0589, Etched, 150X: (a) After Anneal No. 12, (b) After Anneal No. 14, Area 1, (c) After Anneal No. 14, Area 2 and (d) After Anneal No. 14, Area 3.

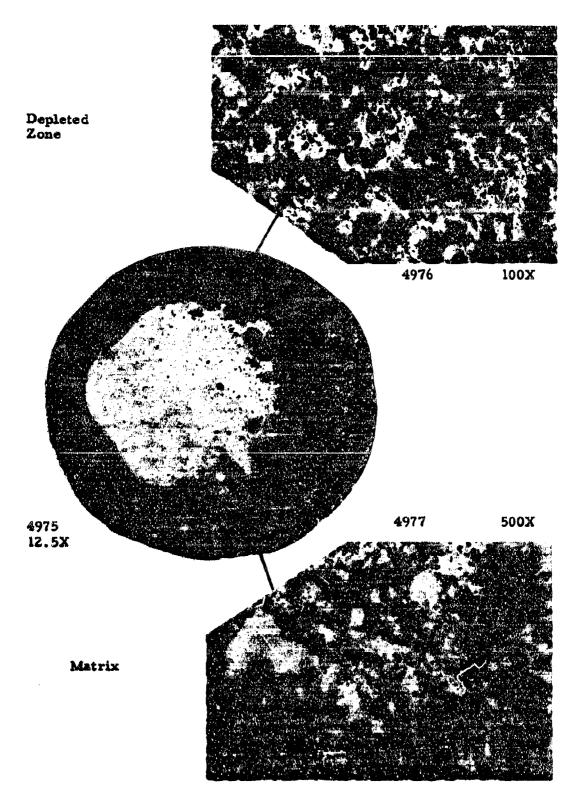
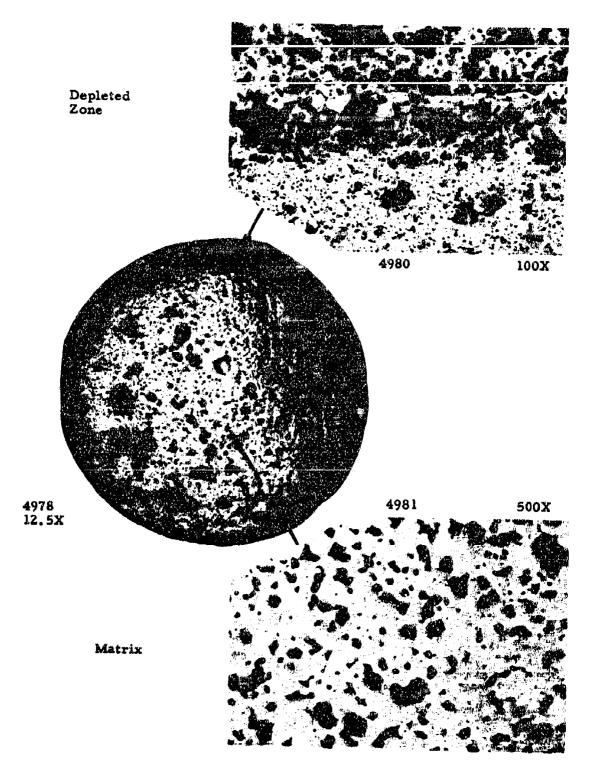
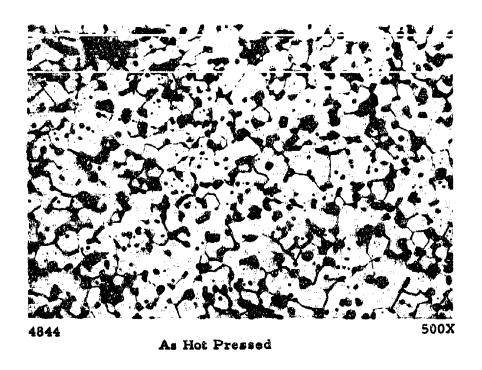


Figure 32. Photomicrographs of Material VIII, D0498, Annealed at 2200°C (Color Temperature) for 15 Minutes.



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Figure 33. Photomicrographs of Material VIII, D0592, Annealed at 2300°C (Color Temperature) for 15 Minutes.



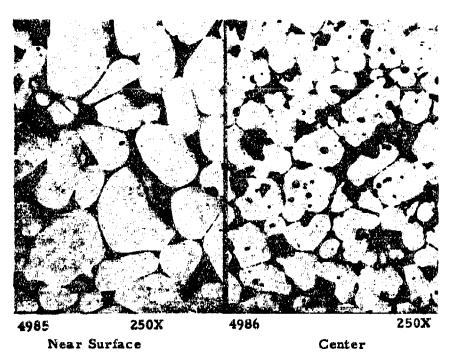


Figure 34. Photographs of Material X, D0596, Annealed at 2200°C (Color Temperature) for 15 Minutes.

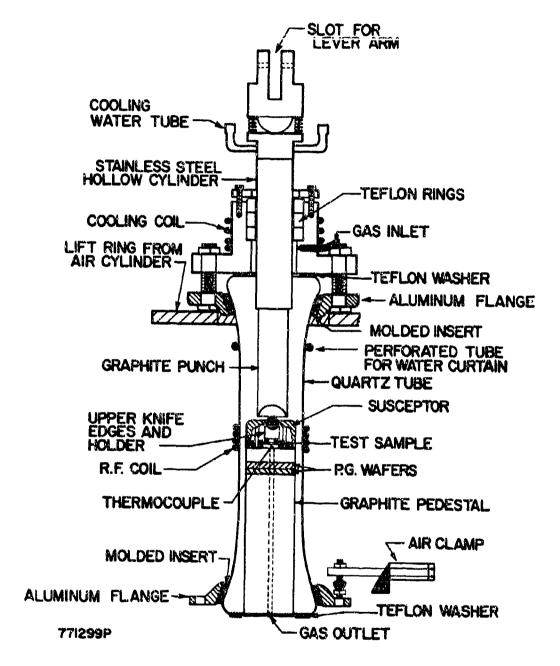


Figure 35. Schematic of High Temperature Lever Arm Bend Test Apparatus.

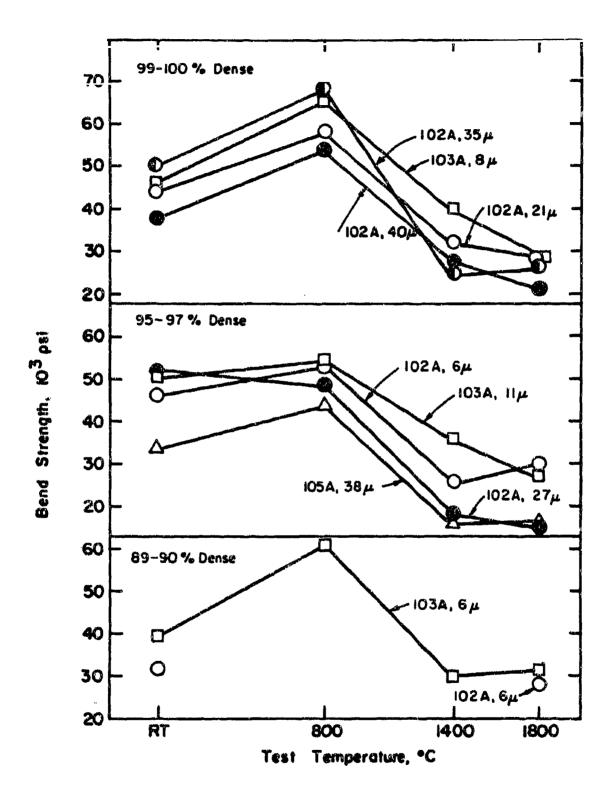


Figure 36. Bend Strength of Material I As A Function of Test Temperature.

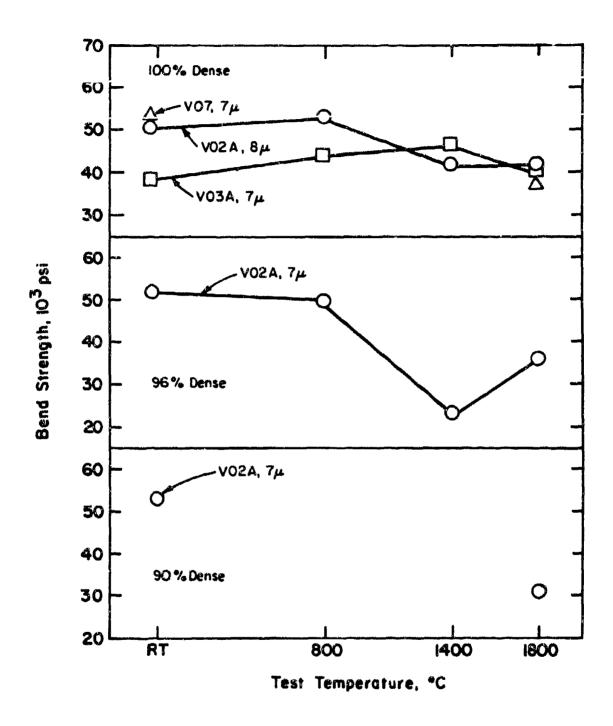


Figure 37. Bend Strength of Material V As A Function of Test Temperature.

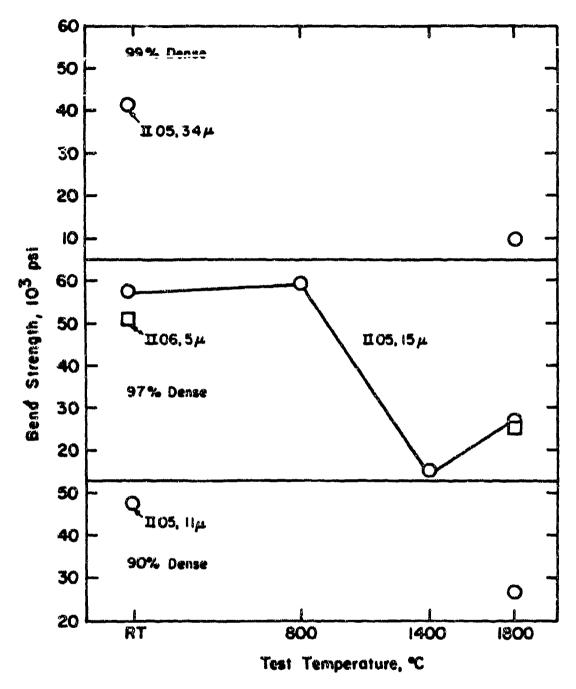


Figure 38 Bend Strength of Material II as a Function of Test Temperature.

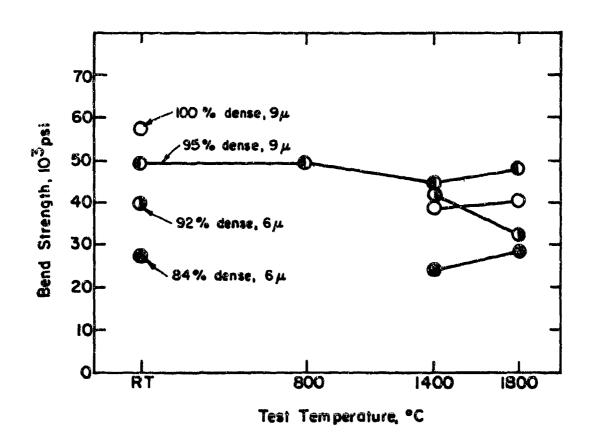


Figure 39. Bend Strength of Material III05 As A Function of Test Temperature.

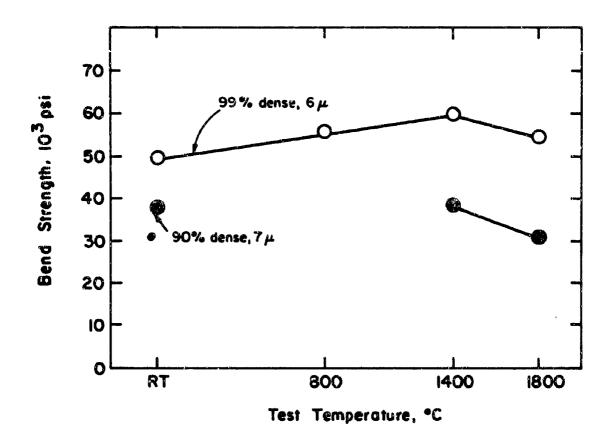


Figure 40. Bend Strength of Material IV05 as a Function of Test Temperature.

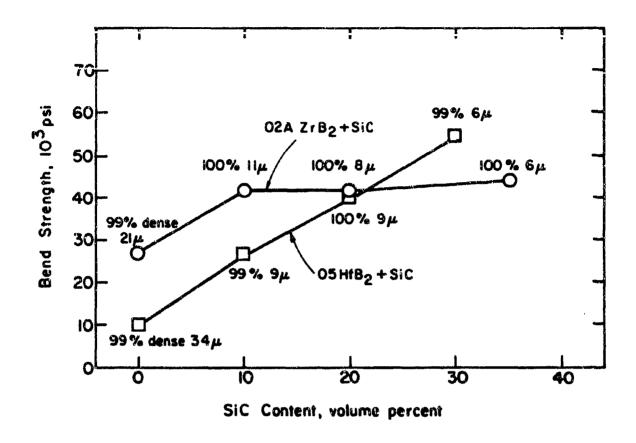
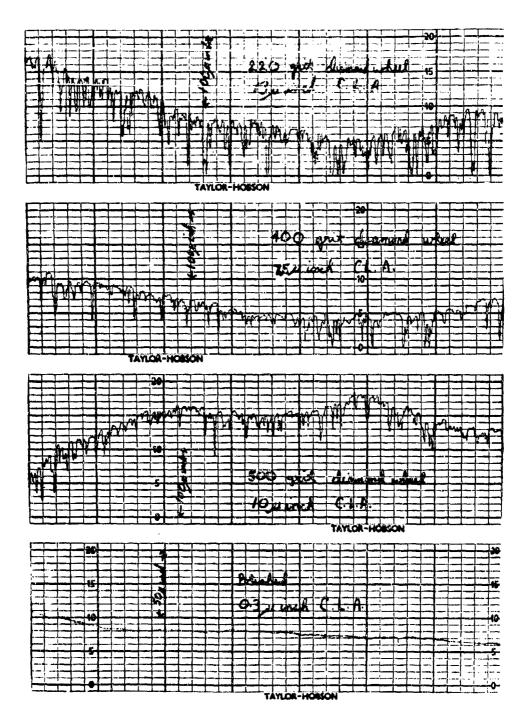


Figure 41. Bend Strength at 1800°C of ZrB₂-SiC and HfB₂-SiC Composites As Functions of SiC Content.



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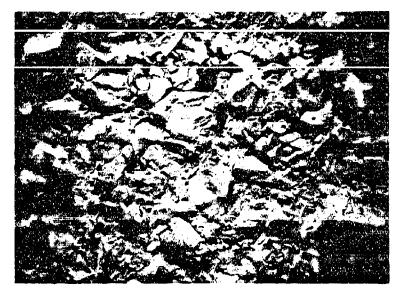
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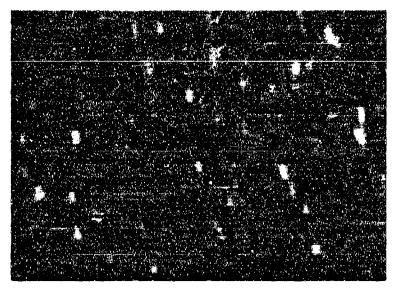
Figure 42. Talysurf Surface Contour Tracers for (a) 220 Grit Finish, (b) 400 Grit Finish, (c) 500 Grit Finish and (d) 0.25 Micron Finish on Billet V07 D0576.



Avco Plate No. 66715

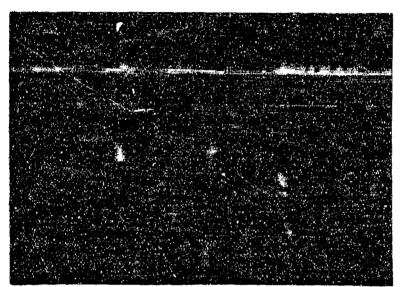
1500X

Figure 43. Electron Micrograph of Surface Structure from 200 Grit Finish on V07 D0576. Note Possible Surface Cracks.



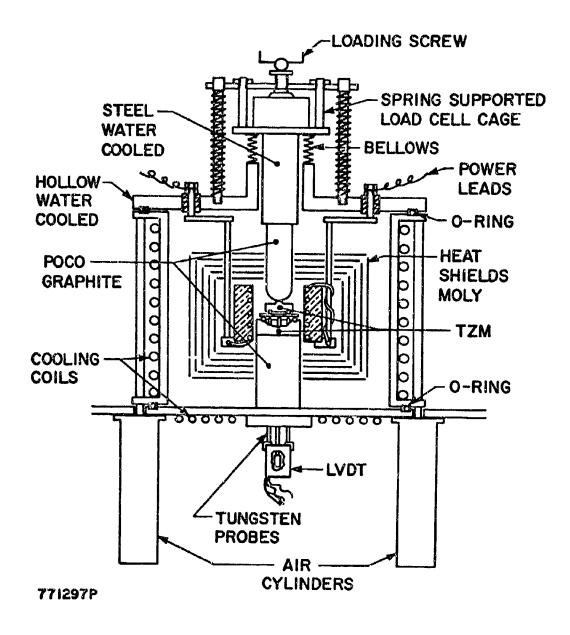
Avco Plate No. 67713

Figure 44. Electron Micrograph of Surface Structure from 400 Grit Finish on V007 D0576.



Avco Plate No. 67709

Figure 45. Electron Micrograph of Surface Structure for 0,25 Micron Diamond on V07 D0576.



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Figure 46. Schematic of High Temperature Apparatus Used for Modulus Measurements.

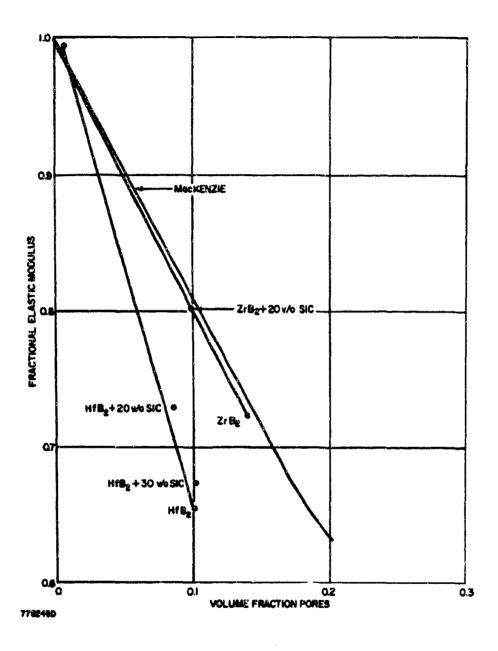
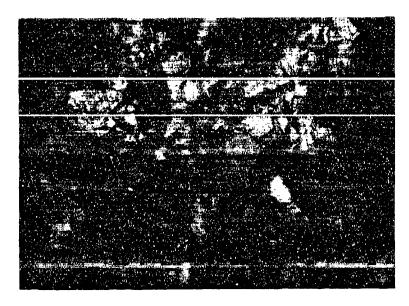


Figure 47. Effect of Porosity on Room Temperature Elastic Modulus for Various Diborides.



Avco Plate No. 661038

1500X

Figure 48. Electron Fractograph of Material V Tested at 23°C with Bend Strengths of 50,500 psi. Billet V02A D0371.



Avco Plate No. 661041

Figure 49. Electron Fractograph of Material V Tested at 800°C with Bend Strength of 52,700 psi. Billet V02A D0371.



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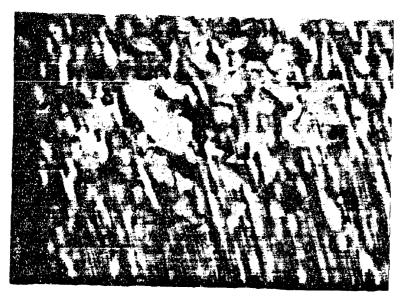
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Avco Plate No. 66 1044

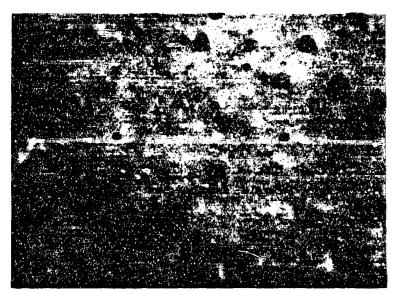
1500X

Figure 50. Electron Fractograph of Material V Tested at 1400°C with Bend Strength o. 43,000 psi. Billet V02A D0371.



Avco Plate No. 67235

Figure 51. Electron Fractograph of Material V Tested at 1800°C with Bene Strength of 44,900 psi. Billet VOZA D0371.



Avco Plate No. 4410A

Figure 52. Edge of Specimen 102A D0338 After Testing at 1800°C in Argon.

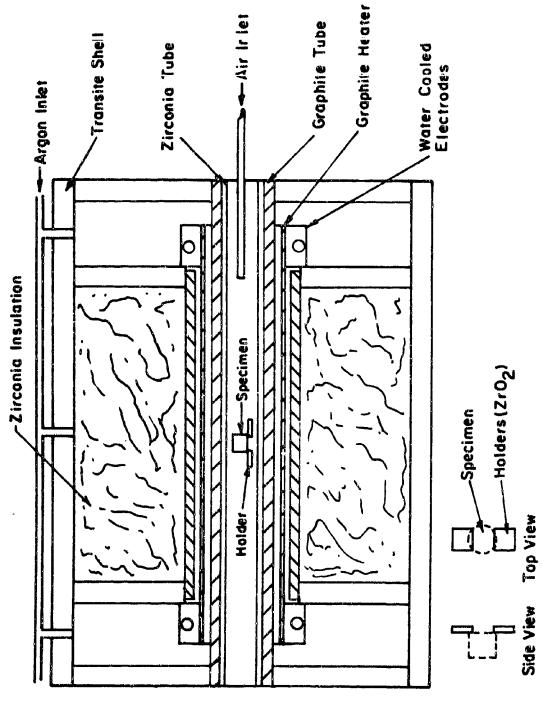
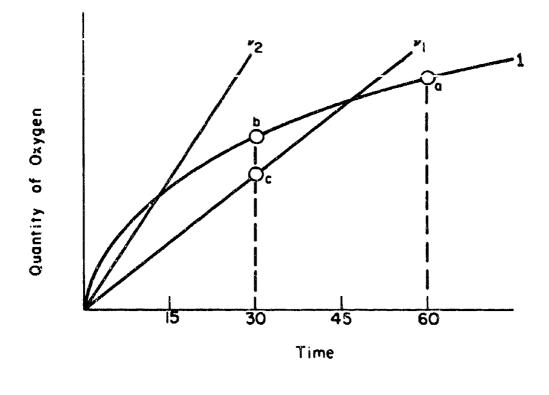


Figure 53. Schematic Diagram of Air Oxidation Furnace.



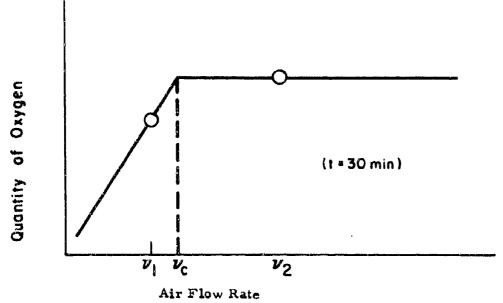


Figure 54. Dependency of Air Flow Rate for Hypothetical Oxidation Experiment at Constant Temperature.

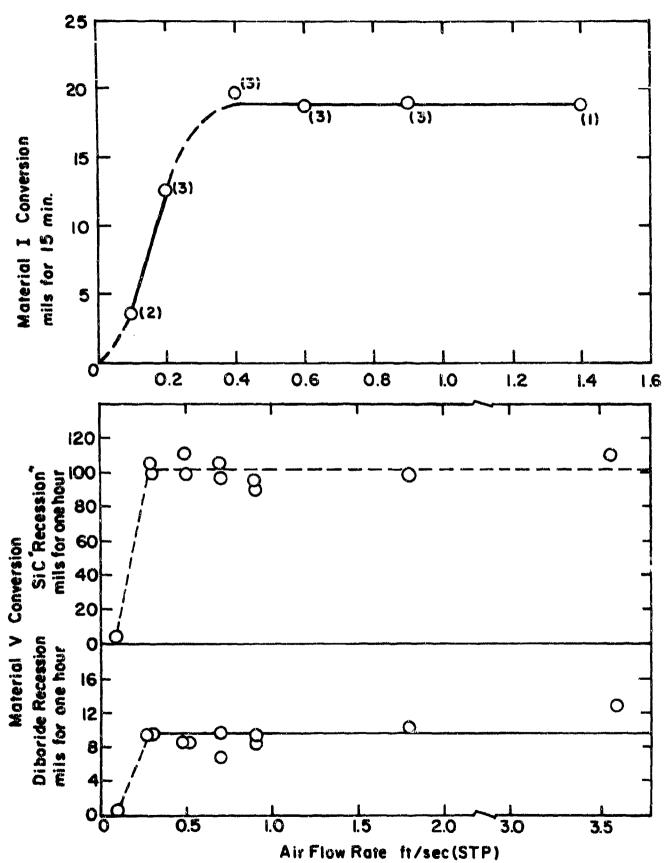


Figure 55. Air Flow Rate Dependence for Material I (1800°C, 15 Minutes and Material III (2120°C, 60 Minutes).

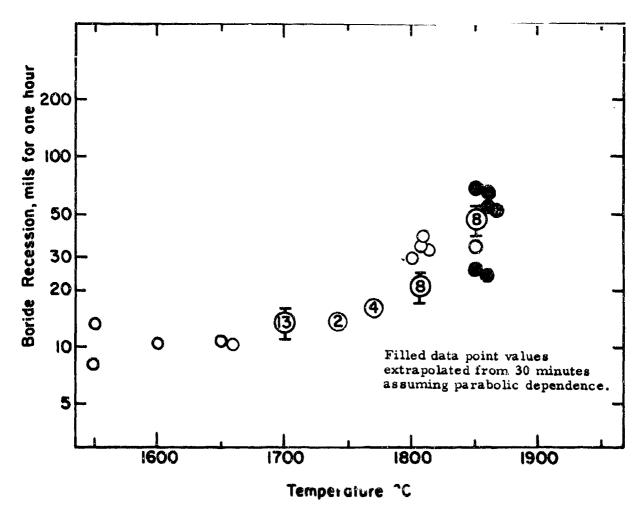


Figure 56. Oxidation Screening: Material I (ZrB2).

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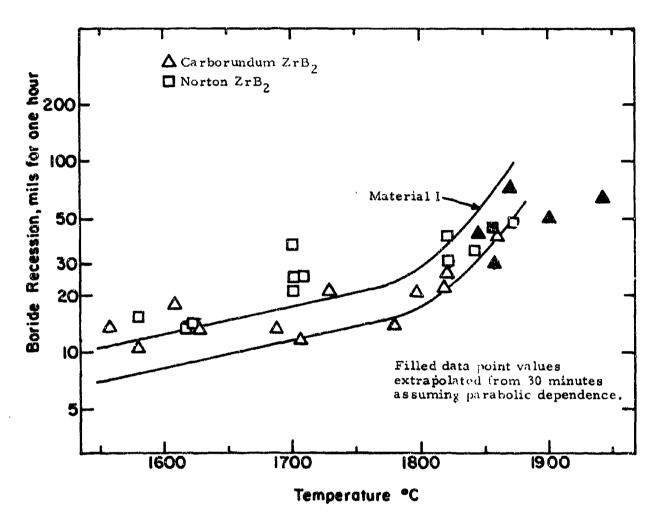


Figure 57. Oxidation Comparison: Commercially Hot Pressed ZrB₂ vs. Material I (ZrB₂).

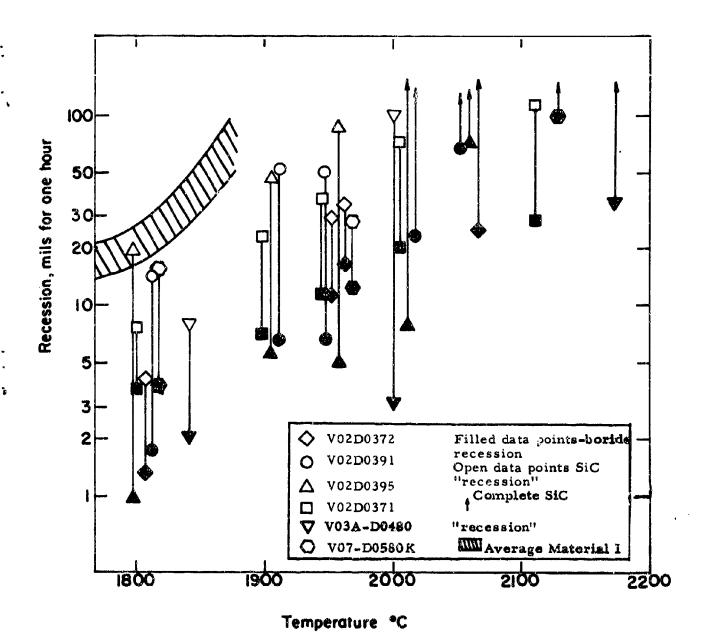


Figure 58. Oxidation Screening: Material V (ZrB2-20 v/o SiC)

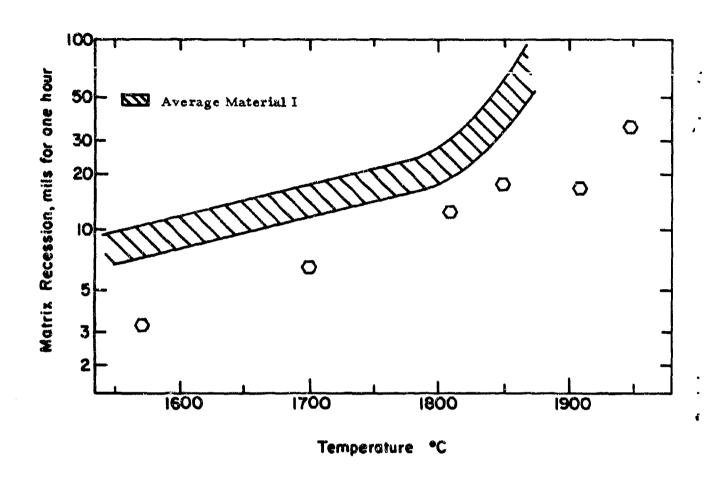


Figure 59. Oxidation Comparison: Boride Z vs. Material I (ZrB2).

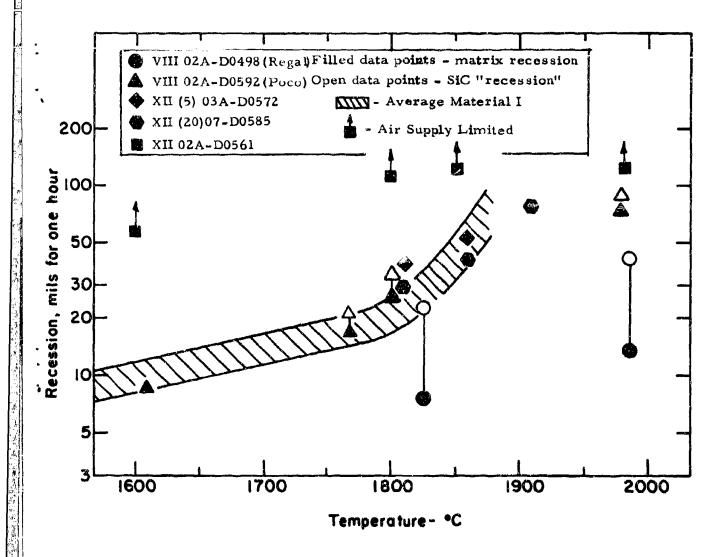


Figure 60. Oxidation Screening: Material VIII (ZrB₂ + 30 v/o Graphite + 14 v/o SiC), and Material XII (ZrB₂ + 50 v/o Graphite).

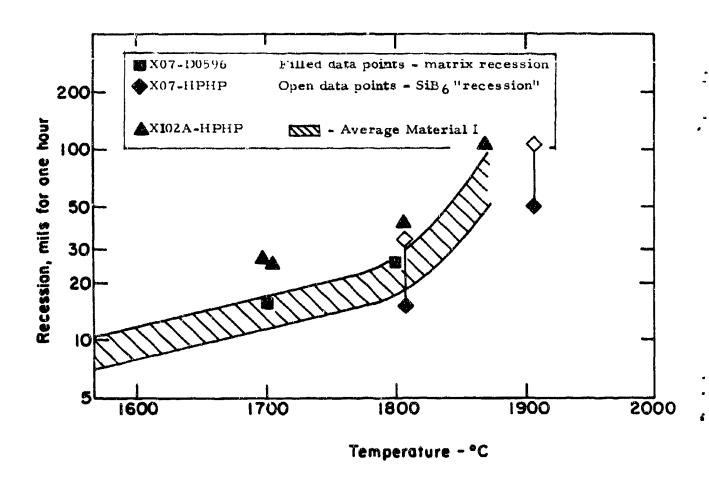


Figure 61. Oxidation Screening: Material X ($ZrB_2 + 20 \text{ v/o SiB}_6$) and Material XI ($ZrB_2 + 8 \text{ v/o Cr}$).

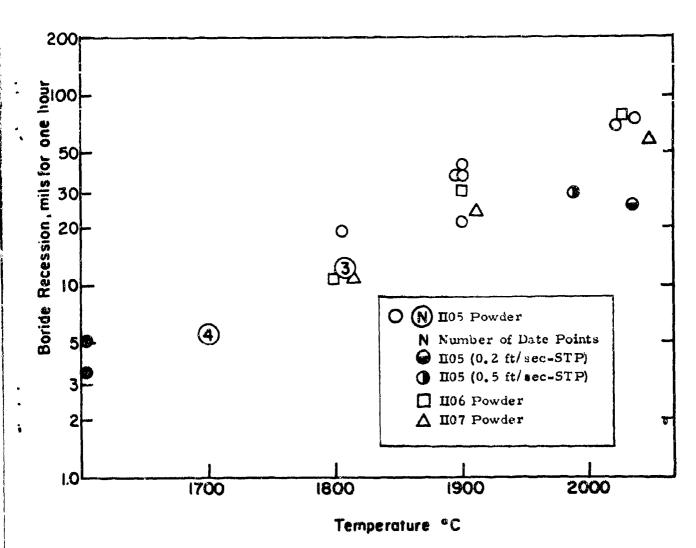


Figure 62. Oxidation Screening: Material II (HfB2).

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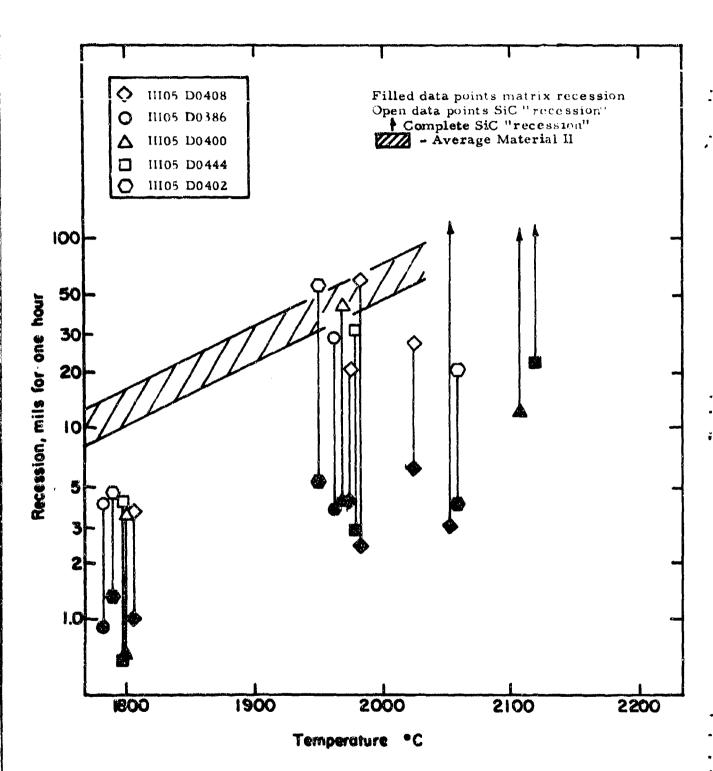


Figure 63. Oxidation Screening: Material III (HfB2 + 20 v/o SiC).

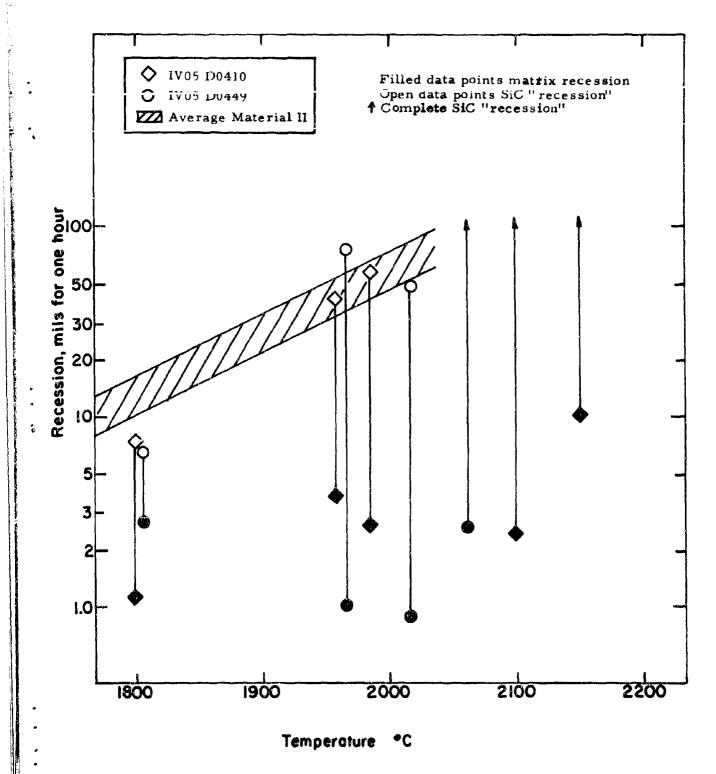
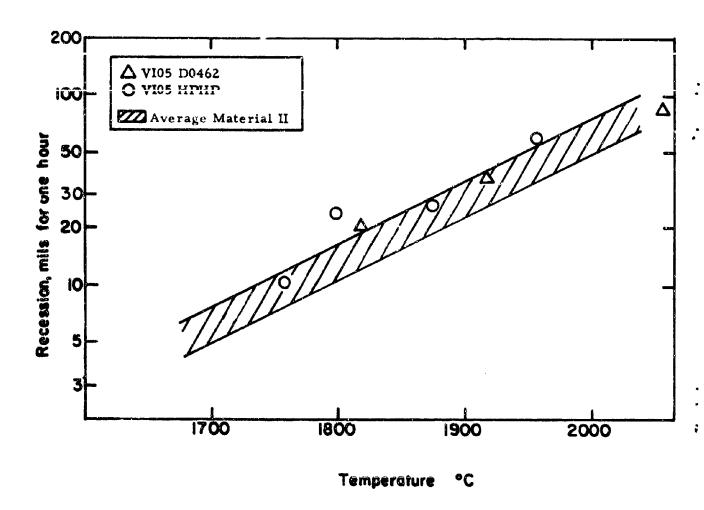


Figure 64. Oxidation Screening: Material IV (HfB2 + 30 v/o SiC).



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Figure 65. Oxidation Screening: Material VI (HfB2*4 v/o Hf-27 Ta).

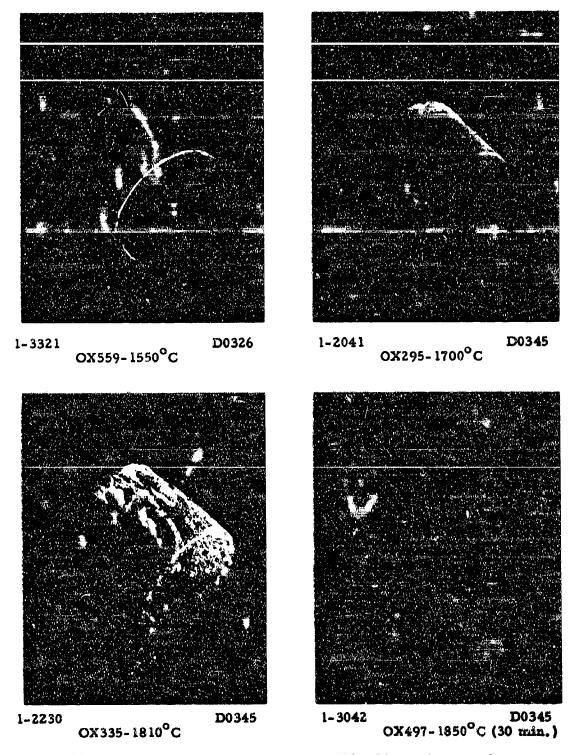


Figure 66. Oxidation Screening, Material 102A: Macrophotographs.

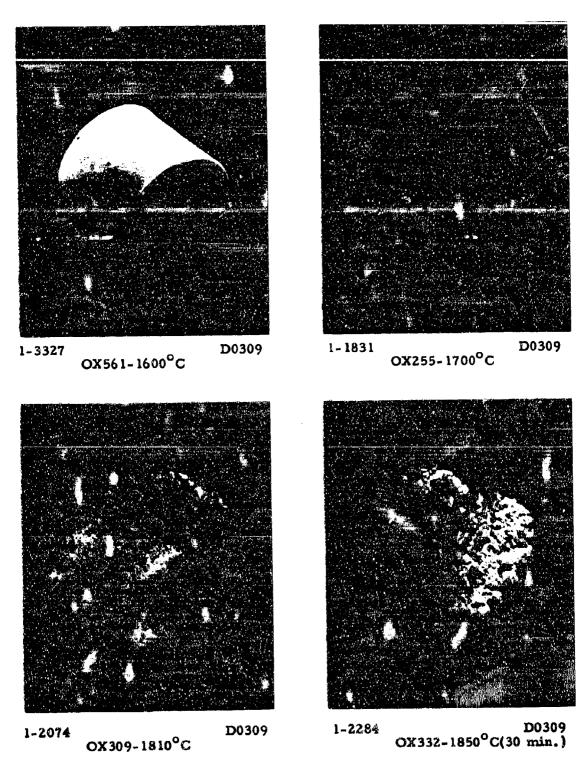


Figure 67. Oxidation Screening, Material 103A: Macrophotographs.

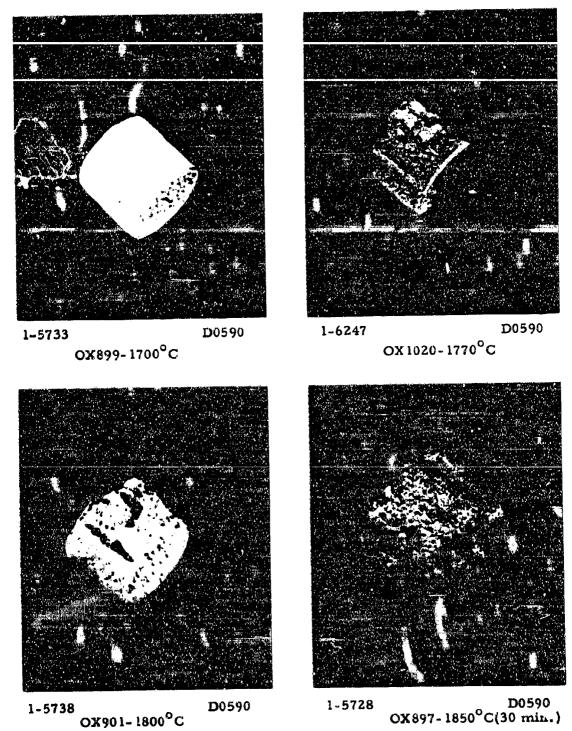


Figure 68. Oxidation Screening, Material 105A: Macrophotographs.

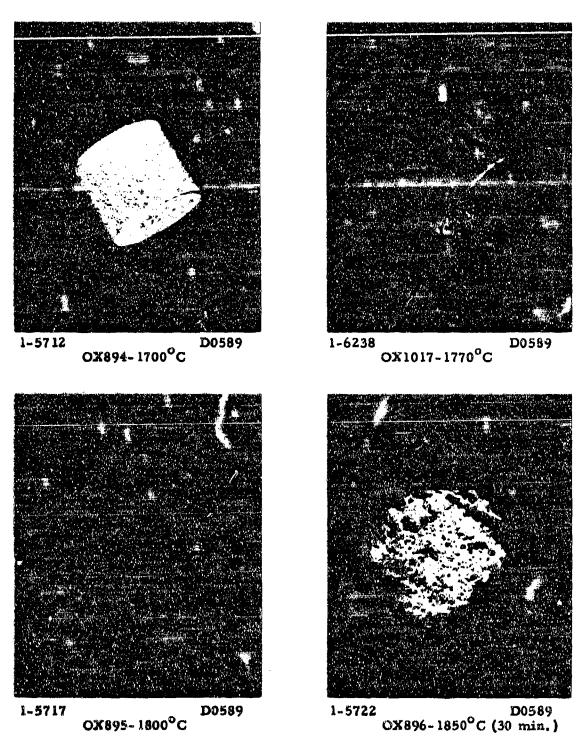


Figure 69. Oxidation Screening, Material 107: Macrophotographs.

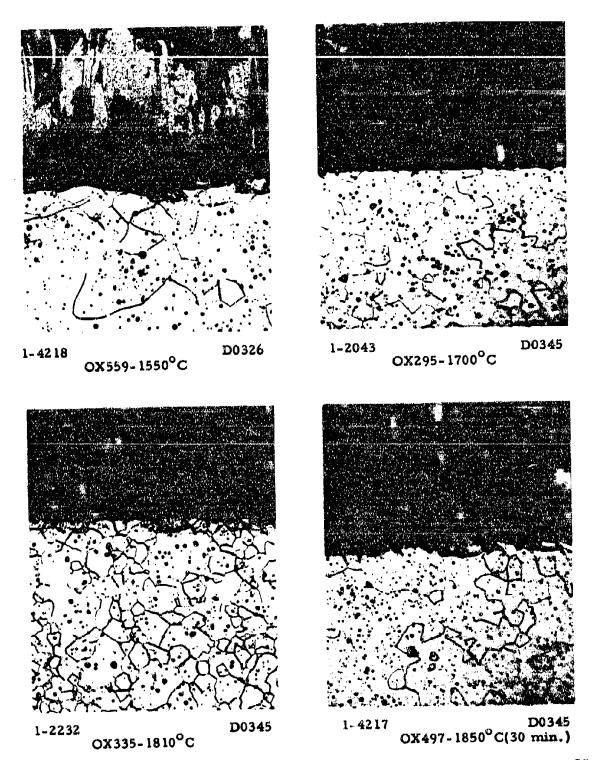


Figure 70. Oxidation Screening, Material 102A: Oxide-Matrix Interfaces, 250X.

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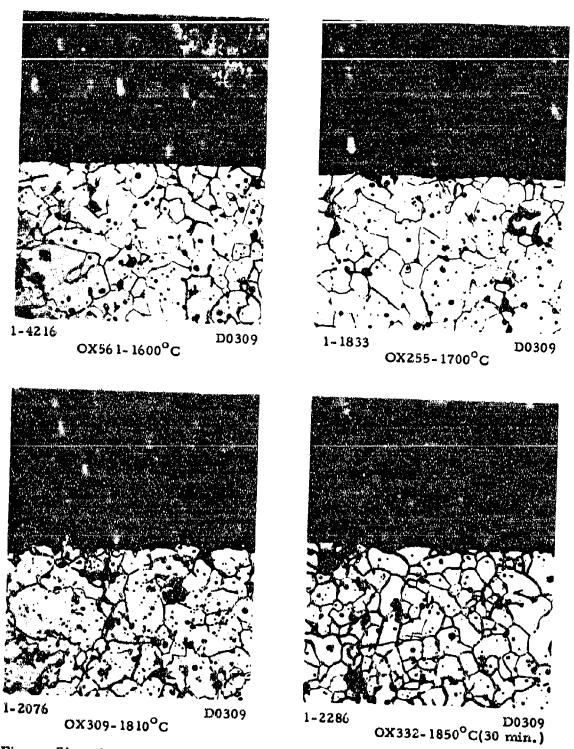


Figure 71. Oxidation Screening, Material 103A: Oxide-Matrix Interfaces, 250X.

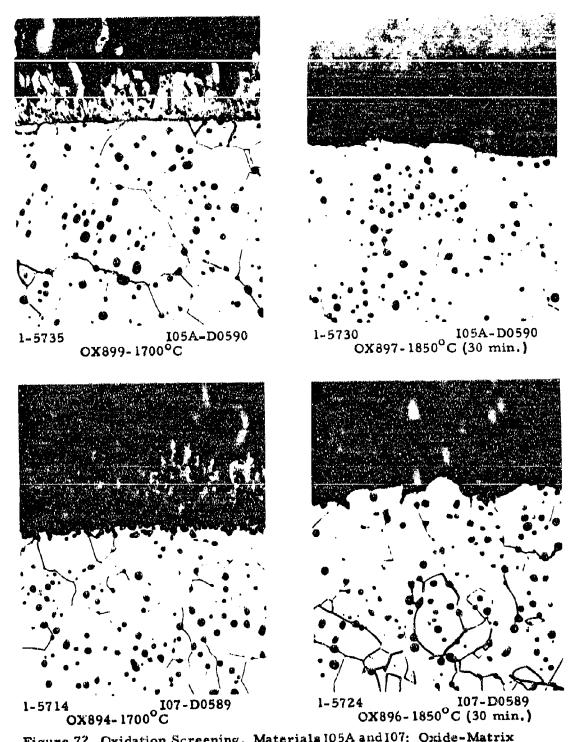
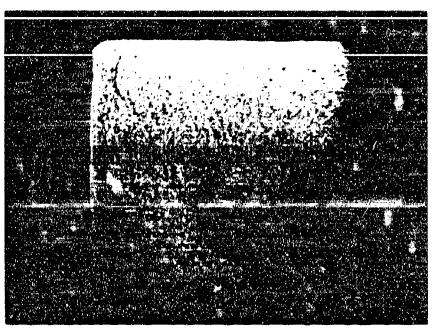


Figure 72. Oxidation Screening, Materials 105A and 107: Oxide-Matrix Interfaces, 250X.



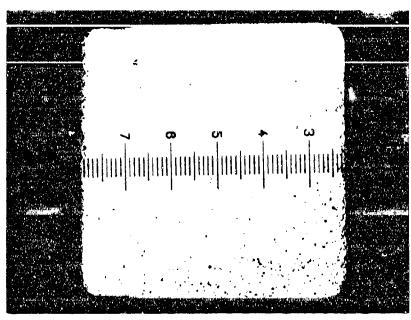
1-2042
Longitudinal
OX295

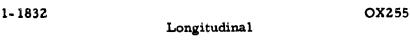
Figure 73. Oxidation Screening, Material 102A: Reticule Photographs (1 div. = 4.86 mils), D0345, 1700°C.

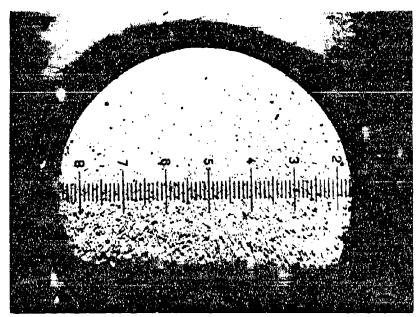
Transverse

1-2045

OX295







1-1835 OX255

Figure 74. Oxidation Screening, Material IO3A: Reticule Photographs (1 div. = 4.86 mils), DO309, 1700°C.

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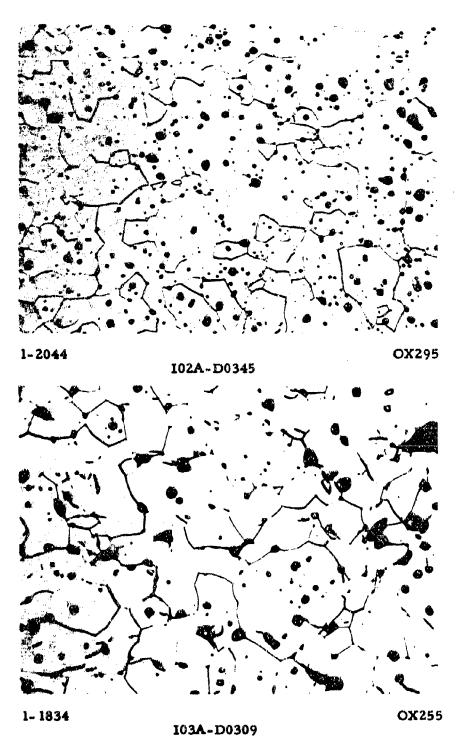


Figure 75 · Oxidation Screening, Material I: Representative Matrix Photographs, 1700°C, 500X.

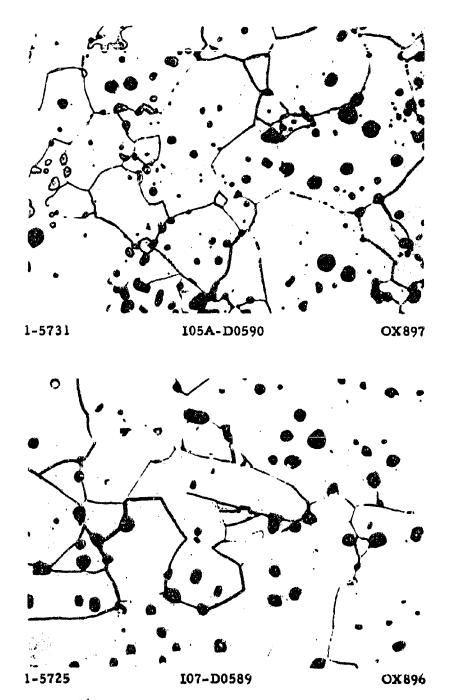
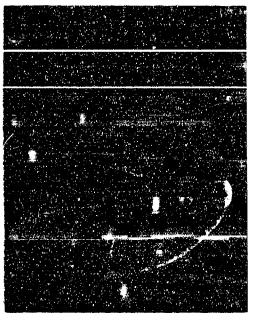
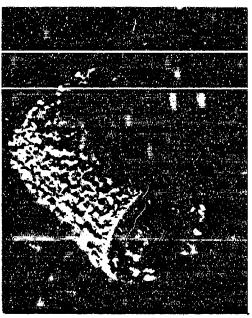


Figure 76. Oxidation Screening; Material I: Representative Matrix Photographs, 1850°C (30 min.), 500X.

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1-1350 OX155 -1550°C



1-1357 OX156-1730°C

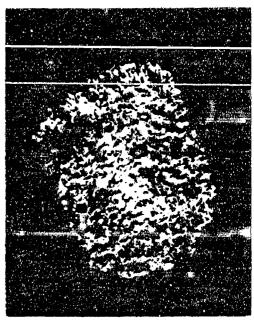


1-1364 OX157-1820°C(30 min.)

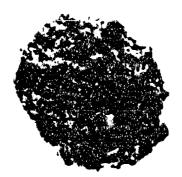
Figure 77. Oxidation Comparison, Carborundum ZrB2: Macrophotographs.



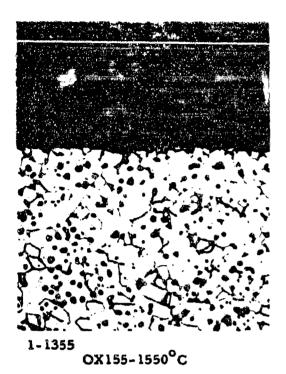
1-1111 OX113-1540°C

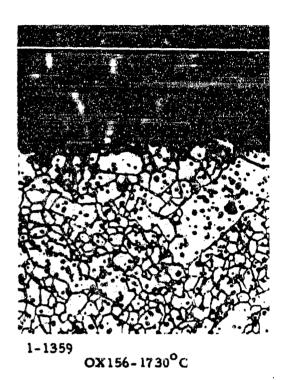


1-1233 OX132-1740°C



1-1125 OX115-1880°C(30 min.)
Figure 78. Oxidation Comparison, Norton ZrB₂: Macrophotographs.





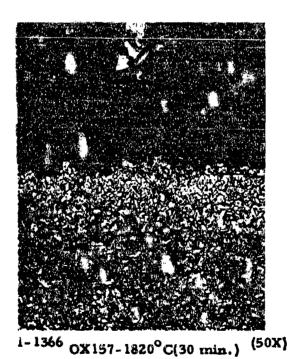
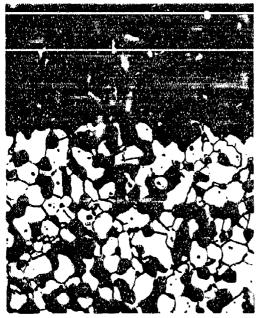


Figure 79. Oxidation Comparison, Carborundum ZrB₂: Oxide-Matrix Interfaces, 250X.



1-113 OX113-1540°C



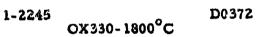
1-1235 OX132-1740°C



1-1127 OX115-1880°C(30 min.)

Figure 80. Oxidation Comparison, Norton ZrB₂: Oxide-Matrix Interfaces, 250X.







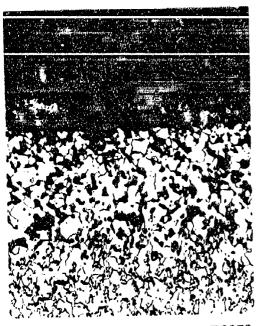
1-2273 D0372 OX343-1960°C



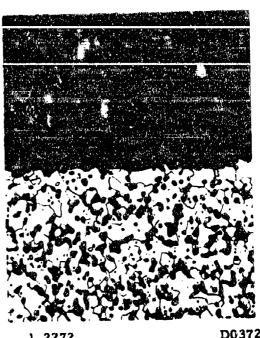
1-2399 OX352-2060°C

Figure 81. Oxidation Screening, Material VO2A: Macrophotographs.

D0372



1-2246 D0372 OX330-1800°C



1-2272 D0372 OX343-1960°C

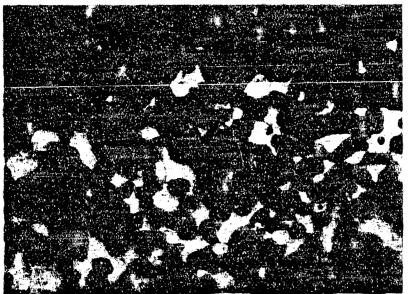


1-2401 D0372 OX352-2060°C

Figure 82. Oxidation Screening, Material VOZA: Oxide-Matri-Interface, 250X.

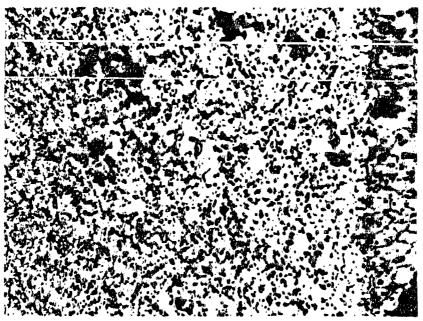


1-3871 250X Interface

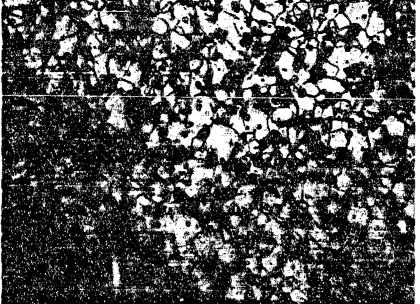


1-3872 500X Interface

Figure 83. Oxidation Screening, Material V07: D0580K, OX635-2100°C.

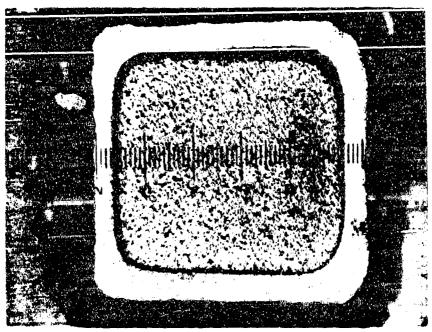


1-2276 160X Interface

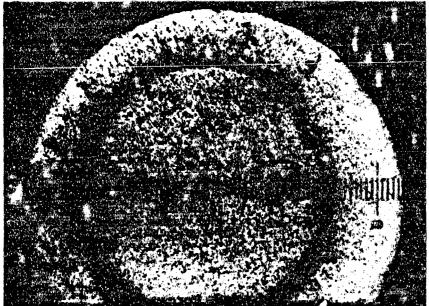


1-2275 500X Matrix

Figure 84. Oxidation Screening, Material V02A: D0372, OX343, 1960°C.



1-2274 OX343 Longitudinal



1-2277 OX343 Transverse

Figure 85. Oxidation Screening, Material VO2A: Reticule Photographs (1 div. = 4.86 mils), D0372, 1960°C.

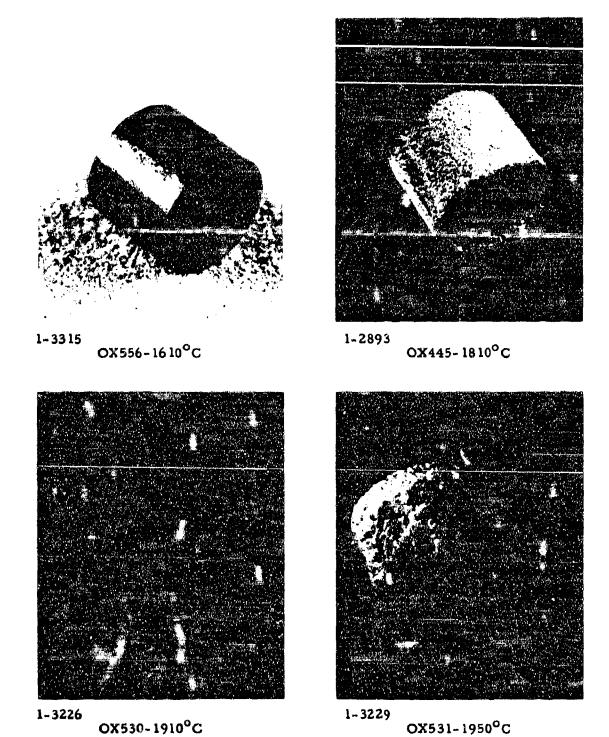


Figure 86. Oxidation Screening, Boride Z: Macrophotographs.

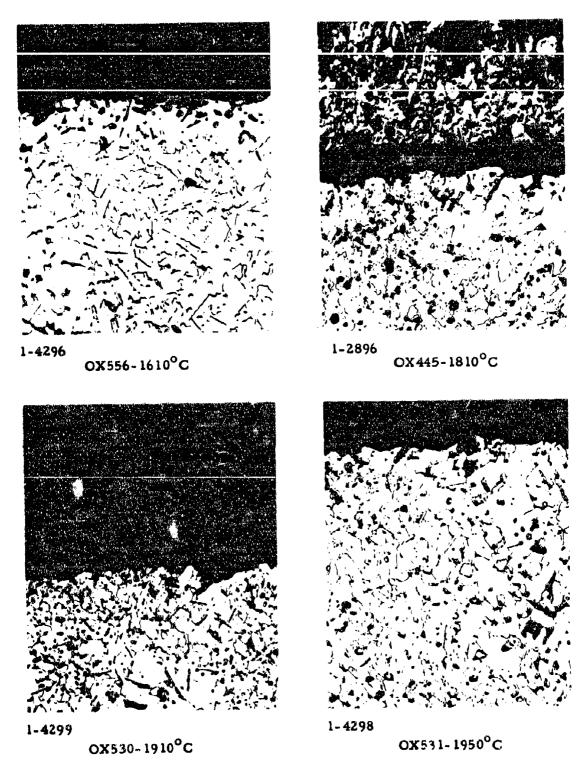
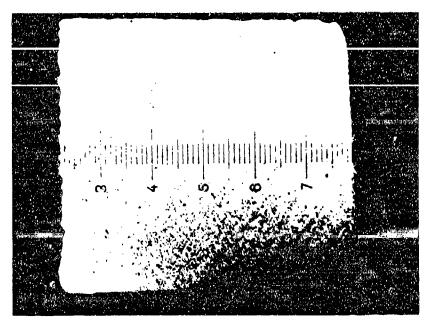
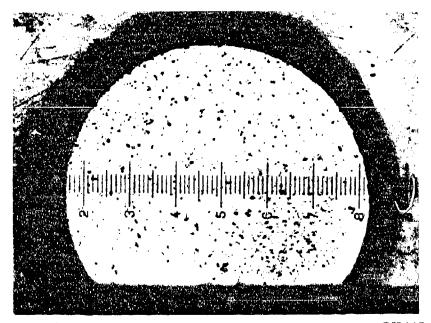


Figure 87. Oxidation Screening, Boride Z: Oxide-Matrix Interfaces, 250X.

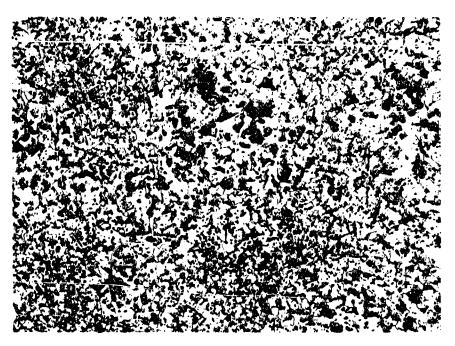


1-2894 OX445 Longitudinal



1-2898 OX445
Transverse

Figure 88. Oxidation Screening, Boride Z: Reticule Photographs (1 div. = 4.86 mils), 1810°C.



1-2895 150X

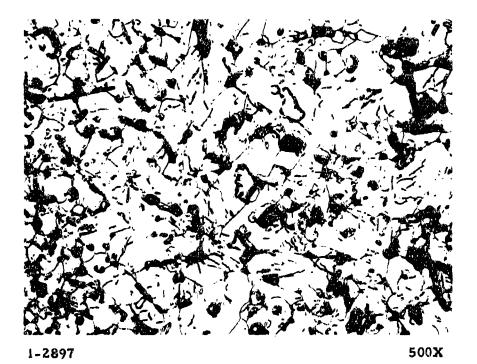


Figure 89. Oxidation Screening, Boride Z: Representative Matrix Photographs, 1810°C.

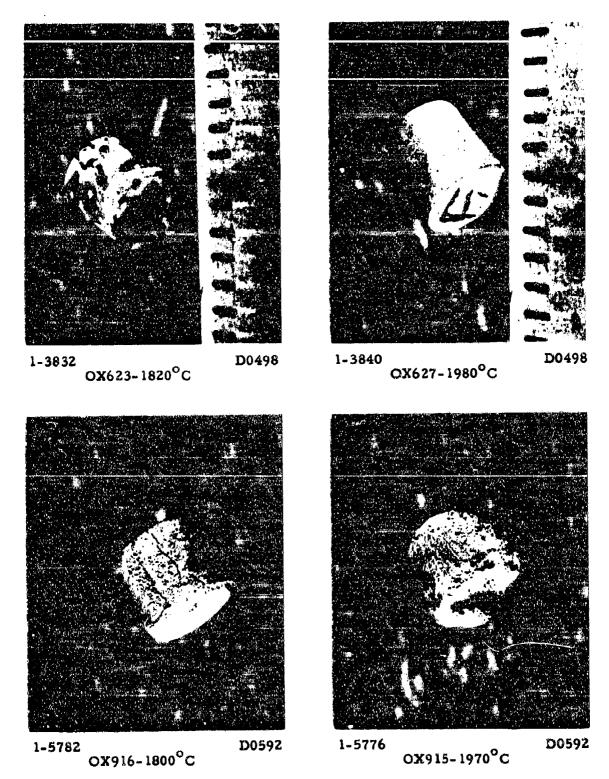


Figure 90. Oxidation Screening, Material VIII: Macrophotographs.

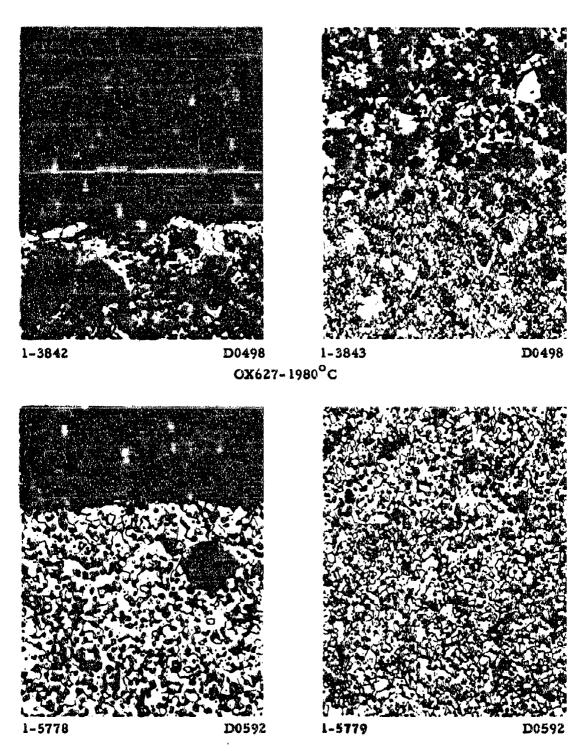


Figure 91. Oxidation Screening, Material VIII: Depleted Matrix-Oxide Interfaces (Left) and Matrix-Depleted Matrix Interfaces (Right), 250X.

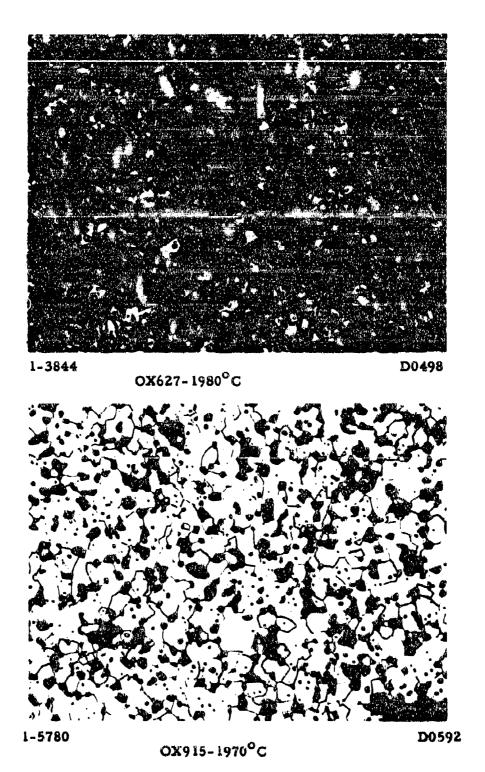


Figure 92. Oxidation Screening, Material VIII: Representative Matrix Photographs, 500X.

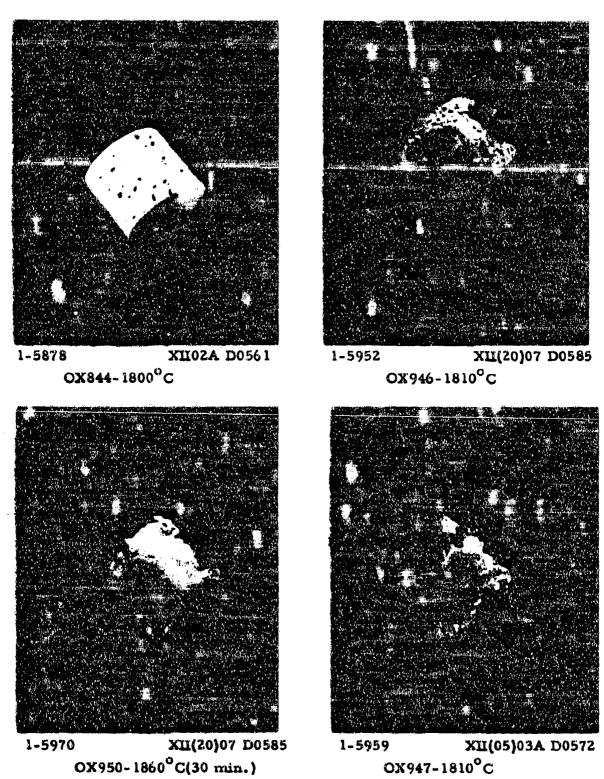


Figure 93. Oxidation Screening, Material XII: Macrophotographs.

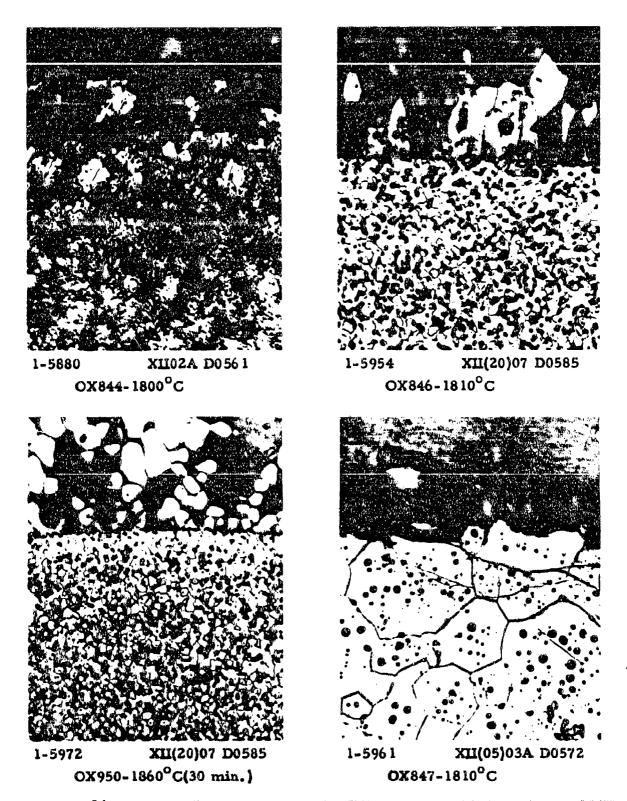
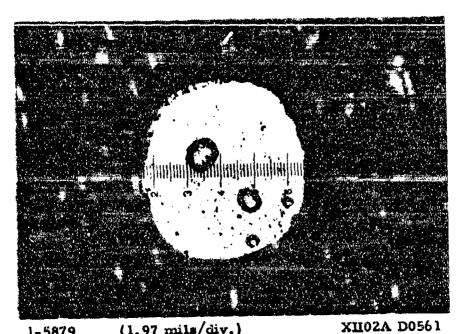
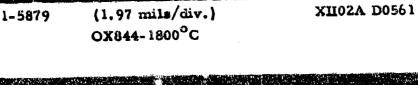
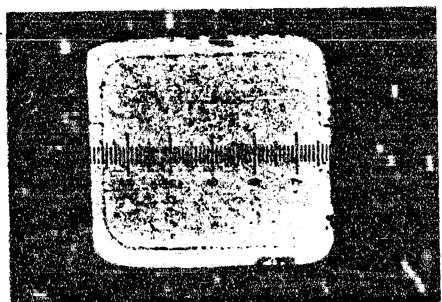


Figure 94. Oxidation Screening, Material XII: Matrix-Oxide Interfaces, 250X.







f-5953 (4.86 mils/div.) XII(20)07 D0585 OX946-1810°C

Figure 95. Oxidation Screening, Material XII: Reticule Photographs.

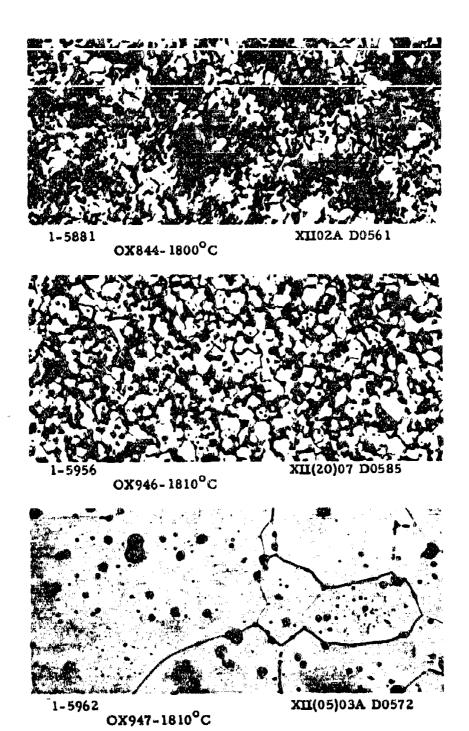


Figure 96. Oxidation Screening, Material XII: Representative Matrix Photographs, 500X.

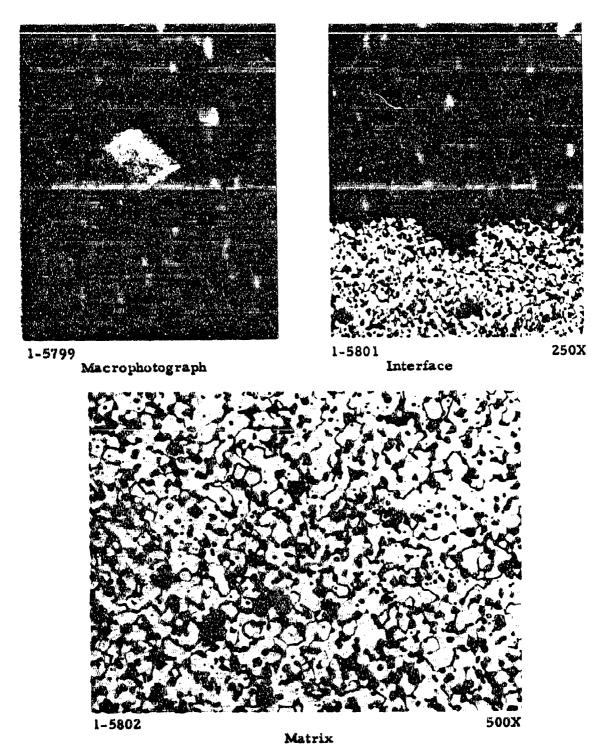


Figure 97. Oxidation Screening, Material K: Typical Microstructures, Pressing D0596, OX925-1700°C.

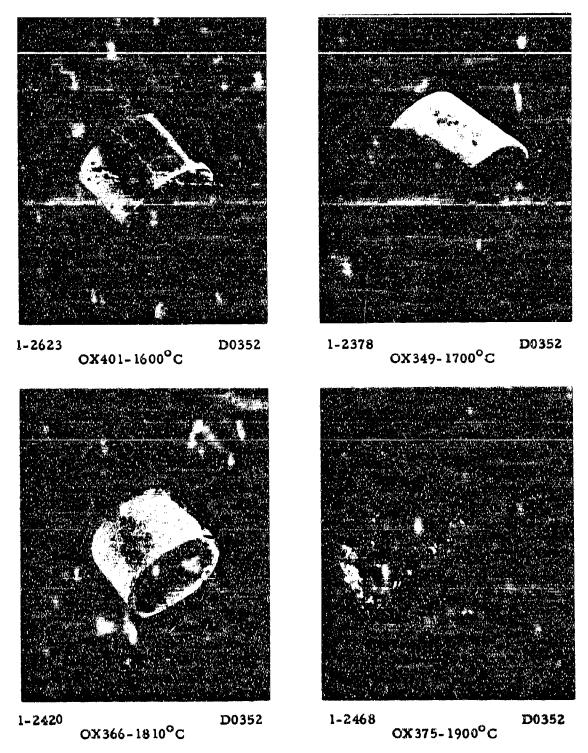


Figure 98. Oxidation Screening, Material II05: Macrophotographs.

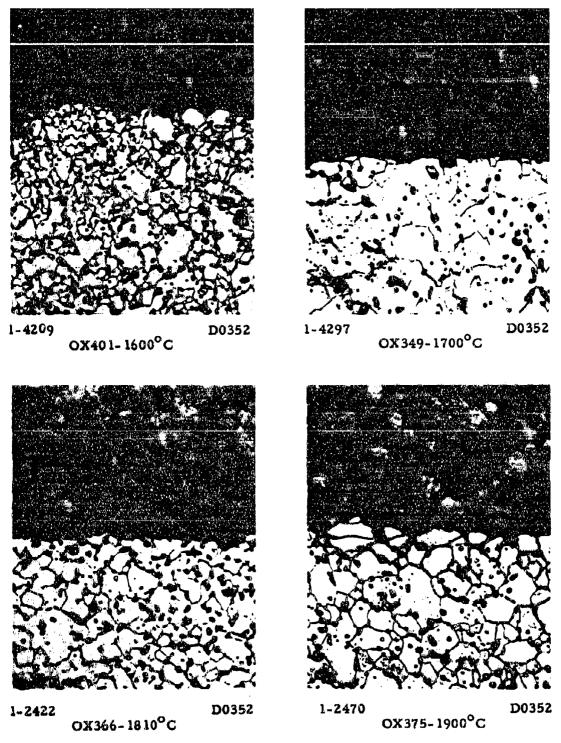
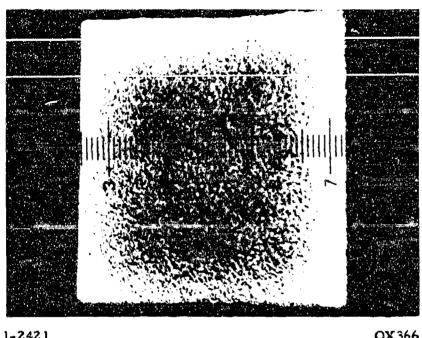
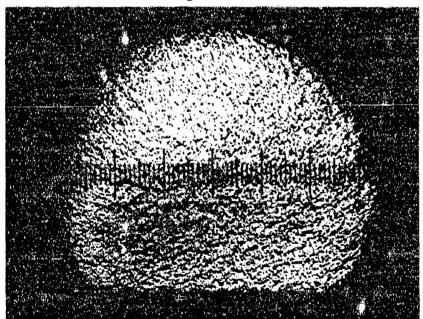


Figure 99. Oxidation Screening, Material II05: Oxide-Matrix Interfaces, 250%.



1-2421 OX366 Longitudinal



1-2424 OX366 Transverse

Figure 100. Oxidation Screening, Material II05: Reticule Photographs (1 div. = 4.86 mils), D0352, 1810°C.

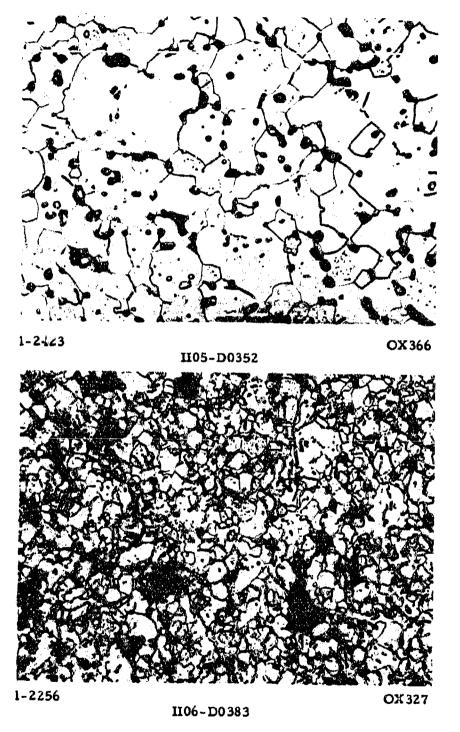
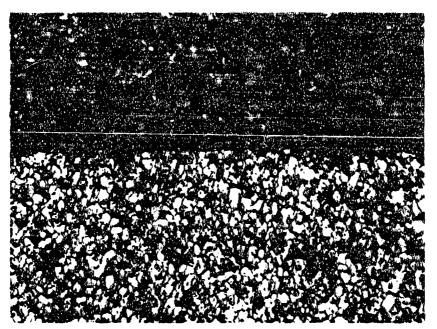


Figure 101. Oxidation Screening, Material II: Representative Matrix Photographs, 1800°C, 500X.

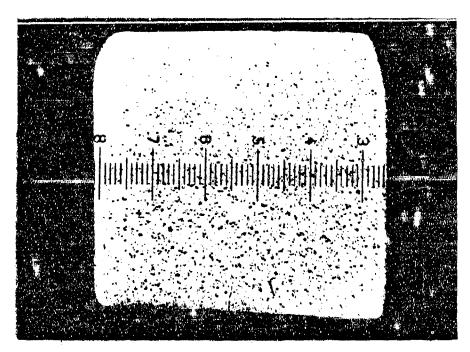


1-2254 Macrophotograph

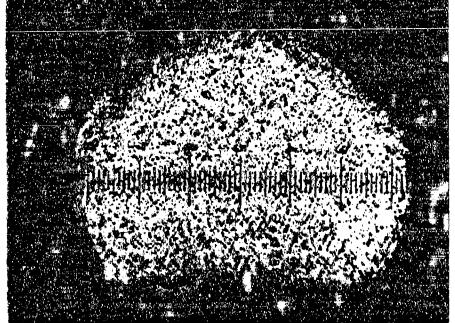


1-2257 250X Oxide-Matrix Interface

Figure 102. Oxidation Screening, Material II06: OX327, D0383, 1800°C.



1-2255 OX 327 Longitudinal



1-2258 OX 327

Figure 103. Oxidation Screening, Material H06: Reticule Photographs (1 div. = 4.86 mils), D0383, 1800°C.



1-2267 D0408 OX340-1800°C



1-2278 D0408 OX345-1980°C



1-2511 D0408 OX384-2050°C

Figure 104. Oxidation Screening, Material III: Macrophotographs.

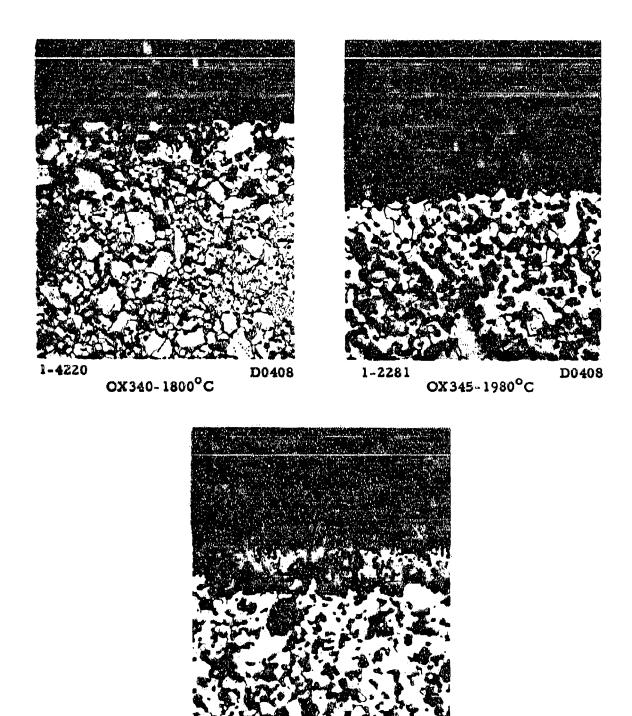
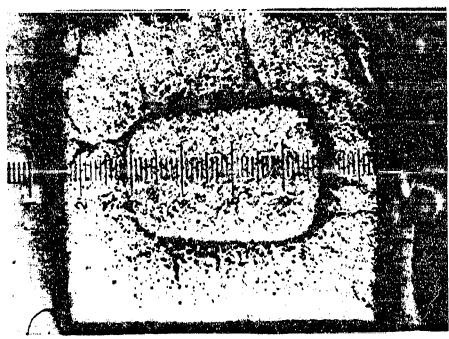


Figure 105. Oxidation Screening, Material III: Oxide-Matrix Interfaces, 250X.

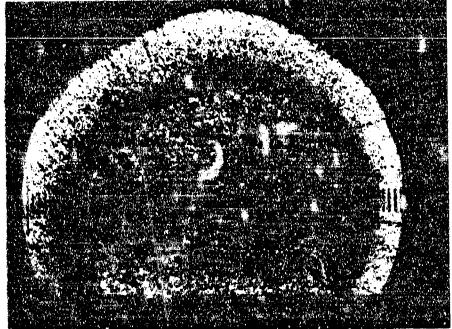
OX384-2050°C

D0408

1-2514

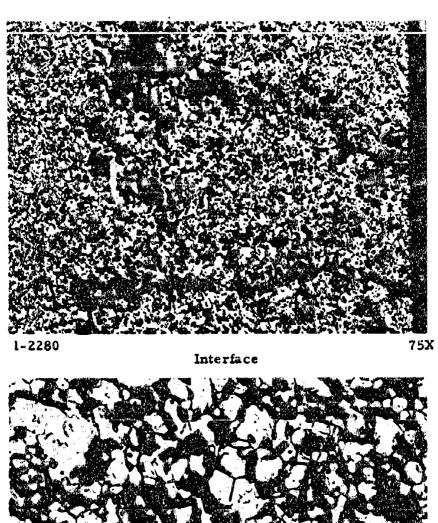


1-2279 OX345 Longitudinal



1-2283 OX345

Figure 106. Oxidation Screening, Material III: Reticule Photographs (1 div. = 4.86 mils), D0408, 1980°C.



1-2282 500X

Matrix

Figure 107. Oxidation Screening, Material III: D0408, OX345, 1980°C.



1-2430 D0410 OX368-1800°C

THE REAL PROPERTY.

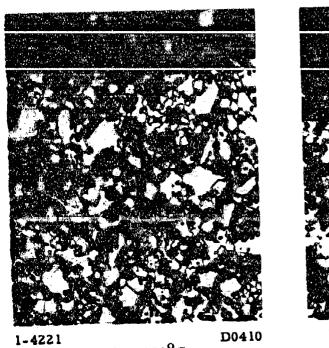


1-2504 D0410 OX383-1960°C



1-2518 D0410 OX385-2100°C

Figure 108. Oxidation Screening, Material IV: Macrophotographs.





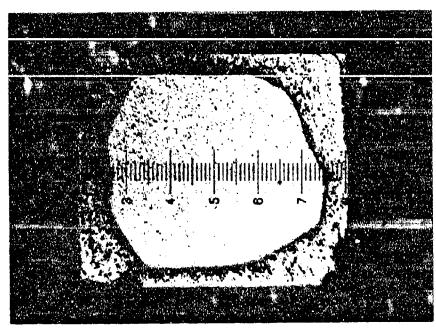
OX368-1800°C

1-2507 D0410 OX383-1960^OC

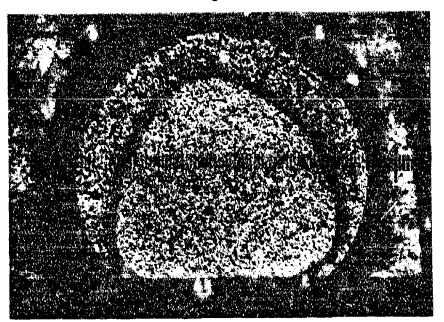


OX385-2100°C

Figure 109. Oxidation Screening, Material IV: Oxide-Matrix Interfaces, 250X.

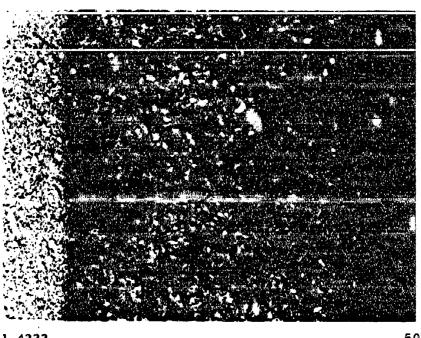


1-2505 OX383 Longitudinal



1-2510 OX383

Figure 110. Oxidation Screening, Material IV: Reticule Photographs (1 div. = 4.86 mils), D0410, 1960°C.



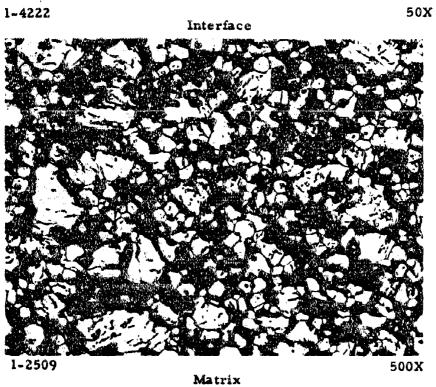


Figure 111. Oxidation Screening, Material IV: D0410, OX383, 1960°C.

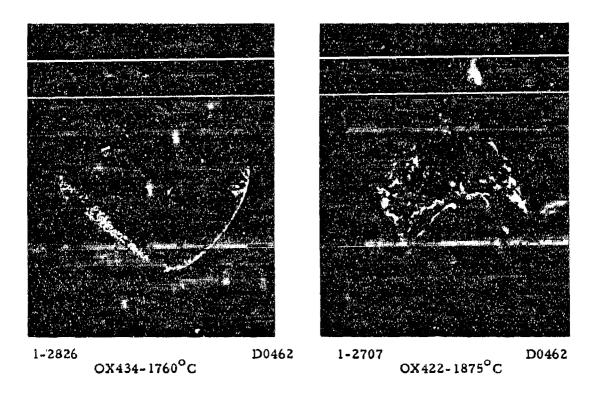
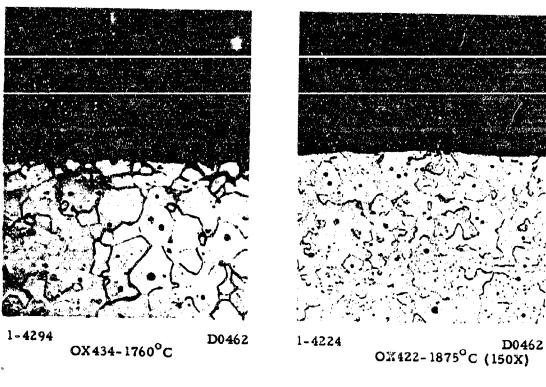




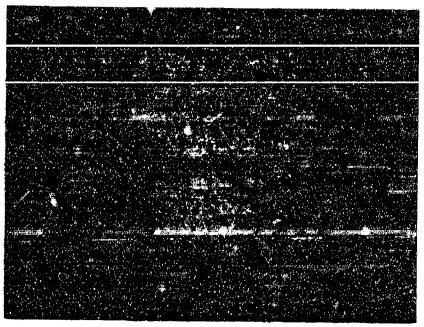
Figure 112. Oxidation Screening, Material VI: Macrophotographs.





1-2496 OX376-1960°C

Figure 113. Oxidation Screening, Material VI: Oxide-Matrix Interfaces, 250X.



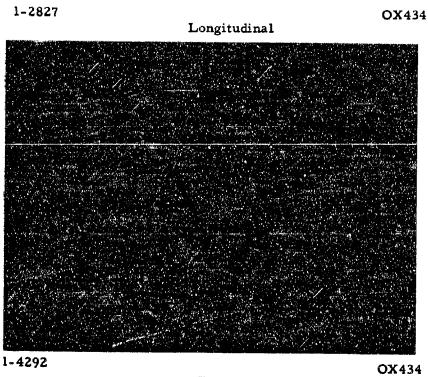


Figure 114. Oxidation Screening, Material VI: Reticule Photographs (1 div. = 4.86 mils), D0462, 1760°C.

Transverse

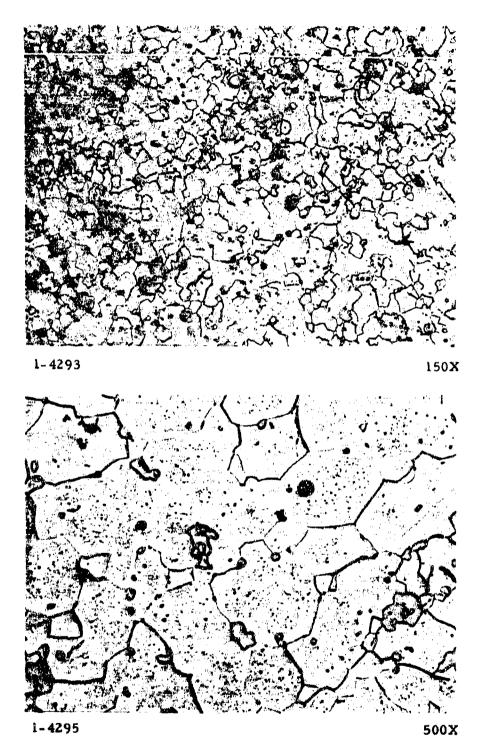


Figure 115. Oxidation Screening, Material VI: Representative Matrix Photographs, D0462, OX434, 1760°C.

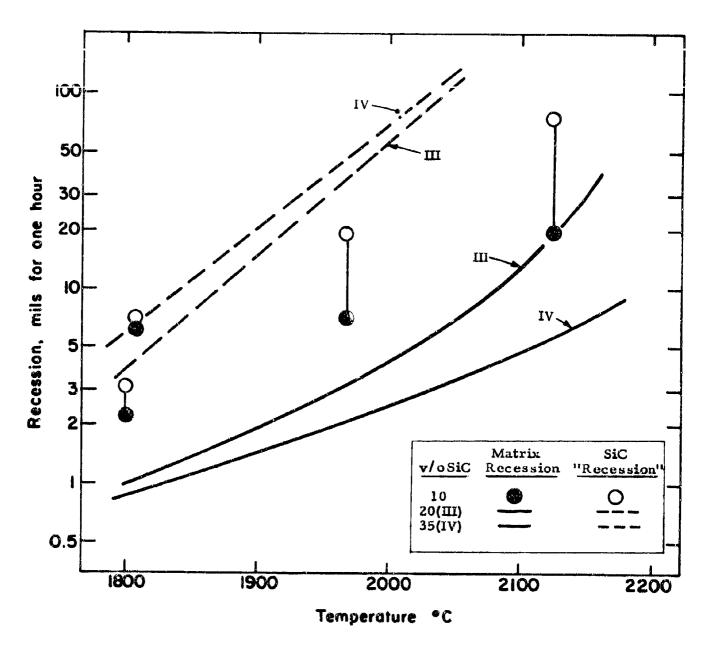
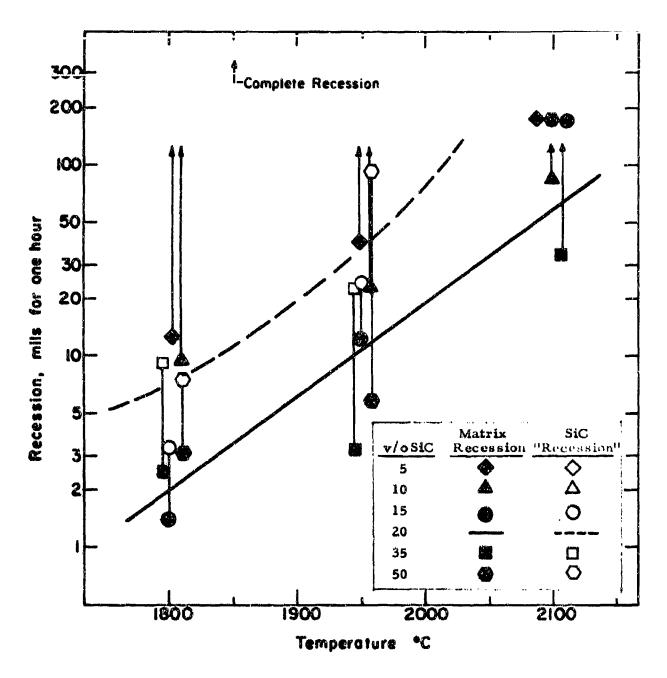
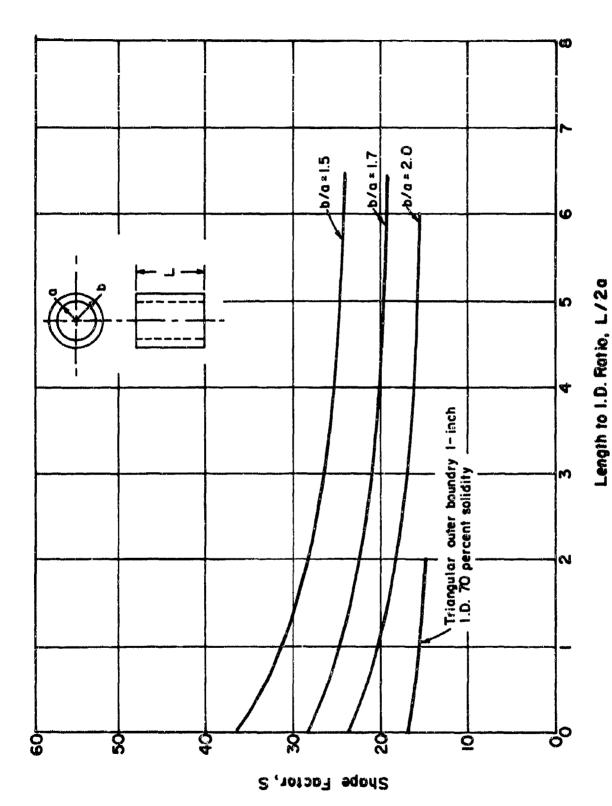


Figure 116. Oxidation Screening: Material III (IIfB₂ + SiC) - Effect of SiC Content.



金属

Figure 117. Oxidation Screening: Material V (ZrB₂ + SiC) - Effect of SiC Content.



Shape Factors of Circular Cylindrical Thermal Stress Specimens. Figure 118.



Figure 119. Thermal Stress Apparatus.

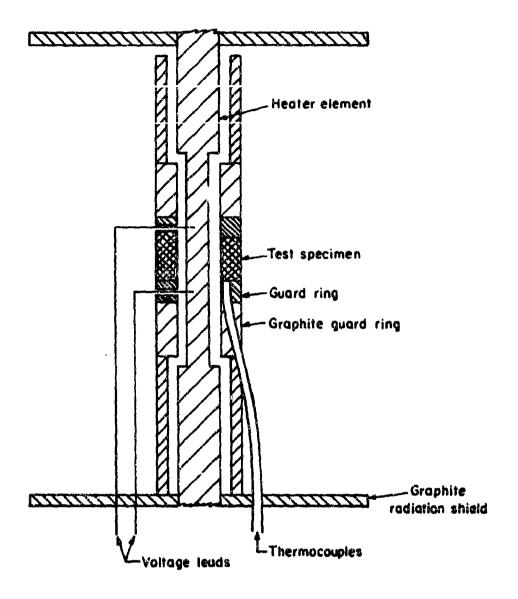


Figure 120. Cross Sectional Schematic of Sample Placement in Thermal Stress Testing Apparatus.



Figure 121. KT SiC Sample Thermal Stre & Specimen after Failure.

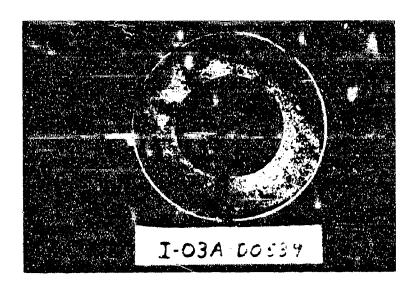


Figure 122. Material I (103A D0539) Thermal Stress Specimen Failed in Cooling after Test.

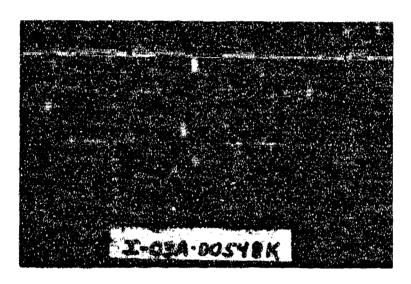


Figure 123. Material I (103A D0548K) Thermal Stress Specimen Failed Under Transient Heating Conditions.

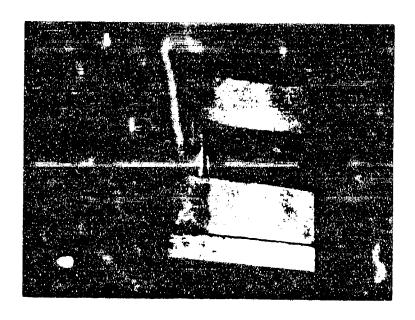


Figure 124. Material II (II05 D0595K) Failed Thermal Stress Specimen Before Removal from Test Apparatus.

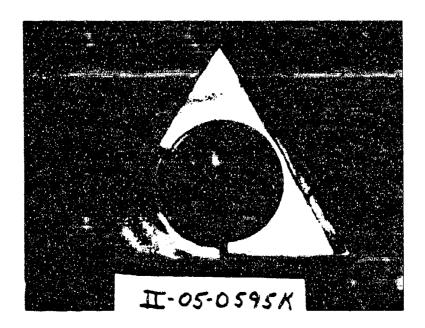


Figure 125. Material II (II05 D0595K) Thermal Stress Specimen after Failure.

ORGANIZATIONAL PESPONSIBILITIES BREAKDOWN

Technical Management	ManLabs
Materials Procurement	ManLabs
Materials Characterization	ManLabs
Fabrication:	
Hot Pressing	Avco/SSD
Characterization	Avco/SSD
Exploratory	Avco/SSD
Characterization	Avco/SSD_
Pyrolytic Depositions	Raytheon Research Division
Characterization	ManLabs
Thermal and Oxidation Evaluations	ManLabs
Mechanical Properties	Avco/SSD
Thermal Expansion	ManLabs
Thermal Diffusivity	North American/Atomics International
Emittance	Avco/SSD
Steady State Thermal Stress Resistance	Battelle Memorial Institute
Simulated Leading Edge Evaluation	Bell Aerosystems

ManLabs - AF33(615)-3859

Avco/SSD - AF33(615)+3942

Arc Plasma Evaluations

Nondestructive Testing

TABLE 2

DIBORIDE MATERIAL IDENTIFICATION: PHASE CONSTITUTION

AND BASE COMPOSITION

Material Diboride	Designation	Remarks and Rationale for Specific Additives
1	ZrB ₂	Zirconium diboride, no additive.
п	HfB ₂	Hafnium diboride, no additive.
ш	HfB ₂ + SiC	Hafnium diboride with twenty volume per cent silicon carbide to enhance oxidation resistance.
IV	HfB ₂ + SiC	Hafnium diboride with thirty volume per cent silicon carbide to enhance oxidation resistance.
v	ZrB ₂ + SiC	Zirconium diboride with twenty volume per cent silicon carbide to enhance oxidation resistance.
VI	HfB ₂ + Hf-Ta	Hafnium diboride with four volume per cent hafnium tantalum alloy to provide an oxidation resistant metallic binder phase and enhance strength properties.
VII	HfB ₂ + SiC	Boron rich hafnium diboride with silicon carbide additive to enhance oxidation resistance.
VIII	ZrB ₂ +SiC+C	Zirconium diboride with fourteen volume per cent silicon carbide, thirty volume per cent carbon to enhance thermal stress resistance and maintain improved oxidation resistance relative to ZrB ₂ .
ıx	HfB ₂ + HfSi	Hafnium diboride with twenty volume per cent hafnium silicide to enhance oxidation resistance.
x	ZrB ₂ + SiB ₆	Zirconium diboride with twenty volume per cent silicon hexaboride to enhance exidation resistance.
жī	ZrB ₂ + Cr	Zirconium diboride with eight volume per cent chromium to enhance mechanical strength properties.
жn	ZrB ₂ + C	Zirconium diboride with fifty volume per cent carbon to enhance thermal stress resistance.
жш	$ZrB_2 + W$	Zirconium diboride with tungsten to enhance mechanical properties.

TENTATIVE POWDER SPECIFICATION FOR HOT PRESSING GRADES OF ZrB, AND HtB,

Limitations of present powder production technology for ZrB₂ and HfB₂ and cost considerations in quantities of the order of 100 pounds for hot pressing purposes will of necessity contain oxygen and carbon impurities. Materials found most suitable for hot pressing without additives or with carbon or SiC additive are characterized by over-all composition such that oxygen and carbon impurities are present as metal oxide, metal carbide or a mixed metal oxycarbide.

Limitations imposed by present powder production technology of ZrB, and HfB, for hot pressing purposes in quantities of the order of 100 pounds lead to the presence of 0.5 to 1.5 per cent nonmetallic impurities principally oxygen and carbon. The over-all chemical composition has to be specified to insure that these impurities are present as metal oxide, metal carbide or as metal oxycarbide. The thermodynamic stability of zirconium and hafnium oxides overrides compositional effects, but over-all metal rich compositions have to be specified to avoid the stabilization of carbon as B_4C . The presence of the latter lowers the temperature required for liquid phase formation relative to that observed for the oxide impurity phases. All metallic impurities have to be kept below 0.1 per cent to maintain basic properties of ZrB2 and HfB2. Of the metallic impurities, iron and titanium are more commonly encountered and both should be kept below the 0.1 per cent level. Powder particle size should be specified as -325 mesh or finer; fluid energy milling can be further specified or performed after delivery of powder to break up particulate aggregates. Chemistry specification are as follows:

	ZrB ₂	HfB ₂	
	Weight Per Cent	Weight Per	Cent
Hf	1.0 - 3.0	88.0 - 89.5	(Hf+Zr)
Zr	79.5 - 80.5 (Hf+Zr)	1.0 - 3.0	
В	18.0 - 19.0	10.0 - 10.5	
С	< 0.50	< 0.50	
0	< 0.50	< 0.50	
Ti	< 0.10	< 0.10	
Fe	< 0.05	< 0.05	
Other Metals	< 0.10	< 0.10	
N	< 0.05	< 0.05	
н	< 0.05	< 0.05	
Atomic Ratio: B/Hf+Zr	< 2.0	< 2.0	

TABLE 1
DIBORIDE POWDER PROCUREMENT SCHEDULE

			Purchase Schedule		
Material*	Supplier	Ouantity pounds	Ordered	Received	
102	U. S. Borax	ı	3/16/66	3/28/66	
102A	U. S. Borax	93	4/11/66	4/14/66	
103	U. S. Borax	1	4/11/66	4/13/66	
I03A	U. S. Borax	100	6/24/66	7/14/66	
105	Shieldalloy	5	6/24/66	10/03/66	
105A (Reprocessed)	Shieldalloy	95	3/01/67	4/13/67	
107	U. S. Borax	400	2/27/67	4/11/67	
1105	Wah Chang	20	3/18/66	7/20/66	
1105A	Wah Chang	80	3/18/66	9/20/66	
1106	Shieldalloy	5	5/13/66	8/29/66	
II06A (Reprocessed)	Shieldalloy	45	1/01/67	10/01/67 (anticip)	
1109	Wah Chang	300 (100) ^{**}	3/15/67	10/01/67 (anticip)	
1110	Carborundum	100	9/11/67	10/01/67 (anticip)	

Original order of 300 pounds changed to 100 pounds.

^{*}The roman numerals I and II identify the material as zirconium diboride and hafnium diboride, respectively; the designations 02 and 02A refer to different shipments of the same powder lot except where reprocessing is indicated.

TABLE 5
CHARACTERIZATION OF ZIRCONIUM DIBORIDE POWDER, 102

Supplier: U. S. Borax Research Corporation

Quantity: 102 (1 pound sample) - 102A (94 pound lot)

1. Qualitative Analysis (weight per cent, w/o)
Ti, Cr, Fe 0.1 - 1.0

Ti, Cr, Fe 0.1 - 1.0 V 0.01 - 0.1

- X-ray Phase Identification
 ZrB₂
 ZrO₂ (impurity)
 ZrC (impurity)
- 2. Quantitative Analysis (w/o)

79.6 Zr В 18.3 C 0.38 0 (AA) 1.05 0.02 Ti0,10 CrFe 0.08 Total 99.53

- 5. Powder Density6.03 g/cc
- 6. Particl: Size Distribution

Range (μ) w/o

0-5 4.0
5-10 23.4
10-20 64.5
20-40 7.6
>40 0.5

3. Atomic Ratio

Over-all B/Zr = 1.94Corrected $B/Zr^* = 2.07$

7. Phase Assay (volume per cent) ZrB₂ ZrO₂ ZrC

Calculated from Composition 93.6 4.4 2.0

^{*}Atomic ratio corrected for metal assumed to be present as metal dioxide and metal monocarbide.

TABLE 6
CHARACTERIZATION OF ZIRCONIUM DIBORIDE POWDER, 103

Supplier: U. S. Borax Research Corporation

99.02

Total

Quantity: 103 (1 pound sample) - 103A (100 pound lot)

- 1. Qualitative Analysis
 (weight per cent, w/o)

 Ca, Fe 0.01 0.1

 4. X-ray Phase Identification

 ZrB₂

 ZrO₂ (impurity)
- 2. Quantitative Analysis (w/o)

 Zr 79.8

 B 17.7

 C 0.03

 O(AA) 1.49

 5. Powder Density

 6.04 g/cc

 6. Particle Size Distribution
- - 7. Phase Assay (volume per cent) ZrB_2 ZrO_2 ZrC Calculated from Composition 93.5 6.3 0.2

Range (µ)

w/o

^{*}Atomic ratio corrected fo. setal assumed to be present as metal dioxide and metal monocarbide.

TABLE 7

CHARACTERIZATION OF ZIRCONIUM DIBORIDE POWDER, 107

Supplier: U. S. Borax Research Corporation

Quantity: 400 pounds

 Qualitative Analysis (weight per cent, w/o)

Fe, Ca, Ti 0.01 - 0.1

4. X-ray Phase Identification Z_rB_2

ZrB₂ ZrO₂ (impurity)

Powder Density

5.96 g/cc

2. Quantitative Analysis (w/o)

A В C Ave. 78.5 78.5 78.6 78.4 Zr 19.1 18.4 18.2 18.6 В C 0.26 0.22 0.31 0.25 O(AA) 1.30 1.31 1.31 1.31 O(VF) (1.15)98.67 98.62 98.16 Tota1 99.12

3. Atomic Ratio

新 一 二 高 藤

Over-all $B/Zr_* = 1.99$ Corrected B/Zr = 2.14 6. Particle Size Distribution

Range (μ) w/o

0-5 7.9

5-10 33.8

10-20 52.1

20-40 5.0

>40 1.2

7. Phase Assay (volume per cent) ZrB₂ ZrO₂ ZrC

Calculated from Composition 93.2 5.4 1.4

5.

1 The four hundred pound lot was blended then shipped in three separated containers designated A, B and C.

*Atomic ratio corrected for metal assumed to be present as metal dioxide and metal monocarbide.

TABLE 8

CHARACTERIZATION OF ZIRCONIUM DIBORIDE FOWDER, 105A

Supplier: Shieldalloy Corporation (H. C. Starck Berlin)

 $B/Zr_{*} = 1.97$ $B/Zr^{*} = 2.02$

Quantity: 100 pounds

Over-all Corrected

- 1. Qualitative Analysis
 (weight per cent, w/o)

 Ti, Fe, Co 0.01 0.1

 4. X-ray Phase Identification

 ZrB₂
- 2. Quantitative Analysis (w/o) 5. Powder Density Zr 79.3 5.97 g/cc В 18.65 0.02 O(AA) 6. 0.42 Particle Size Distribution Total 98.39 \mathbf{w}/\mathbf{o} Range (µ) 0-5 7.7 5-10 26.6 3. Atomic Ratio 10-20 44.7
 - 7. Phase Assay (volume per cent) ZrB₂ ZrO₂ ZrC Calculated from Composition 98.1 1.8 0.1

20-40

>40

17.8

1.1

* Atomic ratio corrected for metal assumed to be present as metal dioxide and metal monocarbide.

¹ The original five pound sample designated 105 was found unsatisfactory for this program as it contained significant amounts of ZrO₂ and ZrC. The 105A was obtained by reprocessing the 105.

TABLE 9 CHARACTERIZATION OF HAFMUM DIBORIDE POWDER, HOS AND HOSA

Range (µ)

w/o

Supplier: Wah Chang Corporation

Qualitative Analysis

0.07

100.38

1.

0

Total

Quantity: II05 (20 pound sample) - II05A (80 pound lot)

0.11

100.13

- X-ray Phase Identification (weight per cent, w/o) HfB_2 Zr 1 - 10 HfC (impurity) 0.1 - 1.0 0.01 - 0.1 Si Al 2. Quantitative Analysis (w/o) 5. Powder Density 10.69 g/cc 1105 II05A Hf+Zr 89.7 89.4 Zr 1.15 10.5 В 10.4 0.21 0.12 6. Particle Size Distribution C
- 0-5 7.7 5-10 29.7 3. Atomic Ratio 10-20 32.2 Over-all B/Hf_{**} = 1.9620-40 30.1 Corrected B/Hf = 2.03>40 0.3
 - Phase Assay (volume per cent) HfC HfB₂ HfO₂ Calculated from Composition 97.6 1.8 1.9

^{*}Atomic ratio corrected for metal assumed to be present as metal dioxide and metal monocarbide.

TABLE 10
ADDITIVE MATERIAL PROCUREMENT SCHEDULE

			Purchase Schedule	
<u>Material</u>	Supplier	Quantity pounds	Ordered	Received
Silicon Carbide: Powder Fiber	Carborundum Carborundum	30 1	3/18/66 3/27/67	5/10/66 3/31/67
Silicides: B ₆ Si HiSi	Cerac Wah Chang	1 1	3/9/67 3/18/66	3/14/67 6/10/66
Metals: Hf Hf-27Ta (01)* Hf-27Ta (02)* W (Filament) Cr	Wah Chang Wah Chang Wah Chang General Electric J. Hardy	5 0.9 6 1 5	3/18/66 5/16/66 3/15/67 4/13/67 MANLABS ST	4/ 5/66 5/20/66 7/15/67 5/ 5/67
Graphites: Poco (Powder) Thornel 25 (Fiber)	AFML AFML	5.0 0.5		2/17/67 4/ /67

^{*}The designations of (01), (02) refer to different orders of a given material.

CHARACTERIZATION OF SILICON CARBIDE ADDITIVES

Silicon Carbide Powder, SiC (04)

Qualitative Spectroscopic Analysis:

Si, > 10%; Ti, 0.1-1%; V, 0.01-0.1%; all other metallic impurities less than 0.01%

Quantitative Chemical Analysis:

Si, 69.8%; C, 29.5%

X-ray Phase Identification:

SiC

Silicon Carbide Fibers

Qualitative Spectroscopic Analysis:

Si > 10%; B, 0.1-1.0%; Mg, Ca, Fe, 0.01-0.1%; all other metallic impurities less than 0.01%

Suppliers Specifications:

 $0.5 - 3.0\mu$ - Diameter

 $100 - 750\mu - Long$

Composition Si + C ≥ 95%

CHARACTERIZATION OF METALS AND ALLOYS

Hafnium Metal Powder, Hf(04)

Qualitative Spectroscopic Analysis:

Hf, > 10%; Zr, 0.1-1%; all other metallic impurities less than 100 ppm.

Qualitative Spectroscopic Analysis (by Supplier):

Zr, 2.50%; all other metallic impurities less than 200 ppm.

Quantitative Chemical Analysis (by Supplier):

O, 790 ppm; C, < 30 ppm.

X-ray Phase Identification:

Hf

Hafnium-Tantalum Alloy Powder, Hf-27Ta(01)

Qualitative Spectroscopic Analysis:

Hf, Ta. > 10%; Zr, 1-10%; all other metallic impurities less than 0.01%.

Quantitative Spectroscopic Analysis (by Supplier):

Zr, 1.9%; W. 0.11%; Mo. 0.06%; all other metallic impurities less than 125 ppm.

Quantitative Chemical Analysis (by Supplier):

Ta, 23.7%; O, 0.15%; C, 50 ppm.

X-ray Phase Identification:

 α Hf, β Ta Consistent with phase diagram for this composition.

Tungsten Filament

Qualitative Spectroscopic Analysis:

Th, B, 0.1-1.0%; all other metallic impurities less than 0.01%.

Dimensions:

0.001 inch diameter, 1/8 inch + 1/64 inch long.

CHARACTERIZATION OF SILICIDE ADDITIVES

Hafnium Silicide Powder, HfSi(01)

Qualitative Spectroscopic Analysis:

Hf, Si, > 10%; Zr, 1-10%; all other metallic impurities less than 0.01%.

Quantitative Chemical Analysis (by Supplier):

Atomic Ratio Si/Hf = 1.35.

X-ray Phase Identification:

HfSi, HfSi,

Boron Silicide Powder, B₆Si(01)

Qualitative Spectroscopic Analysis:

B, Si, > 10%; Mg, 0.1-1.0%; Ca, Mn, Fe, Sn, 0.01-0.1%; all other metallic impurities less than 0.01%.

Quantitative Chemical Analysis:

Si, 31.0

Atomic Ratio:

B/Si = 5.7 (calculated for 68.0% B determined by difference).

X-ray Phase Identification:

SiB₆

TABL: 14

CHARACTERIZATION OF GRAPHITE AND CARBON ADDITIVES

Poco Graphite Powder

Qualitative Spectroscopic Analysis:

B, > 1%; Cr, Mn, Fe, Co, Pb, 0.01-0.1%; all other metallic impurities less than 0.01%.

Particle Size:

-400 mesh.

Thornel 25 Graphite Fibers

Qualitative Spectroscopic Analysis:

All metallic impurities less than 0.01%.

Dimensions:

Regal 330 Carbon Powder

Suppliers (Cabot Corp.) Specification:

Per cent C, 99; per cent volatiles, 1; physical state, amorphorous; particle size, 200A.

TABLE 15

FABRICATION CONDITIONS AND BILLET CHARACTERISTICS FOR RESULTING DENSITIES FOR CUSTOM PRESSINGS PERFORMED BY CARBORUNDUM

	0				Billet	
Ident. No.	Temp. °C	Press.	Hold Time	Density	Characteristics	
	(optical)	(psi)	(min)	(g/cc)		
Carborundun	Powder Lot:	Carbo 166				
Triplica	te Pressing No	<u>. 1</u>				
1 A	2150	3000	45	5.81	Crack free	
1B 1C				5.79	Crack free	
ic				5.75	Crack free	
Triplica	te Pressing No	<u>. 2</u>				
2A	2000	2000	45	5.70	Crack free	
2B				5.60	Circumferential cracks	
2C				5.60	Circumferential	
					cracks	
	wder Lot 102A					
Single P	ressings					
3	1900	4000	50	4.78	Crack free	
4 7	2160 2160	4000 4000	90 50	6.01 6.04	Crack free Crack free	
			30	0.04	Older 11 ce	
Triplica	te Pressing No	<u>. 9</u>				
9A	2160	4000	50	5.97	<pre>1/2 inch Radial edge crack</pre>	
9B				6.00	Extensive crack-	
9C				6.02	ing 1/2 inch Radial	
,0					edge crack	
ManLabs Powder Lot 103A						
5	2000	4000	60	5.52	Crack free	
6	1900	4000	100	4.88	Crack free	
8	2200	4000	50	5.96	Crack free	
Triplicate Pressing No. 10						
10A	2200	4000	50	6.00	Extensive crack-	
10B				6.03	ing Extensive crack-	
100					ing	
10C				6.00	1/2 inch Radial	
					edge crack	

TABLE 16

POWDER DENSITIES AND MAXIMUM BILLET DENSITIES

FOR MATERIALS I TO XII

Material Designation	Air Pycnometric Powder Density or Calculated Density (c) gm/cc	Maximum Density Based On A Fabrication gm/cc
102A	6.03 <u>+</u> .02	*
103A	$6.04 \pm .01$	*
104	6.00 <u>+</u> .02	*
105	$6.33 \pm .02$	*
106	5.96 + .02	6.03
107	5.96 <u>+</u> .02	*
ш05	10.69 + .04	*
1106	11.15 + .04	11.17
1107	10.25 + .	**
1108	9.57 ± .03	10.21
11105	9.20 (c)	9.50
IV05	8.45 (c)	8.62
V02A	5.47 (c)	5.54
V03A	5.47 (c)	*
V07	5.42 (c)	5.56
V105	10.89 <u>+</u> .02	10.97
VIII02A Regal	4.37 (c)	4.50
VIII07 Regal	4.33 (c)	4.66
VIII07 Poco	4.44 (c)	*
X07	5.24 (c)	5.53
X1102	4. 11 (c)	*
XII07 Poco	4.32 (c)	*
XII07 Regal	3.88 (c)	*

^{*}All hot pressed billets were equal to or less than powder density.

**Powder reacted with die.

TABLE 17

MATERIAL I OT PRESSING CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure	Time	Density	Grain Intercept	Furnace No.
	°C			gm/cc		
	- C	psi	min	gm/cc	μ	
				_		
102A D0282	2100	6000	120	5.91	32	
102A D0283	2050	6000	60	5.87	24	
102A D0289	2050	6000	30	5.80	22	
102A D0290	2050	8000	30	5.85	26	
102A D0291	2200	6000	30	5.78	27	
102A D0304*,	2070	6000	60	5.83	35	
102A D0305F1	2075	6000	60	5.99	35	
1 Stark D0306	2070	6000	60	6.08	10	
102A D0307F	2000	6000	60	5.95	30	
103A D0308	2070	6000	60	6.05	25	
103A D0309	1980	6000	60	6.04	20	
103A D0310	1900	6000	90	5 .97	13	
103A D0311	1800	6000	120	5.54	9	
103A D0312	1800	6-8000	60	5.66	7	
103A D0313	1900	4000	60	5.99	10	
103A D0314F	1800	6000	120	6.00	8	
102A D0318**	2080	6000	60	++	en en	
103A D0320**	1900	6000	60	5.81	10	
102A D0322	2200	4000	90	++		
103A D0323	1800	6000	60	5.19		
103A D0324	1800	6000	30	5.56	7	
103A D0325	1800	6000	15	5.18	- ~	
102A D0326	2100	6000	240	6.02	40	
102A D0327	1900	6000	60	5.68	7	
103A D0328	1800	6000	25	5.37	6	
103A D0329	1900	4000	60	6.00	~ 51	
103A D0330	1900	4000	90	5.98		
103A D0331			reacted	ì	~-	
103A D0332	1900	4000	120	5.39		
103A D0333	1900	4000	30	4.89		
103A D0334	1900	4000	180	5.94		
103A D0335	2000	4000	60	5.93		
102A D0336	2000	4000	35	5.65		
102A D0337	1900	4000	90	5.62	9	
102A D0338	1900	4000	50	5.32	30	
103A D0339	1900	4000	100	5.52	9	
103A D0340	1900	4000	145	5.82	11	

^{*}Ball milled with WC balls.

^{**}Sample size 1 inch diameter by 1 inch high.

¹ The letter "F" identifies fluid energy milled powder.

TABLE 17(CONT)
MATERIAL I HOT PRESSING CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure	Time	Density	Grain Intercept	Furnace No.
	°C	psi	min	gm/cc	μ	<u> </u>
	•	P		6. 4	•	
102A D0341	2100	6000	90	5.89	31	
102A D0342	2200	4000	40	4.88		
102A D0343	2000	4000	60	5.43	6	
102A D0344	2100	4000	25	5.40		
102A D0345F	1950	6000	225	5.97	21	
102A D0347	2100	4000	40	5.66		
103A D0359	2000	4000	75	5.94	***	
103A D0360	2000	4000	75	5.77		
102A D0361	2160	4000	50	5.70		
102A D0362	2160	4000	35	5.76		
102A D0363F	2100	4000	80	3.87	24	
102A D0364	2160	4000	90	5.91		
102A D0365	Reacted		• •			
103A D0366	2000	4000	75	5.92		
103A D0367	2000	4000	75	5.85		
103A D0368	2000	4000	75	5.68		
103A D0369	2000	4000	75	6.00		
103A D0414	2000	4000	120	5.88	15	
103A D0415	2000	4000	73	5.78	12	
103A D0416	2000	4000	110	3.95		
103A D0417	1900	6000	105	Reacted		
102A D0418	2100	6000	163	5,88		
102A D0419F	1900	6000	102	5.80	13	
103A D0420F	1800	6000	220	5.81		
102A D0421F	2000	6000	115	5.93	30	
103A D0422	1900	6000	120	6.00		
105 D0455	1900	4000	110	4.95		lB
105 D0446	2000	2500	31	3.94		2B
I04 D0447	2000	6000	80	5.64	10	3B
105 D0450	2100	6000	130	6.11	8	lB
105 D0451	2000	6000	80	4.76		2B
104 D0452	2 100	6000	150	5.81	19	3B
104 D0453	2000	6000	70	4,35		2 B
105 D0454	2 100	4000	80	5.08		1B
105 D0455	2200	4000	75	. 6.22		3B
102A D0481	2 150	5000	33			3 <u>C</u>
103A D0483	2080	4000	1000	5.87	A. (5	2C
103A D0484	2080	4000	90	5.91	13	2C
102A D0485	2100	6000	270	5.02		1C
106 D0486	2100	6000	180	Reacted		3C
106 D0489	2000	6000	160	6.03		3C

TABLE 17 (CONT)

MATERIAL I HOT PRESSING CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure psi	<u>Time</u> min	Density gm/cc	Grain Intercept #	Furnace
		•		B , 00	F-	
103A D0475K	2100	2500	120	5.99	23	2B
103A D0459K	2000	2500	55	5, 5		3C
I05 D0463	2220	6000	180	5.63	7	3C
103A D0466	2220	8000	90	6.03	29	1C
102A D0481	2150	5000	33	0.05	-,	3C
I03A D0483	2080	4000	100	5.87	33	2C
I03A D0484	2080	4000	90	5.91	13	2C
102A D0485	2100	6000	270	5.02		ic
106 D0486	2100	6000	240	5,02		3C
I06 D0489	2000	6000	160	6.03	7	3C
I03A VB01	1500-	4000	400	4.01	31	30
	1600		(vacuum			
103A D0539K	2100	2500	120	6.06		1E
103A D0542K	2000	2500	75	0.00		***
103A D0545K	2000	2500	110			2E
103A D0548K	2000	4000	60	5.17	97	2E
107 D0555	2000	4000	60	5.75	22	1E
107 D0558	2000	4000	150	5.81		1E
107 D0560	1950	3000	60	5.69		1E
103A D0563K	2050	2500	105	5,94	56	3E
107 D0574	2050	4000	80	5.83	35	3E
107 D0575	2100	4000	75	5.75	34	1E
105A D0587	2100	4000	65	5.90	69	3E
107 D0589	2150	4000	120	5.90	38	1E
I05A D0590	2050	4000	80	5,93	15	îĒ
102A D0610	2100	4000	60	5.81		2
102A D0613	2060	4000	60	5.45	18	2
103 D0619	2000	2500	140	6.02		2
107 D0628F	2060	4000	55	5.98		ž
105A D0650K	2080	2500	120	5.92		-
103A D0656	1900	4000	58	. • • =		3
103A D0657	2100	4000	60			3 2
						_

^{*}Letter "K" designated billets 3 inch diameter by 1 inch high, all other billets 2 inch diameter by 0.7 inch high.

Volume Percentage

Phase	103A D0308	102A D0283
ZrB ₂	87.85	87.7
Orange Phase	2.33	1.1
ZrO ₂ (Gray Phase)	9.82	8.5
Pores by Density		2.7

^{*} Data obtained from twelve lineal analysis traces of approximately 500 microns each.

TABLE 19

MATERIAL I WITH INTENTIONAL IMPURITY PHASE ADDITIONS,
FABRICATION CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure	Time	Density
	°C	psi	min	gm/cc
102A D0302 (+5 w/o ZrO ₂)	2070	6000	30	6.03
102A D0303 (+5 w/o ZrC)	2070	6000	30	6.04
I02A D0504 (+10 w/o Y ₂ O ₃ ZrO ₂)	1950	4000	60	4.99
102A D0505 (+10 w/o ZrO ₂	1950)	4000	70	

TABLE 20

MATERIAL V FABRICATION CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure psi	Time min	Density gm/cc	Grain Intercept µ	Furnace No.
		•		•	,	
V02A D0370	2160	4000	50	5 .4 9	9	3
V02A D0371	2 160	6000	58	5.49	8	3 2
V02A D0372	2100	4000	67	5.47	8	1
V02A D0378	2160	6000	120	5,55	11	2.
V03A D0381	2000	4000	60	5.83		1
V02A D0382	2100	4000	60	5,51		2A
V03A D0384	2000	4000	70	5.54		1A
V02A D0387	2 100	4000	20	5.45	7	1A
V02A D0388	1900	4000	30	4.79	5	2A
V03A D0389	1900	4000	40	5.30		3A.
V02A D0390F*	2000	4000	25	5.11	7	3A
V02A D0391F	2000	4000	15	5.02	7	1B
V02A D0392F	2000	4000	45	5,21	7	1B
V02A D0393F	2000	4000	35	5.40	6	2B
V02A D0394F	2000	4000	50	5.47	6	3B
V02A D0395	1900	4000	115	5.22	7	3B
V02A D0396	1900	4000	125	5.49	7	2B
V02A D0397	1900	4000	110	5.28	8	1B
V02A D0398	1800	6000	120	5.23	6	2B
V03A D0473	2000	4000	40	5.2 4	7	1C
V03A D0474	2000	4000	40	5.29		2C
V03A D0477	2100	4000	45	5.33		3C
V03A D0478	2000	2500	50	5.02	7	1 C
V03A D0479	2000	2500	20	4.50		2C
V03A D0480	2000	6000	90	5.54_	7	1 C
V02A Q2206L	2000	2500	90	5.40 ⁺		4A
V02A Q2221L	2000	1000	75	5.12		4A
V02A Q2225L	2050	1000	60			
		2000	60	5.31		4A.
V(5)02 D0531	2050	4000	60	5.84	11	1D
V(10)02 D0532		4000	60	5.80	10	1D
V(15)02 D0533		4000	60	5.66	6	lD
V(35)02 D0541		4000	50	5.04	6	
V(50)02 D0557		4000	105	3.57	5	3E
V02A D0570	2100	4000	85	5.44		2E
V07 D0571K	5200 0	2500	50	5.20		1E

^{*}F Fluid Energy milled.

<u>_4</u>'

L designates billet size 5-3/4 inch x 5-3/4 inch x 1 inch.

^{*}Cracked during extraction from the die.

^{**}K designates billet size 3 inch diameter x 1 inch high.

TABLE 20 (CONT)

MATERIAL V FABRICATION CONDITIONS AND RESULTS

Mate: Design		Temp.	Pressure	Time	Density	Grain Intercept	Furnace No.
		C	psi	min	gm/cc	μ	
V 07 I	D0576K	2100	2500	90	5.39		2E
	D0578K	2100	2500	40	5.59		2E
V07 I	D0580K	2100	2500	55	5.56	7	2 E
	D0582K	2100	2500	50	5.53	•	3E
V07 I	D0586K	2100	4000	37	5.55		1E
V07 I	00594	2100	4000	160	5.54		1E
V02A I	00612	2060	4000	60	5.44		1
V02A I	00614	1900	4000	60	4.93		1
V07 I	00616	2060	4000	40	5.39		2
V05 I	00617	2060	4000 `	45	5.71		1
V05A I	00618	2060	4000	80	5.54	9	1
V07Q 2	2295L	2000	2500	132	5.53		
VOSA I	00622	2100	4000	125	3.76		1
V07Q 2	2297L	2000	2500	80	5.50		2
VO3A I	00658	1900	4000	60	4.95		3 3
VO3A I	00659	2100	4000	60	5.49		3

TABLE 21

FABRICATION CONDITIONS FOR SPECIAL MATERIALS USED
FOR MATERIAL V PHASE ANALYSIS

Composition	Billet	Temp.	Pressure psi	Time min	Furnace No.
20 v/o ZrC 80 v/o SiC	D0623	2100	4000	160	1
20 v/o ZrO ₂ 80 v/o SiC	D0624	2050	4000	120	1
20 v/o 105A 20 v/o ZrC 60 v/o SiC	D0625	2050	4000	110	2
20 v/o 105A 20 v/o ZrO ₂ 60 v/o SiC	D0626	2050	4 000	100	1
20 v/c ZrC 20 v/c ZrO ₂ 60 v/c SiC	1 0627	2050	4 000	155	1

TABLE 22

MICROSTRUCTURE STUDY OF SPECIAL MATERIALS USED FOR MATERIAL V ANALYSIS

	H ₂ SO ₄			;	no attack etched no attack		etched	no attack	stched no attack	
Result of Etching with	HINO.			• •	no attack etched no attack		etched	no attack	no attack no attack	
Resul	HNO ₃ +HF			17 m	etched		etched	no attack	no attack etched	
	Color			1	white gray dk. gray		white	white	gray dk. gray	
**	Measured			(-36) (20	701 (25g) 1231 (25g) 2241 (25g)		1128 (25g)	833	1321 (25g) 1723 (25g)	
•	Microhardness, KHN Accepted Measured Kg/mm Kg/mm			950 (50g)	1030 (100g) 3000 (100g) 1875 (100g)		2250K (100g) 1128K (25g)	950 (50g) 1030 (100g)	3000 (130g) 1875 (100g)	
i	X-ray Phase Identification Sefore After	ZrB2 SiC	ZrC SiC	$2rSi_2$	ZrC SiC	ZrB2 ZrC SiC	ZrB2	ZrSi ₂	ZrC	ZrC ZrSi Sic
;	X-ray Identii Before	ZrB2 SiC	ZrC SiC	Zr0z	Sic	ZrB2 ZrC SiC	ZrB2	2r0 ₂	Sic	Zrc Zroz Sic
Power	Mixture Composition	20v/o ZrB2 80v/o SiC	20v/o ZrC 80v/o SiC	20v/o ZrO2	80v/o SiC	20v/o ZrB2 20v/o ZrC 60v/o SiC	20v/o ZrB2	20v/o ZrO ₂	60v/o SiC	20v/o ZrC 20v/o ZrO ₂ 60v/o SiC
į	No.	D0622	D0623	D0624		D0625	D0626			D0627
					201					

^{*} Losd values shown in perentheses.

TABLE 23

MATERIAL VIII FABRICATION CONDITIONS AND RESULTS

Material Designation	Graphite Source	Temp.	Pressure psi	Time min	Density gm/cc	Grain Inter- cept	Furnace No.	
VIII02 D0497	Regal	2200	4000	90	Reacted			
VIII02 D0498	Regal	2100	4000	90	4.53	5	3C	
VIII02A D0592	Poco	2050	4000	100	4.50	5	3 E	
VIII07 D0605K	Regal	2100	2500	48	Reacted		2	
VIII07 D0606K	Regal	2050	2500	190	4.55		3	
VIII07 D0607	Poco	2050	4000	82	4.42	4	3	
VIII07 D0609	Aquadag	2050	4000	70	4.57	4	2	
VIII(17)(15)07 D0620	Regal	2050	4000	120	5.04	4	2	
VIII07 D0621K	Regal	2060	2500	155	4.47		1	
VIII07 Q2301L	Regal	2000	2500	140	4.27			

TABLE 24

MATERIAL X FABRICATION CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure psi	Time min	Density gm/cc	Grain Intercept µ	Furnace No.
X07 D0596	1900	4000	40	5.53	12	1
X07 D0597	1800	4000	50	5.28	4	1
X07 D0634	1700	4000	195	5.28	5	1
X07 D0635	2000	4000	140	5.81	15	3

2000年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,1900年,19

TABLE 25

MATERIAL XII FABRICATION CONDITIONS AND RESULTS

Material Designation	Graphite Source	Temp.	Pressure	Time	Density	Grain Intercept	Furnace No.
		°C	psi	min	gm/cc	μ	
XII02 D0544	Poco	2200	4000	60	Reacted		2 E
XXX02 D0546	Poco	2100	4000	120	3.64		2E
XX107 D0579	Poco	2100	4000	80	4.06	4	3E
XXX(20)07 D0585	Poco	2100	4000	50	5.30	5	1E
XII(5)07 D0500	Poco	2100	4000	80	Reacted		lΈ
XXX(10)07 D0601	Poco	2100	4000	Reacte	d		2 E
XXX(5)07 D0602	Poco	2050	4000	145	5.89		2
XXX(15)07 D0603	Poco	2050	4000	105	5.42	6	3 2
XII(35)07 D0604	Poco	2050	4000	190	4.61	4	2
XII(20)07 D0608	Rogal	2050	4000	80	5.23	5	2
XXX(5)07 D0615	Thornel	2060	4000	103	5.89		1
XII07 D0629K	Regal	2060	2500	113	3,88		2
XII07 D0630K	Regal	2060	2500	69	Porous		1
XII(5)07 D0638	Regal	2080	4000	73	5.89		3
XII(10)07 D0634	Regal	2080	4000	80	5.61		1
XX(15)07 D0641	Regal	2080	4000	85	5.51		1
XII(20)07 D0642	Regal	2080	4000	80	5.19		3
XII(5)07 D0665	Poco	1900	4000	120			3
XXX(10)07 D0667	Poco	2050	4000	202			3
XII(5)07 D0668	Poco	2050	4000	200			1

TABLE 26

MATERIAL II HOT PRESSING CONDITIONS AND RESULTS

Material Designation	T'emp.	Pressure	Time	Density	Grain Intercept	Furnace No.
	°C					
	C	psi	min	gm/cc	μ	
TIOE DOGLE	2000	4000				
Ц05 D0315	2000	6000	150	9.23	9	
HO5 D0316	2200	6000	120	10.62	40	
H05 D0346	2100	6000	60	9.52	12	
HO5 D0348	2200	6000	200	10.58	34	
HO5 D0349	2150	6000	30	9.53	11	
H05 D0351	2200	4000	200	10.53	31	
1105 D0352	2100	4000	150	10.25	15	
П05 Д0353	2200	4000	140	10.52	37	
110" D0354A	2165	4000	120	10.32		
1105 D0354B	2165	4000	120	10.53		
1105 D0355A	2200	4000	120	10.50	42	
1105 D0355B	2200	4000	120	10.46	41	
1105 D0356A	2170	4000	120	10.07		
1105 D0356B	2 170	4000	120	10.19	19	
1105 D0357	2150-2200	4000	120	9.93	14	
1106 D0373	2200	4000	55	11.10		2 A
Щ06 D0374	2100	4000	42	11.17		3 A
II06 D0375	2000	4000	68	11.15		1 A
II06 D0376	1900	4000	145	11.14	7	3A
II06 D0379	1800	4000	130	10.84	5	3A
II06 D0383	2000	4000	40	11.17	•	3A
II05 D0399	1900	4000	100	9.10		3B
II05 D0409	2000	6000	180	9.80	8	3B
II05 D0413	2100	2500	124	9.54	•	3B
1105 D0423	1900	6000	180	9.26	9	žB
II05 D0425	2000	4000	153	9.45	ý	1B
II05 D0427	2100	4000	108	9.57	15	2B
1105 D0429	2100	6000	137	10. 13		1B
1105 D0430	2200	2500	60	Reacted		3B
II05 D0435	2100	6000	95	9.84		3B
H05 D0437	2200	2500	110	9.93		
II07 D0458	2200	4000	53	Reacted	22	238
II05 D0471	2000	8000	30	9.36	EL	1B
H05 D0482F	2100	6000	40	7.36 10.24		3C
II05 D0482A	1980	6000	60			3C
1108 D0487	2200	4000		10.21	A	2C
1108 D0490	2 100		120	9.95	46	2C
1105 D0595K	2100	4000 2500	160	10.21	23	2C
			20 16 #	9.51		3E
1106 D0672	1900	4000	165	10.67		

TABLE 27

PHASE DISTRIBUTIONS FOR HOT PRESSED BILLETS

OF MATERIALS II, III AND IV

			o e Per (Cent	
Material Designation	HfB ₂	SiC	Major Impurity Phase	Grain Boundary Phase	Pores
II05 D0316	91.4	0	7.8	0,1	0.7
11105 D0377	71.8	24.8	3.4	0	0
IV05 D0405	69.2	29. 5	1.3	0	0

TABLE 28

MATERIAL III HOT PRESSING CONDITIONS AND RESULTS

Material * Designation*	Temp.	Pressure psi	Time min	Density gm/cc	Grain Intercept µ	Furnace No.
H105 D0377	2200	4000	90	9, 50	16	2A
III05 D0380	2150	4000	90	9.41	12	1A
III05 D0385	2050	4000	7 5	9.25	9	2A
11105 D0386	2050	4000	60	9.26	ģ	3A
III05 D0400	2000	4000	110	8.86	ģ	1B
III05 D0401	1900	4000	100	8.19	Ś	2B
III05 D0402	1900	6000	160	7.84	6	1B
11105 D0403	2100	4000	90	9.28	8	2B
III05 D0404	1800	5000	120	7.34	-	3B
III05 D0408	2000	6000	160	9.03	5	1B
III05 D0412	2100	2500	132	9. 12	10	1B
H105 D0426	2000	4000	128	9.06	7	3B
III05 D0431	2200	2500	80	8.61		3B
11105 D0433	2200	4000	39	9.33	11	1B
III05 D0438	2100	2500	100	9.04		1B
III05 D0440	2000	2500	128	7.82		18
III05 D0444	2000	4000	100	8,52	6	1B
III(5) 05 D0496	2200	4000	90	10.16	63	2C
III(10)05 D0503	2150	4000	90	10.00		3C
III(10)05 D0538	2030	4000	70	9.81	9	1D
III(10)05 D0559	1950	3000	60	7.35		3E
11105 D0573	2100	4000	80	9.18		2E
11105 D0583K	2100	4000	80	9.30		2E
III(50)05 D0593	2050	4000	120	6.79		3E
11105 D0599K	2100	2500	40	9.23		1E

The basic composition of Material III contains 20 vol. % SiC. Composition variations from this base are denoted by placing the vol. % of SiC in parenthesis following the roman numeral III.

TABLE 29

MATERIAL IV FABRICATION CONDITIONS AND RESULTS

Material * Designation	Temp.	Pressure psi	Time min	Density gm/cc	Grain Intercept µ	Furnace No.
IV05 D0405	2200	4000	103	8.62	13	18
IV05 D0406	2100	4000	70	8.60	8	2B
IV05 D0407	2000	4000	110	7.92	8	2B
IV05 D0410	2000	6000	191	8.57	6	2B
IV05 D0411	2100	2500	160	7.91	7	1B
IV05 D0424	1900	6000	122	7.78	7	1B
IV05 D0428	1900	4000	127	6.98		2B
IV05 D0432	2200	2500	60	Reacted		1B
IV05 D0434	2000	4000	80	8.45	8	2B
IV05 D0436	2100	2500	120	7.97		31B
IV05 D0439	2100	4000	68	8,57	8	2B
IV05 D0441	2000	2500	80	6.88		3B
IV05 D0442	1900	4000	141	6.97		2B
IV05 D0443	2000	4000	90	7.99		3B
IV05 D0448	2150	2500	50	8,59	10	3 B
IV05 D0449	2050	4000	140	7.78	7	2B
IV05 D0476	2000	5000	95	7.94	6	2C
IV05 D0547	2000	4000	80	Cracked		2E
IV05 D0549	2000	4000	140	8.53		3E

^{*}The basic composition of Material IV contains 30 vol. % SiC.

TABLE 30

MATERIAL WI FARRICATION CONDITIONS AND RESULTS

Material Designation	Temp.	Pressure psi	Time min	Density gm/cc	Grain Intercept µ	Furnace No.
VI05 D0460	2000	6000	120	9.01		2C
VI05 D0461	2100	6000	160	10.03	8	10
VI05 D0462	2200	4000	190	10.97	14	16

TABLE 31

PHASE DISTRIBUTION FOR MAXERIAL VI
BILLET VI05 D0462

Phase	Volume Per Cent
нв ₂	92
Hf-Ta Phase	6.3
Gray Phase	1.7
Porosity	0.0

TABLE 32
INCIDENCE OF BILLET CRACKING FOR
MATERIALS I AND II

Designation	Powder		Number/ Total	Per Cent
I	02 A	severe cracks total examined	0/13 4/13 4/13	0
	02A	edge cracks/total examined	4/13	0 31 31
	02 A	total cracked/total examined	4/13	31
	03A	severe cracks/total examined	4/19	21
	03A	edge cracks/total examined	6/19	31
	03A	total cracked/total examined	10/19	31 53
	£ 11**	severe cracks/total examined	6/38	16
	all	edge cracks/total examined	12/38	31
	all	total cracked/total examined	18/38	16 31 4 7
11	05	severe cracks/total examined	3/24	1.3
**	05	edge cracks/total examined	3/24 4/24	13 17
	05	total cracked/total examined	7/24	29
	03	total clacked total examined	•	-,
	06	severe cracks/total examined	4/5	80
	06	edge cracks/total examined	4/5 0/5	0
	06	total cracks/total examined	4/5	80

の 1000 mm 10

^{*}Severe cracks, indicates billet scraped.

^{**}Includes 102A, 103A, 104, 105 and 106 powders.

TABLE 33

PRESS FORGING OF MATERIAL I

Reduction In Height	35*	16
Final Density	93,3	100
Forging Time min	180	06
Forging Pressure psi	0009	8000
Forging Temp.	2200	2200
Original Density	42	99.5
Original Billet	D0451	D0369
Material Designation	105 DO463	103A D0466

* Partially due to densification.

TABLE 34
PLASMA SPRAYING OF MATERIALS I AND II

Material Designation	Substrate	Gun to Work Distance inches	Current amps	Results
102A P009F	Silica Phenolic	5	700	12 mil coating, poor self bonding
П05 Р007	Silica Phenolic	5	700	12 mil coating, poor self bonding
102A P0158F	Stainless Steel	5	700	3 mil coating, poor self bonding
102A P0159F	Stainless Steel	2-3	750	5 mil coating
102A P0160F	Stainless Steel	2-3	750	7 mil coating
102A P0161	Stainless Steel	2-3	750	5 mil coating
102A P0162F	Stainless Steel	2-3	750	Poor adherence
102A P0175	Stainless Steel	2-3	750	12 mil coating
102A P0176	Copper	2-3	750	11 mil coating
102A P0177	Aluminum	2-3	750	8 mil coating

TABLE 35

SINTERING CONDITIONS AND RESULTS

W.	gm/cc %	68 7.27 No	2.67 Yeu	23 28,8 Yeu	35 27.5 Yeii	43 28.2 Yen	50 2.7 No	50 1.4 No	37 5.0 No	48 0.5 One End
	•	3,68		5,23	5,35	5, 43	4,50	3,50	4,37	3.48
		1.5 x 10 ⁻⁵	1,5 x 10°5	1,0 × 10-5	1.0×10^{-5}	1.0 × 10-5	Argon	Argon	Argon	Argon
	uju	09	09	150	150	150	40	960	066	120
i i	o C	2075	2075	2200	2200	2200	2400	2000	2000-2100	2200
Cold	10 psi	02	70	15	40	20	10	រេ	20	20
Material Designation		V03A B0001*	103A B0002*	103A B0003*	103A B0004*	103A B0005	102A B0009*	103A B0010	V03A B0011	105A B0012**

*Samples 1/2 inch diameter x 1/4 inch high. **Samples 1 inch diameter x 1 inch high.

TABLE 36

REINFORCED COMPOSITES FABRICATION CONDITIONS
AND RESULTS

Material Designation	Rein- forcing Agent	Temp °C	Pres- sure psi	Time min	Density gm/cc	Remarks
Vf(5)02A D0566	SiC Whiskers	2050	4000	50	5.78	Whiskers descroyed redistributed
Vf(2002A D0567	SiC Whiskers	2050	4000	115	3.05	Whiskers destroyed
XIIf(5)03A D0572	Thornel 25	2100	4000	80	5.94	Reaction of Fibers
XUf(5)03A D0615	Thornel 25	2060	4000	103	5.89	Fibers completely disappeared
XIIf(5)07 D0644	Thornel 25	2060	4000	102	5.83	Continuous filaments satisfactory distribution
XIII(5)02A D0564	W Filament	2050	4000	185	5.76	Filament cluster and slight reaction

TABLE 37
POSSIBLE DIBORIDE MATRIX FIBER COMBINATIONS*

Material	Expected Stability Limit	Remarks
W-ZrB ₂	2250°C	Probable cracking due to differences in coefficients of thermal expansion (CTE) but otherwise mechanically and thermally stable.
W-HfB ₂	2345°C	Same as W-ZrB2.
Mo-ZrB ₂ , Mo-HfB ₂	<1400°C	Possible ternary reaction phase leading to dissappearance of fibers.
Ta-ZrB ₂	2160°C	Liquid formation and possible ternary reaction phase at much lower temperature leading to dissappearance of Ta.
Ta-HfB ₂	2220°C	Same as Ta-ZrB ₂ .
B-ZrB ₂	2000°C	Eutectic melting, moreover B fila- ments degrade severely and perma- nently around 800°C.
B-HfB ₂	2065°C	Same as B-ZrB ₂ .
C-ZrB ₂	2390°C	Pseudo binary eutectic melting, also probably cracking due to CTE difference.
C-HfB ₂	2515°C	Same as C-ZrB ₂ .
SiC-ZrB ₂ , SiC-HfB ₂	2200°-2300°C	Excellent thermochemical compatibility and increased oxidation resistance of diborides. Cracking found in particulate composites.
B ₄ C-ZrB ₂	2220°C	Pseudo binary eutectic melting, also probable cracking due to CTE difference.
B4C-HfB2	2330°C	Same as B ₄ C-HfB ₂ .
Al ₂ O ₃ -ZrB ₂ , Al ₂ O ₃ -HfB ₂	2049°C	Melting of alumina. Possible lung term lower temperature utilization if fabrication can be performed below melting point of oxide.

TABLE 38
SUMMARY OF THERMAL SCREENING

Run No.*	Temp OC (optical)	Time-min	Atm	Specimen	Remarks
1	1830	60	Argon	Carb ZrB2	Thin oxide skin
2	1830	60	Argon	Carb ZrB2	
3	1830	60	Argon	Norton ZrB ₂ 102A D0283	
4	1830	60	Argon	102A D0291	
5	1830	60	Argon	Carb ZrB ₂ 102A D0305 103A D0340	Thin oxide skin Thin oxide skin Thin oxide skin
6	1830	60	Argon	102A D0291 102A D0326 102A D0338 102A D0345 103A D0309 103A D0314 103A D0328 103A D0360	
7	1830	60	10 ⁻⁵ Torr	V02 D0372	~ 1 mil SiC "recession"
8	1800	120	Argon	11105 D0386	~ 1 mil SiC "recession"
9	2100	60	10 ⁻⁵ Torr	102A D0326 103A D0314 1105 D0348 11105 D0386 1V05 D0410 V02A D0371 V03A D0480 V105 D0462	
10	Furnace	failure at 227	70 ⁰ C (opti	ical) in vacuum	
11	Furnace	failure at 216	oOC (opti	cal) in vacuum	

TABLE 38 (CONT)

SUMMARY OF THERMAL SCREENING

Run No. *	Temp C (optical)	Time-min	Atm	Specimen	Remarks
12	2300 (color)	15	Argon	102A D0289 103A D0324 105A D0590 107 D0589 1105 D0352 1105 D0538 1V05 D0410 V02A D0372 V03A D0480 V07 D0580K V11107 D0592 X1102A D0561	Very large ZrB ₂ grains Pheripheral change
13	2200 (color)	15	Argon	VIII02A D0498 X07 D0596	Peripheral change Second phase melting
14	2200	15	Argon	107 D0589	Orange phase

Runs No. 13 and 14 were carried out in the oxidation furnaces in flowing argon. Temperatures were determined by a two-color pyrometer.

TABLE 39
MELTING POINTS OF HOT PRESSED STRUCTURES

	Melting Temperature - °C			
Material	Incipient	Complete		
I02A 0289	2630	3095		
I03A 0324	2568	3075		
Norton ZrB*	2945	3017		
Carborundum ZrB ₂	2600	3085		
1105 0315	3235	3344		
П06 0383	2697	3085		

^{*}Heavy outgassing at 2540°C.

TABLE 40
BEND STRENGTH AS A FUNCTION OF TEMPERATURE

- B. 4	W 4-41 50 - 14	h, 10 ³ psi,	0 ³ psi, at		
Material Designation	Relative Density Grain Intercept μ	<u>23°C</u>	800°C	1400°C	1800°C
102A D0305	99.3 35 FEM	42.3* 55.8* 51.9	72.0* 64.2 68.6	21.5 25.5* 27.3*	19.0 N.B. 26.2 29.1 N.B.
102A D0326	99 . 9 40	38.5 36.5 38.5	56.6** 56.9 47.8	27.5 25.4 29.9	21.1 N.B. 20.8 N.B. 20.2 S.B.
102A D0345	99.2 21 FEM	50.1* 34.9 47.7**	49.4* 52.6** 65.3	30.8 32.0* 33.3	27.4 N 24.0 N.B. 29.5*N.B.
103A D0314	99.6 8	46.2 42.3* 48.1	77.8 59.7 57.8	39.7* 39.5	25.5 [*] S.B. 26.8 [*] B 29.2 [*] B
102A D0338	97.6 33	49.0 47.8** 40.7*	54.3 58.7 46.1	26.8 26.6 23.0	24.2 S.B. 28.3 S.B. 37.2
102A D0291	95.9 27	44.2* 50.0* 58.6	54.2** 49.2 40.9	17.8 17.6	13.6 N.B. 13.5 N.B. 17.5 S.B.
103A D0360	95.6 11	59.7 39.0* 51.7**	36.5 56.4* 70.2	35.8 34.9	29.8 [*] S.B. 32.3 [*] S.B. 18.7 [*] B
103A D0328	89.1 6	30.8 40.4 46.2	67.8 55.3** 58.0*	33, 2 26, 3	33.3 B 28.4 S.B. 31.5 B
102A D0343	90.0 6	40.3 25.3 28.2			26.9 28.0.5.B. 28.2 B
105A D0590	97 38	38.2* 39.2 82.9*	42.8* 49.0* 42.6*	18.4 16.1 15.3	15.0 N.B. 16.8 N.B. 17.2 N.B.

TABLE 40 (CONT)
BEND STRENGTH AS A FUNCTION OF TEMPERATURE

Material	Relative Density	В	end Strength	, 10 ³ psi, a	<u>t</u>
Designation	Grain Intercept	23°C	800°C	1400°C	1800°C
1105 D0348	99.4 34	41.4** 36.7 45.9			9.8*S.B. 10.2*B 9.0 N.B.
1105 D0352	96.7 15 FEM	55.7** 63.8** 52.0	65.9** 58.4 53.2	16.9 14.5 14.2	21.3.S.B. 29.0*S.B. 28.3*N.B.
H05 D0349	90 11	47.5** 44.7** 50.5**			21.3 N.B. 25.8 S.B. 23.0 N.B.
1106 D0379	96.7 5	56.9** 44.8* 50.3**		15.1	23.3 B 25.8*S.B. 27.4*B
III(10)05 D0538	98.9 9	68.7** 60.9* 63.5*			26.8*B 28.1.B 24.8*B
11105 D0386	99.7 9	54.9** 56.9** 59.2		38.6* 39.0* 38.0*	35.7*S.B. 41.9*S.B. 42.4*S.B.
11105 D0400	95 . 3 9	44.3 47.4** 55.3**	45.6 46.1** 55.9**	42.0 46.7 45.0*	42.0*S.B. 53.7 S.B. 48.1 S.B.
11105 D0444	91.6 6	41.7 37.3** 39.9		39.5* 56.6* 28.9	26.8*B 32.2 S.B. 37.3 S.B.
11105 D0402	84.3 6	29.9* 22.2 29.9**		25.8 22.7 23.1	27.9*B 30.0*B 28.0*B
IV05 D0410	99.4	50.4 48.6** 49.0	50.9** 54.9 61.3*	61.7* 61.9 _* 56.4	44.9*S.B. 58.9*S.B. 59.6*N.B.

TABLE 40 (CONT) BEND STRENGTH AS A FUNCTION OF TEMPERATURE

Material Designation	Relative Density Grain Intercept µ	23°C Bend Streng	th, 10 ³ psi at 1400°C	1800°C
IV05 D0449	90.2 7	41.i** 38.1 34.5*	43.0* 34.1*	20.5 [*] B 30.9 [*] S.B. 40.3 [*] S.B.
V02A D0371	100 8	50.5 52.7 50.0* 50.6 50.0 55.0	43.0 42.0 39.2	38.2*B 44.9 B 41.0 B
V02A D0395	95.5 7	51.2** 51.5 51.4 52.2 46.8 51.2 48.2 55.6 45.5	24.3*	34.7*B 32.0 B 39.3 B
V02A D0391	90.1 7 FEM	39.7* 48.2** 69.2**		25.5*B 34.9 B 30.4 B
V03A D0480	100	39.3** 46.3 38.1* 48.4 36.4 34.9	41.3* 48.1 48.2**	43.8*B 35.0*S.B. 40.5*B
V(10)02 D0532	100 11	68.7** 60.9* 63.5*		42.5 B 38.6 B 42.5 B
V(35)02 D0541	100 6	71.8** 62.7** 71.1		44.9*B 43.3 S.B. 43.8 B
VI05 D0461	91.2 8	55.1* 38.2** 38.5		42.2**S.B. 34.3* N.B. 34.8* N.B.
VIII02 D0498		41.2 43.3* 37.8		47.8 B 48.1 B 45.5***B
XII(20)07 D058	35 100 4.8	69.4 63.4		18.1* B 21.9* B 25.5* B

^{*}Single fracture at one knife edge. **Primary fracture within gage length and secondary fracture at one knife edge

resulting in three sections.

NB = no bending.

SB = slight plastic bending <<1%.

B = plastic bending of <1%.

TABLE 41 PHASE II BEND STRENGTH AS A FUNCTION OF TEMPERATURE

		Bend Strength	ı, 10 ³ psi at
Material Designation	Relative Density Grain Intercept	23°C	1800°C
103A D0619K	100	52.0**	20.8 [*] S.B.
	18.4	36.1	22.8 S.B.
		49.3	25.5* S.B.
V07 D0580K	100	57.6*	37. 1* B
	7.0	48.2	38.3 B
			35.2 [*] B

^{*} Single fracture at one knife edge.

** Primary fracture within gage length and secondary fracture at one knife edge resulting in three sections.

S.B. Slight plastic bending <<1%.

Plastic bending <1%.

TABLE 42 BEND STRENGTH[†] VERSUS TEST TEMPERATURE FOR TWO COMMERCIAL LOTS OF HOT PRESSED ZIRCONIUM DIBORIDE

Test Temperature	Loading System++	Norton ZrB2* Bend Strength	Carborundum ZrB ₂ ** Bend Strength
°c		10 ³ psi	10 ³ psi
- 196	3-point	35.8	48.5
23	3-point	33.0	43.3
700	3-point	27.7	
1000	3-point	25.0	38.2
1200	3-point	21.8	35.0
1400	3-point	22.3	17.0
	4-point	16.2	17.2
1800	4-point	4.7	15.6

*Norton ZrB2, 89% dense, 18µ grain intercept, ZrC X-ray second phase (calc. to be 9.0 w/o from chemical analysis), 3.0 w/o metallic impurities (principally Cr, Fe, Al).

**Carborundum ZrB2, 95% dense, 16µ grain intercept, ZrO2 X-ray phase (calc. to be 3.8 w/o from chemical analysis), low in metallic impurities.

^{*}Reported strengths are averages of from 3 to 11 tests per temperature. ++3-point tests performed at ManLabs, 4-point tests performed at Avco.

TABLE 43
BEND STRENGTHS OF PREOXIDIZED COMMERCIAL
HOT PRESSED ZIRCONIUM DIBORIDE

Material	Test Temperature	Unoxidized Matrix	Pre-oxidized Matrix	Matrix + Oxide
	°C	10 ³ psi	10 ³ psi	10 ³ psi
Norton ZrB2	23	27-49	40.7	24.6
_	1000	19-31	28.0	14.4
Carborundum ZrB ₂	23	30-55	38.0	23.4
	1000	25-55	62 6	38.6
	1000	25-55	55.3	36.1

TABLE 44

EFFECT OF SURFACE FINISH ON BEND STRENGTH OF
BILLET V07 D0576K AT 23°C

Surface Preparation Grit Size	220	400	5 0 0	1/4µ diamond
Surface Finish Center Line Average Deviation, Microinches	13	7.5	10	0.3
Strength Values, 10 ³ psi	64.7** 76.5** 58.7** 51.3* 45.1* 69.4	68.3 43.0 71.6 67.9 64.5 64.1	62.0** 62.6** 69.2** 66.8 66.4**	69.9** 72.7** 47.8 60.3 73.8* 76.4
Mean Strength, 10 ³ psi	60.9	63.2	65.9	66.8
Standard Deviation, 10 ³ psi	11.6	10.3	2.9	10.8

^{*}Single fracture at one knife edge.

Primary fracture within gage length and secondary fracture at one knife edge resulting in three sections.

TABLE 45

DYNAMIC ELASTIC MODULUS MEASUREMENTS

Material Designation	Dens	ity	Compressional Pulse Velocity	Transverse Pulse Velocity V T	Poisson Ratio	Young s Modulus E
	gm/cc	%	10 ⁵ cm/sec	10 ⁵ cm/sec		10 ⁶ psi
103A D0313	5.99	99.4	9.30	5.85	0.17	70.5
1105 D0353	10.52	99.2	6.93	4.58	0.12	71.0
1105 D0355B	10.46	98.6	7.02	4.35	0.19	68.5
III 05 D0385	9.25	100	7.47	4.79	0.15	70.5
11105 D0426	9.06	98	7.25	4.78	0.12	67.2
IV05 D0405	9. 4 5	100	7.35	5.03	0.06	73.0
V02A D0387	5.45	100	9.90	5.75	0.24	66.0

TABLE 46

ELASTIC MODULUS AS A FUNCTION OF TEMPERATURE

E at 1400°C* Static 10°psi						37.6	58.5		37.6		31.4
E at 800°C* Static 10°psi			9.19			54.7	711.7	78.0	55.1		35.8
E at 23°C* Dynamic 10°psi								_ເ			
E at 23°C Static Static 10° pei		75.7							53,7		34,8
E at 23°C Static 10°psi	65.7	57,7 59.6 65.6	68.7	61.8	55,4 40,4		63.3	71.0	55. 4.1	8.63	29.5 32.4
Relative Density Grain Intercept	99.0	99.6	100 23	90.1	86.2 8	100	100 8	94.1	90.1	100	100 5
Material Designation	102A D0345F	103 A D0314F	I03A D0457	103A D0343	103A D0323	V03A D0480	V02A D0371	V02A D0395	V03A D0391F	V(10)02A D0532	VIII02 D0498

TABLE 46 (CONT)

ELASTIC MODULUS AS A FUNCTION OF TEMPERATURE

	Material Designation	Relative Density Grain Intercept	E at 23°C. Static 10°psi	E at 23°C Static 10°psi	E at 23°C* Dynamic 10°psi	E at 800°C* Static 10 ⁵ psi	E at 1400°C Static
	HO5 D0348 HO5 D0349	99.4 34. 90.0	69.1 70.4 44.1 45.9	8.9	16.1	62.7	
27	11105 D0386 11105 D0444	99.7 9 91.6	68.6 69.1 48.5	79.6	72.1	75.9 75.0 50.3	6.1.0
00	III(10)02A D0532 IV05 D0410	-	69.8 75.9	74.2	72. i	72.3	69.0
	IV05 D0449	90.0	48.1 44.3 45.1	48.3	ч		

* Performed at AVCO.

TABLE 47 STATIC AND DYNAMIC MODULUS VALUES FOR HOT PRESSED ${\tt ZrB}_2$

Material	Relative Density	Method	Young ts Modulus (E) 10 ⁶ psi
(13)	87	dynamic	51.9
Norton	89	static	54. 5
(13)	95	dynamic	63.8
Carborundum	95	static	65.4
(13)	98	dynamic	73.5

TABLE 48

COMPARISON OF POST - 1800°C - TEST FRACTURE CRAIN SIZE

WITH AS-HOT PRESSED GRAIN SIZE

Material Designation	As-Hot Pressed Grain Intercept	Post - 1800°C - Test Grain Intercept
	μ	μ
102A D0291	27	36
102A D0338	30	27
1105 D0348	34	36
H05 D0349	11	14
щ05 р0400	9	7
11105 D0402	6	9
11105 D0386	9	12
IV05 D0410	6	9
IV05 D0449	7	7
V02A D0371	8	8
V02 D0391	7	7

TABLE 49

DENSITY MEASUREMENTS ON BEND SPECIMENS
TESTED AT 23°C

Material Designation	Original Billet Density	Specimen Density Displacement Method	Specimen Density Geometrical Method
	gm/cm ³	gm/cm ³	gm/cm ³
102A D0305	5.99	5.94	5.94
102A D0345	5.97	6.04	5.93
103A D0314	6.00	6.06	5.96
11105 D0348	10.48	10.68	10.53
11105 D0386	9.26	9.17	9.08
IV05 D0410	8.57	8.60	8.43
V02A D0371	5.49	5.59	5.48

TABLE 50

AIR FLOW RATE DEPENDENCE FOR MATERIAL III

(HfB₂ - 20 v/o SiC at 2120°C, 60 Minutes)

(Billet III05D0573, 0.35 in. diameter by 0.35 in. high)

				sion
Air Flow Rate ft/sec	Height/ <u>Diameter</u> mils/mils	Average mils	Height/ Diameter mils/mils	Average mils
0.1 0.3 0.3 0.5 0.5 0.7 0.7 0.9	0/0 9.0/9.4 8.7/9.7 8.3/8.7 7.3/9.7 8.7/10.0 6.1/7.2 6.1/10.0 7.3/11.1	0 9.2 9.2 8.5 8.5 9.4 6.7 8.1 9.2	3.2/ 4.2 103.7/107.2 94.5/108.5 99.5/ 99.2 118.2/103.0 108.6/101.5 101.8/ 94.1 87.0/ 94.0 98.4/ 91.9 100.1/ 96.6	3.7 105.5 101.5 99.4 110.6 105.1 98.0 90.5 95.2 98.4
	ft/sec 0.1 0.3 0.3 0.5 0.7 0.7	Flow Rate Diameter ft/sec mils/mils 0.1 0/0 0.3 9.0/9.4 0.3 8.7/9.7 0.5 8.3/8.7 0.5 7.3/9.7 0.7 8.7/10.0 0.7 6.1/7.2 0.9 6.1/10.0 7.3/11.1 1.8 9.4/11.1 9.4/11.1	Flow Rate Diameter mils Average mils ft/sec mils/mils mils 0.1 0/0 0 0.3 9.0/9.4 9.2 0.5 8.7/9.7 9.2 0.5 7.3/9.7 8.5 0.7 8.7/10.0 9.4 0.7 6.1/7.2 6.7 0.9 6.1/10.0 8.1 0.9 7.3/11.1 9.2 1.8 9.4/11.1 10.3	Flow Rate Diameter Average Diameter ft/sec mils/mils mils mils/mils 0.1 0/0 0 3.2/4.2 0.3 9.0/9.4 9.2 103.7/107.2 0.3 8.7/9.7 9.2 94.5/108.5 0.5 8.3/8.7 8.5 99.5/99.2 0.5 7.3/9.7 8.5 118.2/103.0 0.7 8.7/10.0 9.4 108.6/101.5 0.7 6.1/7.2 6.7 101.8/94.1 0.9 6.1/10.0 8.1 87.0/94.0 0.9 7.3/11.1 9.2 98.4/91.9 1.8 9.4/11.1 10.3 100.1/96.6

TABLE 51

OXIDATION SCREENING: MATERIAL I (ZrB₂)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

				Height/	Jiameter	
Exp. No.	Pressing No.	Temp	Time	Initial*	Boride Recession	Average One Hour Boride Recession
		°c	min	mils/mils	mils/mils	mils
440	102AD0338	1550	60	300/350	12.1/14.2	13.2
259	102AD0326	1550	60	290/350	8.0/8.3	8.2
560	I03AD0309	1600	60	300/350	9.9/10.6	10.3
561	I03AD0309	1660	60	300/350	10.3/11.3	10.8
796	102AD0343	1690	60	250/350	13.5/13.7	13.6
212	I02AD0281	1700	60	290/350	11.9/16.5	14. 2
229	I03AD0340	1700	60	300/350	11.9/13.9	12.9
230	I03AD0340	1700	60	300/350	13.7/13.4	13.6
23.	I03AD0340	1700	60	300/350	13.2/15.2	14.2
255	I03AD0309	1700	60	300/350	11.4/10.9	11.2
263	102AD0291	1700	60	280/350	11.7/15.0	13.4
265	102AD0326	1700	60	290/350	12.4/14.4	13.4
274	103AD0328	1700	60	285/350	/11.6	11.6
285	102AD0338	1700	60	300/350	13.6/14.4	14.0
286	103AD0314	1700	60	300/350	11.6/14.4	13.0
287	103AD0360	1700	60	270/350	13.7/17.8	15.8
295	102AD0345	1700	60	300/350	12.1/13.9	13.0
304	103AD0328	1700	60	265/350	/12.2	12.2
894	107D0589	1700	60	300/350	12.6/13.1	12.9
899	105AD0590	1700	60	300/350	12.5/12.9	12.7
1016	105AD0590	1740	60	300/350	13.6/14.3	14.0
1018	103AD0457	1740	60	420/350	13.3/14.6	14.0
1014	I03AD0457	1770	60	420/350	17.5/17.4	17.4
1017	107D0589	1770	60	300/350	15.4/16.4	15.9
1019	102AD0305	1770	60	290/350	14.9/16.1	15.5
1020	105AD0590	1770	60	300/350	17.1/17.4	17.3
308	103AD0360	1800	60	270/350	23.4/22.4	22.9
211	I03AD0314	1800	60	300/350	21.6/20.6	21. 1
312	I02AD0338	1800	60	300/350	27.8/21.4	24.6
787	I02AD9343	1800	60	290/350	28.0/32.3	30.2
309	103AD0309	1810	60	300/350	25.0/27.1	26. 1
314	102AD0326	1810	60	285/355	16.3/22.2	19.3
316	I03AD0328	1810	60	270/350	17.7/17.4	17.6
318	102AD0291	1810	60	300/350	21.3/22.3	21.8
335	102AD0345	1810	60	300/350	19.4/20.7	20.0
895	107D0589	1810	60	300/350	33.8/36.4	35.1
901	105AD0590	1810	60	300/350	31.5/36.5	34.0
955	I02AD0343	1820	60	290/350	34.9/43.7	39.3

TABLE 51 (CONT)

OXIDATION SCREENING: MATERIAL I (Z. B.)

(152 Torr O2 in Air at 0.9 ft/sec - STP)

				11018111	74411000	
Exp. No.	Pressing No.	Temp	Time	<u>Initial*</u>	Boride Recession	Average One Hour Boride Recession
		°C	min	mils/mils	mils/mils	mils
253	I03AD0340	1850	60	300/350	28.1/38.1	33.1
288	I03AD0328	1850	30	300/350	Severe Oxid	ation
332	I03AD0309	1850	30	300/350	31.8/44.1	(52.9)†
333	I02AD0326	1850	30	290/350	24.7/31.7	$(40.0)^{T}$
497	I02AD0345	1850	30	290/350	23.2/31.8	(38.8)4
504	I02AD0338	1850	30	300/350	41.0/52.8	(67.0)+
513	I03AD0360	1850	30	270/350	16.4/22.0	(25.8)+
864	103AD0457	1850	60	420/350	41.5/48.2	44.9
786	102AD0343	1850	30	290/350	34.5/42.5	(54.9)
897	I05AD0590	1850	30	300/350	29.8/39.8	(49.2)+
896	I07D0589	1860	30	300/350	29.6/37.6	(47.5) ⁺
473	102AD0291	1860	30	280/350	29.5/46.6	(5 4. 0)†
503	I03AD0360	1860	26	270/350	15.2/16.7	(24.3)
419	103AD0360	1870	30	270/350	43.6/50.2	(66.4)
420	I03AD0314	1870	30	300/350	29.5/46.6	(54.0)
512	102AD0338	1890	30	300/350	37.3/	(52.7) ⁺

^{*}Nominal dimensions.

⁺Assumes parabolic oxidation kinetics.

TABLE 52

OXIDATION OF COMMERCIAL HOT PRESSED

ZIRCONIUM DIBORIDE

(152 Torr O2 in Air at 0.9 ft/sec - STP)

Exp. No.	Temp	Time	Initial*	Recession E	verage One Hour Soride Recession
	°C	min	mils/mils	mils/mils	mils
Carborundu	ım Hot Pr	essed			
558	1540	60	400/375	11.6/15.5	13.6
638	1580	60	400/375	10.0/10.8	10.4
88	16 10	60	400/375	14.7/21.0	17.9
155	1630	60	400/350	10.4/15.8	13, 1
129	1690	60	4 00/350	13.0/13.5	13.3
266	1700	60	400/350	12.1/12.3	12.2
89	1730	60	400/375	16.3/26.5	21.4
130	1780	60	400/350	14.4/14.3	14. 4
156	1810	60	4 00/350	21.4/20.9	21.2
317	1810	60	4 00/350	21.3/22.3	21.8
90	1820	60	4 00/375	23.0/30.5	26.8
131	1850	30	400/350	27.4/30.0	(4 0.2) ⁺
474	1860	60	400/350	36.4/50.5	43.5
486	1860	30	400/350	16.5/26.5	(30.5)
107	1870	30	400/375	38.6/47.5	(74.6) +
157	1900	30	400/350	36.6/D	(51.8)4
120	1920	60	400/375	Complete Oxidat	ion
124	1940	30	400/375	47.9/D	(67.7) ⁺
121	1970	60	400/375	Complete Oxidat	
93	1980	30	400/375	Complete Oxidat	
92	1990	30	400/375	Complete Oxidat	ion
Norton Hot	Pressed				
639	1580	60	400/390	17.5/13.5	15.5
113	1620	60	410/390	15.1/13.1	14.1
128	1620	60	4 00/350	13.4/15.3	14.4
267	1700	60	400/400	32.0/ 44 .2	38. 1
272	1700	60	400/400	21.5/21.8	21.7
475	1700	60	400/400	26.6/24.5	25.6
114	1710	60	390/340	26.3/24.3	25.3
105	1820	60	400/350	30.8/31.1	31.0
132	1820	60	400/350	43.1/41.8	42.5
421	1840	60	400/400	27.6/43.0	35.3
487	1860	30	400/400	30.9/32.7	(45.0) ⁺
123	1870	60	400/350	50.2/D	50, 2
159	1900	30	400/350	Complete Oxidat	
112	1920	60	400/340	Complete Oxidat	
115	1960	30	400/350	Complete Oxidat	
106	2040	60	400/340	Complete Oxidat	ion

^{*}Nominal dimensions.

[†]Assumes parabolic oxidation kinetics.

TABLE 53

OXIDATION SCREENING: MATERIAL V (Z-B₂ + 20 v/o SiC)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

				Height/I	Diameter	Average One Hour
					Boride	Boride
	Pressing			*	Recession 4	Recession
Exp. No.	No.	Temp	Time	Initial*	(SiC Recession)	(SiC Recession)
		°C	min	mils/mils	mils/mils	mils
388	V02AD0395	1800	60	300/350	1.1/0.6	0.9
441	V02AD0371	1800	60	300/350	(29.2/ 9.6) 4.2/ 2.8	(19.4) 3.5
330	V02D0372	1800	60	295/350	(/7.2) $1.2/1.3$	(7.2) 1.2
389	V02AD0391	1810	60	300/350	(5.0/) 1.8/ 1.5	(5.0)
918	V07D0580K	1810	60	330/350	(14.8/11.7) 4.3/3.3	(13.5) 3.8
631	V03AD0480	1840	60	350/350	(16.6/14.3) 1.7/2.5	(15.5) 2.1
433	V02AD0371	1900	60	300/350	(7.3/9.3) 7.0/6.2	(8.3) 6.7
432	V02AD0395	1900	60	300/350	(19.0/25.2) 4.2/6.7	(22.1) 5.5
430	V02AD0391	1910	60	300/350	(32.3/61.9) 8.4/4.6	(47.1) 6.5
391	V02AD0391	1950	60	300/350	(67.6/34.8) 6.4/6.5	(51.1) 6.4
437	V02AD0371	1950	60	300/350	(67.1/31.9) 9.7/11.6	(49.5) 10.7
343	V02D0572	1960	60	295/350	(30.3/41.7) 13.4/18.3	(36.0) 15.9
393	V02AD0395	1960	60	300/350	(35.8/31.9) 4.5/5.2	(33.9) 4.9
435	V02D0372	1960	120	300/350	(76.6/94.8) 16.1/15.7	(86.2) 11.2 ⁺⁺
436	V02D0372	1960	30	300/350	(39.3/44.7) 10.1/9.2	(29.7)** 13.7**
438	V02D0372	1960	60	300/350	(18.6/30.8) 9.9/12.7	(34.9)++
903	V07D0580K	1970	60	330/350	(22.0/34.9) 16.8/9.0	(28.5) 12.9
634	V03AD0480	2000	60	350/350	(34.3/23.3) 3.4/ 2.7 (111.9/93.5)	(28.8) 3.1 (102.7)

TABLE 53 (CONT)

OXIDATION SCREENING: MATERIAL V (ZrB₂ + 20 v/o SiC) (152 Torr O₂ in Air at 0.9 ft/sec - STP)

				Height/	Diameter	Average
Exp. No.	Pressing No.	Temp	Time	Initial*	Boride Recession (SiC Recession)	One Hour Boride Recession (SiC Recession)
		°C	min	mils/mils	mils/mils	mils
470	V02AD0371	20 10	60	300/350	20.6/	20.6
471	V02AD0391	2010	60	300/350	(73.6/) 21.6/	(73.6) 21.6
472	V02AD0395	2010	60	300/350	(C/) 7.8/	(C) 20.6
	·			-	(C/)	(C)
398	V02AD0391	2050	60	300/350	56.2/74.5 (C/C)	65,4 (C)
399	V02AD0395	2060	60	300/350	75.5/65.8	70.7
352	V02D0372	2060	60	295/350	(C/C) 22.8/26.4	(C) 24.6
467	V02AD0371	2110	60	300/350	(C/C) 28.2/	(C) 28,2
	•			·	(127.7/)	(127.7)
913	V07D0580K	2130	60	330/350	83.0/121.0	102.0
635	V03AD0480	2170	60	350/350	(C/C) 24.3/47.5	(C) 35.9
906	V07D0580K	2220	60	330/350	(C/C) Complete Oxid	(C)

^{*}Nominal dimensions.

⁺C designates complete oxidation of the SiC phase.

⁺⁺Assumes parabolic oxidation kinetics for the diboride and SiC phases.

TABLE 54

OXIDATION OF COMMERCIAL HOT PRESSED BORIDE Z

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

Exp. No.	Temp	Time	Initial* mils/mils	Material Recession mils/mils	Average One Hour Material Recession mils
636	1570	60	300/350	3.6/ 2.8	3.2
444	1710	60	300/350	6.3/6.7	6.5
445	1810	60	300/350	12.6/12.3	12,5
508	1850	60	300/350	15.9/15.8	17.5
530	1910	60	300/350	16.4/16.8	16.6
531	1950	60	300/350	30.3/39.8	35.1

^{*}Nominal dimensions.

TABLE 55

OXIDATION SCREENING: MATERIAL VIII (ZrB₂ + 30 v/o Graphite + 14 v/o SiC)

(152 Torr O₂ in Air at 0.9 ft/sec - STF)

				Height/	Diameter	Average One Hour	
Exp. No.	Pressing No.	Temp	Time	Initial*	Boride Recession (SiC Recession)	Boride Recession (SiC Recession)	
		°C	min	mils/mils	mils/mils	mils	
1021	VIII02A D0592	16 10	60	290/350	8.3/ 9.5	8.9	
1022	VIII02A D0592	1770	60	290/350	15.6/ 19.2	17.4	
					(20.2/22.4)	(21.3)	
916	VIII02A D0592	1800	60	290/350	21.0/ 33.3	27.2	
4 5 0			4.5		(28.3/39.1)	(33.7)	
623	VIII02A D0498	1820	60	300/350	3.8/ 11.5)	7.7	
					(15.1/29.0)	(22.1)	
915	VIII02A D0592	1970	60	290/350	64.8/85.0	74.9	
					(75.3/102.2)	(88.8)	
627	VIII02A D0498	1980	60	300/350	20.8/ 6.2	13.5	
					(34.1/48.5)	(41.3)	
912	VIII02A D0592	2000	60	290/350	Complete Oxi		
624	VIII02A D0498	2180	60	300/350	Complete Oxi	dation	

^{*}Nominal dimensions.

TABLE 56

OMIDATION SCREENING: MATERIAL MI (ZrB₂ + 50 v/o Graphito)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

Exp. No.	Pressing No.	Temp	Time	Initial*	Boride Recession	Average One Hour Boride Recession
		°C	min	mils/mils	mils/mils	mils
953	XII02AD0561	1600	60	290/350	41.9/ 70.3	56.1
954	XII02AD0561	1710	60	290/350	Complete O	xidation
844	XII02AD0561	1800	60	300/350	99.3/122.3	110.8
946	XII(20)07D0585	1810	60	340/350	29.0/ 29.6	29.3
947	XII(5)03AD0572	1810	60	330/350	33.6/ 39.8	36.7
843	XII02AD0561	1850	60	300/350	109.8/125.2	117.5
951	XII(5)03AD0572	1860	30	330/350	35.0/ 37.4	51.2 ⁺
950	XII(20)07D0585	1860	30	340/350	26.2/30.7	40.2+
949	XII(5)03AD0572	1910	60	330/350	Complete C	xidation
948	XII(20)07D0585	1910	60	340/350	79.07 76.8	77.9
845	XII02AD0561	1980	60	300/350	110.1/132.3	121.2

^{*}Nominal dimensions.

⁺Assumes parabolic oxidation kinetics.

TABLE 57

OXIDATION SCREENING: MATERIAL X (ZrB₂+20 v/o SiB₆)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

Exp. No.	Pressing No.	Temp °C	Time min	Initial* mils/mils	Material Recession mils/mils	Average One Hour Material Recession mils
925 923 922	X07D0596 X07D0596 X07D0596	1700 1800 1910	60 60	300/330 300/350 300/350	17.2/14.2 21.6/29.6 Complete C	15.7 25.6 Oxidation

^{*}Nominal dimensions.

TABLE 58 OXIDATION: HIGH PRESSURE HOT PRESSED MATERIALS (152 Torr O2 in Air at 0.9 ft/sec - STP)

		Height/Diameter							
Exp. No.	Pressing No.	Temp °C	Time	Initial*	Material Recession mils/mils	Average One Hour Material Recession mils			
		C	min	mils/mils	mits/mits	1111112			
Material VI (HfB ₂ + 4 v/o Hf-27Ta)									
599	VI05H0585	1820	60	380/310	17.8/23.4	20.6			
606 608	VI05H0586 VI05H0585	1920 2060	60 60	380/330 360/310	28.9/45.8 85.9/81.8	37.3 83.9			
000	1203220303		•	200,010	200,, 200				
Material X	(ZrB ₂ + 20 v/	o SiB ₆)							
733	X02AH0649	1810	60	330/330	12.1/17.9	15.0			
77.0	X02AH0648	1910	60	350/330	12.1/17.9 33.6/33.5) 51.7/50.9	15.0 (33.6) ⁺ 51.3			
738	O#OUMASUA	1910	00	3507330	112.9/95.9)	$(104.4)^{+}$			
				·					
Material X	1 (ZrB ₂ + 8 v/c	Cr)							
72 7	X102AH0645	1700	60	350/350	18.4/34.3	26.4			
598	XI02AH0583	1710	60	260/340	25. 1/	25. 1			
731	XI02AH0645	1810	60		38.8/43.6	41.2			
729	XI02AH0645	1870	30	360/310	82,2/61.4	101.5++			

^{*}Nominal dimensions.

[†]SiB₆ recession.
††Assumes parabolic oxidation kinetics.

TABLE 59

OXIDATION SCREENING: MATERIAL II (HfB₂)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

Exp. No.	Pressing No.	Temp °C	Time min	Initial* mils/mils	Boride Recession mils/mils	Average One Hour Boride Recession mils
382	H05D0352	1600	60-60	260/350	7.6/ 6.8	(5,1)
401	H05D0352	1600	120	260/350	4.9/ 5.1	(3.5)+
349	H05D0352	1700	60	260/350	5.2/4.7	5.0
351	1105D0348	1700	60	265/350	4.0/5.5	4.8
348	H05D0349	1700	35	280/350	3.7/4.5	(5.4)+
360	II05D0349	1710	60	280/350	6.4/5.7	6.1
327	II06D0383	1800	60	300/ 350	/10.9	10.9
363	1105D0349	1800	60	280/350	10.2/12.7	11.5
329	1105D0315	1810	60	300/350	10.7/11.0	10.9
366	II05D0352	1810	60	260/350	11.7/12.2	12.0
321	II07D0458	1810	60	300/350	11.6/11.5	11.6
36 1	II05D0348	1810	60	265/350	18.9/19.3	19.1
350	H05D0315	1880	48	300/350	54.9/57.5	(63.0)+
367	H05D0348	1900	60	265/350	44.1/45.4	44.8
369	1105D0349	1900	60	280/350	40.4/36.6	38.5
375	1105D0352	1900	45	260/350	33.1/33.9	(38.7) ⁺
455	H06D0383	1900	60	300/350	28.9/35.2	32.0
456	H05D0315	1900	6 0	300/350	17.5/26.3	21.9
465	H07D0458	1910	60	300/350	23.2/26.4	24.8
4290	1105D0348	1990	60	265/350	31.4/29.8	30.6
428	H05D0349	2 02 0	60	280/350	62.4/81.3	71.9
507	H06D0383	2020	60	300/350	74.6/86.6	80.6
338	1105D0315	2030	60	300/350	67.2/85.8	76.5
386 ⁰⁰	II05D0348	2030	60	265/350	30.0/24.9	27.5
510	1107D0458	2060	60	300/350	54.4/71.6	63.0

^{*}Nominal dimensions.

^{*}Assumes parabolic oxidation kinetics.

OAir flow 0.5 ft/sec.

OOAir flow 0.2 ft/sec.

TABLE 60

OXIDATION SCREENING: MATERIAL III (HfB₂ + 20 v/o SiC)

(152 Torr O₂ in Air at 0.9 ft/sec - STP)

				Heigh	Average One Hour	
					Boride	Boride
	Pressing			44	Recession _	Recession
Exp. No.	No.	Temp	Time	Initial	(SiC Recession)	(SiC Recession)
		°C	min	mils/mils	mils/mils	mils
496	11105D0386	1790	60	260/350	1.1/0.7	0.9
492	III05D0444	1800	60	300/350	(3.9/ 4.1) 0.6/ 0.6	(4.0) 0.6
493	11105D0400	1800	60	200/350	(3.9/ 4.5) 0.7/ 0.4	(4.2) 0.6
494	III05D0402	1800	60	350/350	(3.2/ 3.8) 1.5/ 1.0	(3.5)
340	H105D0408	1800	60	300/350	(4.2/ 5.0) 0.9/ 1.0	(4.6)
426	III05D0408	1910	120	300/350	(3.7/) 2.3/8.8	(3.7) 4.0 ⁺ +
498	III05D0402	1950	60	350/350	(12.1/19.1) $6.4/4.2$	(11.0)** 5.3
387	11105D0400	1960	60	300/350	(68.9/44.6) 2.3/4.7	(56.8) 3.8
396	11105D0386	1960	60	260/350	(34.8/34.0) 3.6/3.5	(44.2) 3.6
425	11105D0408	1960	30	300/350	$ \begin{array}{c} (32,0/27.0) \\ 4.7/5.7 \\ (32.5/20.2) \end{array} $	(29, 5) 7, 4 ⁺⁺
427	11105D0408	1970	60	300/350	(29.5/30.9) 2.0/6.0	(42.7) ⁺⁺ 4.0
442	11105D0444	1980	60	300/350	(17.3/23.5) 2.7/3.1	(20.4) 2.9
464	11105D0408	2020	60	300/350	(27.5/39.6) 4.7/ 7.7	(33.6) 6.2
384	11105D0408	2050	60	300/350	(24.6/31.3) 2.7/3.5	(28.0)
500	ш05D0402	2060	60	350/350	(C/C) 2,3/5.8	(C) 4.1
525	11105D0400	2100	60	300/350	(12.8/28.2) 10.3/13.8	(20.5)
524	11105100444	2110	60	300/350	(C/C) 15.8/26.6 (C/C)	(C) 21.2 (C)

^{*}Nominal dimensions.

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⁺C designates complete oxidation of the SiC phase.

⁺⁺ Assumes parabolic oxidation kinetics for the diboride and SiC phases.

TABLE +1

OXIDATION SCREENING: MATERIAL IV (HIB₂ + 30 v/c Sc)

(152 Torr U₂ in Air at 0,9 ft sec - STP)

				Hengi	or/Deameter	Average One Hour
Emp. No.	Pressing No.	T+map °C	Time	imetal d	Boride Recession (SiC Recession)	Boride Recession (SiC Recession)
		c	PRIM Th	mule/mule	mis/mis	male
36.0	1V05D0410	1600	6 0	300/350	0.8/ 1.4	1.4
					(/ 7.3)	(7,3)
484	1V05D0449	1800	94	300/350	2.9/ 2.6	2.0
	•				(6.6/ 6.6)	(6.6)
303	1V05D0410	1960	60	300/350	6.8/ 0.8	3.8
			-		(34.7/48.3)	(41.5)
443	1V05D0449	1960	60	300/390	1.4/ 0.6	1.0
44.2	2.0300447	.,,,,	•••	3007 330	(77.0/73.1)	(75.0)
499	1V05D0410	1980	•0	300/350	3.8/ 1.6	2.7
444	140300410	. ••••	-	700/ 370	(53.8/60.3)	(57, 1)
4.5.3	*****	***		300/350	•	
402	1V05D0449	2026	60	300/330	/ 0.4	0.9
					(59.1/39.6)	(44. %)
511	IV 05 D0449	2070	◆ 0	300/350	2.4/ 2.9	2.7
				i	(10.3/C)	(C)
365	IV05D0410	\$100	60	300/350	2.6/ 2.1	Z. 4
				_	(C/C)	(C)
431	1V05D0410	2150	66	30 0/350	8.3/12.8	£0. 🍎
					(C/C)	(C)

Manufact dimensions

^{*}C designates complete exidation of the ScC phase.

TABLE 62
OXID/ TION SCREENING: MATERIAL VI (HIB2 + 6 v o HI-27Ta)

(152 to, r Oz in Air at v + m/sec - SiP)

Lap. No.	Pressung No.	Temp °C	Tirrie	Initial mula	Material Recession male/male	Average One Hour Material Recession mals
434	V165D0462	1760	•0	300/350	10.7/10.6	10.6
36 4	V105Du462	1600	60	500/350	31,8/17.6	24.7
422	V105D0462	1875	60	300/350	23.7/27.5	25.6
376	V105D0462	1960	•0	300/350	50.9/64.8	57.9

Names de mensions

TABLE 63

EFFECT OF SIL CONTENT ON THE CYIDATION BEHAVIOR

OF MATERIALS III AND V

(152 Torr O₂ in Air at 0.9 ft/age \$1P. 60 Minute Engagement)

			Temp	Boride Re	C 4.8 5102	Sic Recession	
OX No. Pressing	v/≎ \$4C	Height/ Diameter		Average	Height/ Diameter	Average	
			°C	male/male	male	maks/mals	mi le
785	11105D0538	10	1800	1,5/ 1.3	2, 2	2.9/ 2.0	3. 1
867	11105D0538	10	1794	3. 1/ 9. 1	6, ì	4.0/10.0	7.0
754	11105D0534	16	1965	7.2/ 6.6	6.5	18.7/19.3	19.0
763	11145D6536	10	2125	15,7/23,3	19.5	70.4/00.5	75.5
764	VezaDo531	9	läüs	12.3/12.9	12.6	C/C	c
763	VOZADOS31	5	1945	33.2/47.5	40.4	c/c	C
762	VOZAĐOSJI	5	2:20	Complete (Des districts		
767	VOZAĐOSIZ	10	1810	9.3/ 9.6	9.4	c/c	ĉ
766	VOZADOS3Z	10	1950	24.2/26.3	25.3	c/c	C
765	SCCOGASOV	10	2105	76.2/96.3	06.3	C/C	Č
770	VOZADO534	15	1405	1.0/ 1.1	1,4	2.6/ 3.8	3. 3
769	PERMITS OF SERV	1.5	1955	14. 1/11.4	12.8	/23.4	23.6
764	V02AD6534	15	2115	Complete (Dandalion		
777	VOZADOŠ34	15	2115	Complete (
773	VOZAĐOS41	35	1405	3.0/ 1.7	2.4	9,2/ 9,1	9,2
772	VOZADOSAL	35	1955	5, 1/ 1,5	3.3	30.6/15.6	29.1
77 1	VGZADG541	35	2105	37.1/29.2	53.2	C/C	C
762	VOLADOSS?	50	1805	4.2/ 2.0	3, 1	6.1/ 7.1	7.6
775	VOZALISSI	50	1955	5.9/	5.9	92.4/	92.4
774	VOZADOS 57	940	2105	Complete (ans abuse		
*13	VOZADOSS7	50	2120	Complete (Deside tree		

Original specimen exmensions are 0.15 is. distanter by 0.25 to 0.33 is. longth.

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^{*}C is used to indicate complete oxidation of the ScC phase.

Es manute exposure, average recessions calculated for 60 manutes assuming parabolic outdition binetics.

?成熟让家一点

SUMMARY OF AVERAGE OXIDE RECESSIONS OF OXIDATION MIREENEW. MATERIALS AND OF SELECTED COMMERCIAL MATERIALS AS A FUNCTION OF TEMPERATURE

		Average	One Hou	ir Oxide	Racesta	one Mul	\$ \$
Material	Ţs	1600°C	1700°C	1800°C	1900°C	20000	2100°C
1(ZrB ₂)		10	13	22	- 100		
Norten ZrB2		14	22	25			
Carborundum Z.B.		14	1.6	26	- 100		
V(ZrB2+20 v/o SiC)				2 (7)	(20)	20 (70)	60 (> 150)
Bonde Z		•	•	12	25	45	
VIII(ZrB_+30 v/o Graphite) +14 5/o SiC}							
s) Regal Graphite				(Sai	(10)	15 (50)	
e) Peco Grapute		(10)	14 (20}	25 (35)	45 (60)	6 0 (110)	
XII(ZrB ₂ +Graphite) a) 90 v/o Poco Graphite b) 20 v/o Poco Graphite c) 5 v/o Thornel Graphite		55	•0	110 28 35	120 70	120	
X(2;82+20 v/o \$484)			14	24			
X1(ZrB ₂ + 6 v/o Cr)			25	40	190		
Li(H±B ₂)		ü	\$	84	20	00	
Ш(НгВ ₂ +20 v/o ScC)				(4)	2 (15)	4 (55)	15 (>150)
1V(HfB ₂ +35 v/o ScC)				2 (6)	5 (05)	(6-0)) (> 150)
VIIHIB,+4 =/+ HI-27 Ta)				15	35	•0	

^{*}Foresthetical numbers are average additive phase recessions, in mile. **Probably anidation is air supply or diffusion limited.

TABLE 65
EXPERIMENTAL VERIFICATION OF PRODUCT RELATION.

Rz = W max /S

<u>Shep</u>	Material	No. of Specimens	(watta/cm)	Retio (ScC/A ¹ 2 ^O 3)
Circle	Al ₂ O ₃	8 6	33.5 ± 0.4 152.0 ± 4.0	4.54 ± 0.13
Square	Al ₂ O ₃	9	28.7 ± 0.4	4.78 ± 0.07 4.78 ± 0 07

SUMMARY OF PRELIMINARY RESULTS OF THERMAL STRESS EVALUATIONS TABLE 66

To start to the st	Failed	No (as) are	No favoure Sample failed while cooling to right temp	Sample fatted in 1 faming a hear section and a hear flux of 14% (si/rin section). Failure occurred hear hear reached	No failure Heat Tun hanged from [4] is 164 callon sec in 1 in	No failure Heat flux changed from 142 to 166 calfra rot in th	front flux thenged from (64 to 192 cal'my sec in 1 in crement No failure
Atmendable sustainer	Vacuum	Veruum	Vecuum	Helium	Vacuum	Helium Helium	Helica
Tent Co	1350	1570	1419	٠ <u>٠</u>	1361	1235	¥1.
Material Factor, R. Calculated Experimented (cal/oec cm)	4 78.4 90	7.95	20.	7. T	05.6	6. 6. 3 . 1 .	. %
Carabios (cal/o	• •	•	;	;	: :	8 6 0 0 0 0	:
Heat Flus (cal/sec cm)	196-124	3-	170 000	<u> </u>	7 9	162	~
7 actor	50 FG 50 FG 50 FG	4	0 0 07	6	2. 2. 0 0	15.0	0.51
Specimen Decignation	## ## ##		10 14 E0 57	25 DE	VET DOSGEK VET DOSGEK	X96500 LOA	Meses ros

TABLE 46 (CONT)

FUNDARY OF PRELIBERARY RESULTS OF THERMAL STREES EVALUATIONS

Spocimen Dystanding	No.	Calles Cin	Material Factor, Ry Calculated Experimental (cal/sec cm)	N. Wall	Atmosphere	
VOT DOST K	• •	0		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	He ii um	Hat flux therged in the formation of the reinest shown for the full his state of the first services each terrement show
				1630		Wa failure
200 DS-03K	 	3 3	05 6	1235	Helium	No failure Heat flas charges from 142 to 144
1164 D593K	o •	261		***************************************	Helium	cellun sec in in croment No failure Heat flux changed from 142 to 166 cellum sec in in

Mage Factor - 8, values are 23.5 for 1.7 tach o 4., 20.0 for 2 0 tach o d circular apecimiens and is for equilateral triangular specimens, all apecimens have 1.0 tach i.d Graphite Cuard Rings - were used f. - all experiments except for Specimen IIOS D595K for which Material V was employed.

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APPENDIX I

CHARACTERIZATION OF DIBOR(TE POWER P. SHIPMER N.E.)

1、1の日本のおりのは、大学のは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、大学のでは、

In admit.2.2 to the large powder procurements of the diborides, which have been described in Section III, several small quantity shipments have been received for evaluation. These powders were characterized by chemical and X-ray analysis and by powder density measurements. The characterization results are presented in Tables I-1 to I-5.

The Zrill, powders 104 and 106 represent small quantity lots. Their chemistries are approximately the same as the 102A powders. Analysis of the 165 powder showed large quantities of metal carbade and outde impurities. The material was reprocessed with a substantial reduction of phase impurities. The characterisation data for the reprocessed powder, identified as 105A, is presented in Table 5.

The Milly powders 1107 and 1108 represent experimental processing lots obtained from the U.S. Sorax Research Corporation. Very migh halmium cande and halmium carbide consents rejected these materials for further consideration. The II06 material, which also has a high level of phase impurities, is being reprocessed.

L

TABLE LI

CHARACTERIZATION OF ZURCONIUM DIBORIDE POWDER, 204

Supplier: U. S. Boran Research Corporation

Quantity: 8,5 pound lot

 Qualitative Analysis (weight per cent, w/o)

T: 0.01 - 0.1

2. Quantitative Applysis (v/e)

Zr 60,1 B 18,55 C 0,11 O 0,76 Total 79,48

3. Atomic Batto

Over-all B/Zr = 1.92 Corrected B/Zr = 2.93 4. X-ray Phase Identification

Zrk₂

Eroz (umpurulyi

5. Powder Deastty

6.00 a/cc

t. Phase Assay (volume per cent)
Calculated from Composition

ZrR_d ZrO₂ ZrC 46.1 3.2 0.7

Alternac ratio corrected for metal assumed to be present as metal desaids and metal mesocarbide.

CHARACTERIZATION OF ZERCONIUM DIBORIDE POWDER, 194

Supplier: Shieldalloy Corporation (H. C. Starck, Berlins

Quantity: 5 pound evaluation enterness

1. Qualitative Analysis (Weight per cent, w/o)

> Hi 0,1 - 1.0 Mo 0,0i - 0,1

2. Quantitative Analysis (w/o)

Zr 80.85 B 15.9 C 0.48 O 1.17 Total 96.40

3. Atomic Ratio

Overmall B/Zr w 1.66 Corrected B/Zr % 1.62 4. X-ray Prace Identification

ZrB₂ ZrC (impurity) ZrO₂ (impurity)

5. Powder Density

6.33 g/cc

Phase Assay (volume per cent)
 Calculated from Composition

2rB₂ 2rO₂ 2rC 91.7 5.0 2.5

e Azemic ratio corrected for metal assumed to be present as metal dictide and metal mesocarbide.

TABLE L.

CHAR. CTERETATION OF ZERCONIUM DESCREDE POWDER. 106

Sapplier: U. S. Boren Research Corporation

Quantity: I pound evaluation chipmont

i. Qualitative Analysis (weight per cett, w a)

Fe

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0.01 - 0.8

2. Quantitative Analysis (w/c)

2: 79.75 B 18.75 C 9.41 O 1.18 Total 106.09

3. Atomic Ratio

Over-all B/Zr = 1.98 Corrected B/Zr = 2.16 4. X-ray Phase Linutification

žrB_Z ZrO_Z (impurity)

5. Person Desetty

5. 96 g/cc

Phase Assay (volume per cent)
 Calculated from Composition

2:B₂ 2:O₂ 2:C 93.2 4.8 2.0

Alemic ratio corrected for metal annumed to be present as metal district and metal metacs risids.

CHARACTERIZATION OF HAFNIUM DESORIDE POWDER, LINE

Supplier: Saieldalloy Corporation (H. C. Starck, Berling

Quantity: 5 pound evaluation enigenent

 Qualitative Analysis (weight per cent w/o)

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9.4 **96**1

4

Ti 0.1 - 1.6 Cr. Co 0.01 - 0.1

2. Quantitative Analysis (w/o)

3. Alemic Ratio

Over-all B/Hf a 1.58 Corrected B/Hf a 1.58 4. X-ray Phase Identification

HIB₂ HiC (impurity) HIO₂(impurity)

5. Fower Density

-11.2 p/cc

b. Phase Assay (volume pur cent)
Calculated from Composition

1.18₂ HSC₂ HSC 86.1 7.8 6.1

Atomic rillo corrected for motal assumed to be present as metal disaste and motal movecarbide.

CHARACTERIZATION OF HAFRUM DEBORIDE POWDER, 1107

Supplier: V. S. Some Research Corporation

Chamtity: 1 Pound Evaluation Shapment

I Quilitative Amilyons fereight per cont. w/o)

ijō.

Ca. 31 0.1 - 1.0 Cr 0.0: - 0.1 6. X-ray Phase Identification

Hdb₂

HIO (impurity)

2. Omniciative Analysis (w/o)

HE + Zr 64.35 Zr 11.26 C 0.12 O 1.15 Total 99.40 5. Powder Demaity

19.25 g/cc

J. Atoms Ratio

Over-all B/Ht - 2, 14

CHARACTERIZATION OF HAFNIUM DIBORIDE POWDER, 1106

Supplier: U. S. Boran Research Corporation

Quantity 4 Pound Evaluation Shi penend

1. Qualitative Antiyete (weight per cent, w/o)

Co. Ti. Cr 0.1 - 1.0

2. Quantitative Analysis (w/o)

84 + Zr	64,68
2*	
	11.35
C	1.68
0	0,50
Total	96. 13

3. Atomic Ratio
Over-all B/M = 2,21

X-ray Phase Identification
 HiB₂

MC (ampurity)

5. Powder Denesty

4.51 g/cc

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APPENDIX U

PRODESSING VARIABLES FOR HOT PRESSING OF DIBOSIDES

A live Providing Positivy

Fabrication studies were conducted on 2 anch diameter a 5/16 anch high billets. These processes were conducted in a conventional induction bested graphite mold system which is shown schematically in Figure II-1. Other billets of 3 anch diameter were also made in the same press, but with larger furnices.

Diffusion Barriers

Channel resctions between the graphite furnice and the disorted pewder have been frequently observed. The following distances were tested as reaction limiting diffusion barriers; (a) horse satisfy wash on graphite sleeve, (b) tangeten fast, (c) pyrolytic graphite paper, (d) oilicon carbade wash and (e) pyrolytic graphite paper with an inner BN mask coating. The results for each barrier system will not be discussed in detail; it is sufficient to report that the pyrolytic graphite paper with an inner bares satisfies coating to the most affective at temperatures up to 2100°C. Above 2100°C, reaction somes are very apparent and approach the width of those found without a diffusion barrier (about 3/10 tack).

blany billeto pressed below 2100°C stall showed macrostructural evidence, an terms of grain stad, percenty level, or phase distribution, of an interaction with the BM layer, but the effects are minor compared with results obtained without such diffusion berriers. The difference compositions commanns by.C. Materials III. IV and V, revealed markedly smaller reaction layers than Materials I and II. In fact, the wast majority of the billets of these additive containing materials embilished no evidence for a die wall interaction.

C Microstructure Reproductivity

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An important aspect of this program is to obtain sufficient process control so that deplicate microstructures and compositions may be interested. Esperiment indicated that density would be the most difficult parameter to reproduce, so this property was unliked as the primary measure of reproducibility.

A number of proteings with comparable temperature-pressure-tume cycles are presented in Table 11-1. In neverticance the digrees of control appears quite good, e.g., Daley vs. Daley, Daley vs. Dale

Consequently, the hot processing process was esamined in detail to order to determine whether the process control could be improved. Temperature was accuming to be the most difficult partimeter to measure. In the temperature range but a compleyed the precision of optical temperature readings is approximately a 30°C. Bilisto proposed to the study with an intentional difference of 90°C in the present temperature can give assumable althous

so the variation introduced by the degree of procision in the temperature musicure: many the introduced of a deposit within the temperature eight tube makes even the temperature control to \$20°C difficult.

The time of present to probably the engine parameter to control. Some variation in the heating rate to encountered, which could give different effective proposing times if the heating rates were different within 250 to 100°C of the hot prototing temperature.

Presoure to not a difficult parameter to control and an automatic pressure religion when deducate accurately since relatively low lends (6 to 6 tens out of a total 75 tens excitable in the press) are required for the I tack diameter tellers. A lend variation of \$500 pounds between runs is possible. During the course of this progras: this were collected on the effect of pressure on the destification of historial st. Table link. It was consisted from those data that a change in pressure from 4000 to \$000 pet produced miser or no virialisms in density. But some lower processes between \$500 to \$000 pet acted as a threebold pressure for a uniform densitication was.

During the course of this study, covered other parameters were considered for precion control. The describention rate was used with limited success as a capacity of process to the describential process. Another technique often employed in the process to the process that is to construct the die so that, for a given quantity of process, the process train comes against a physical stop modify a clong in the pieton, at the desired describe level. However, this technique is not effective for but processes the discrete describes because of the high temperatures required in the technique. In the 1800 to 1800 to temperature range, the parts of the graphite furnises cross of a fact rate and this after the initial governors which is used to differ the step point.

Another important variable recognised in this program is the list precing further house. Three furthers are amployed and any variation in their thermal absences finishes could mainlest that is the care manner as a variation in their thermal processes transportance. The point of a measurement is early in the dismall is approximately I inches from the billet; consequently, different rates of host fore the processes tooks will effect the billet temperature. Carbon binnesses in the processes to as thermal inculators. As these blocks graphities their thermal contentivity changes which probably results in a variation is functioned at the billet value of the temperature of the discussions.

An experiment was designed to thintends the importance of further construction as a presse parameter. Three furthers were examinately rebuilt in an marry on the little manner as possible. Two providings were examinated in each furnace with the filth possion under identical interioristics, conditions, the recuits of which are provided in Table II-5. It appears that, in opins of the procautions, turnace IA behaves differently from furnace IA. It is difficult to form any conclusions concerning formule IA behavior of the law density for table BIA BISE. It is not clear whether proces to the mannerman of temperature and processe, variations in beating rate or, furnish continuation led to the variations in density in Table II-3. However, these appearance point out that the appearance is density, although greater for had present the discripts to absent 1.7% relative density, although greater variations on occur.

HOT PRESSINGS OF VARIOUS DESCRIDE COMPOSITIONS
SHOWING DEGREE OF PROCESS CONTROL

Material					Redative	Furnace
Designation	Temp.	Pressure	Tene	Denvier	Density	No.
	ÎC	poi	TVI LOD	gm¹c€	*	
IGEA DOZES	2050	4006	60	5.87	97, 4	
DALA DO JOS	2070	6000	60	5.63	₹4. €	
الأفلاق متط	2075	6000	60	5.99	99.3	
PACOD ALOI	2050	6000	30	5.80	96, 2	
IDIA DOISO	2050	6000	30	5. 65	96. 9	
BOBA DOŠII	1800	6000	120	5.54	92.6	
MAA DOJI4	1.000	6079	05 1	6.99	øģ. 5	
ISSA DON4	1890	6000	30	3.56	92.1	14
MAN DONE	1000	6800	25	5.37	49. 1	LA
ISSA DO130	1 100	6000	40	5. 98	99. 3	1A
103A D0339	1 900	4000	i 60	5. 52	41.5	18
lijos boseo	2000	4000	1 10	5.55	•3.3	18
11305 D#464	2000	4000	1 60	8.52	69. 9	1.0
nios doies	2090	4000	75	9.25	96.6	2.8
mos doles	2090	4899	**	9.26	98.6	75
VOZA D0145	1 400	4000	115	5.22	94.5	3.5
VOLA DEST	1 900	4600	110	9.20	45. I	13
voia Debiji	2000	4600	45	9.21	64. 9	18
Ateled viel	2000	4000	35	5.40	47. 6	2,38
VOLA DOSSAL	2000	4400	50	5.47	96.5	38

Ball milled.

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F Fluid energy milled.

TABLE U-2

EFFECT OF PRESSURE ON MOT PRESSURE MATERIAL II AT 1200°C

Designation	Pressure	Time	Density gra/cc	Density	Furnace No.
Mos Dolle	6000	120	10.62	99. 5	38
Dos Doser	4006	200	10.50	99.0	13
1265 D0351	1000	200	10.53	98.6	18
1905 D0151	4000	140	10.32	96.6	28
1395 D0155 c and b	4000	120	10.46	97. 9	19
LEDS 130-637	2500	110	9. 93	93.0	28

TABLE U-3 BILLET DENSITIES OF MATERIAL 103A HOT PRESSED AT 2000°C, 4000 PSI FOR 75 MIRUTES

Billet Namber	Furnaçe	Relative Dunnity &
D0 160	ia	97.4
20347	1.4	47.0
D0359	2A	96.5
DØ368	3.X	94. 1
D0 346	3.A	96.1
20344	3A	99.5
Average		97.1
Standard Deva	16144	1.7
Massacen Dev		S. 4

APPENDIX III

CHIDATION CHARACTERISTICS OF ZIRCORUM AND MAENIUM DIRORIDES CONTAINING SELECTED RARE EARTH AND ALKALINE EARTH REXABORIDE ADDITIVES

The thermal expansion conficients of vacuum hot pressed ZrB, and Hilly were determined as part of a coating study for graphite (High), to determine the extent of boride coating compatibility. Thermal expansion data were also obtained for ZrB; and Hilly doped with 20 mole per cent of various alkaline or rare earth benaborides; these additives were found to alter—the expansion coefficients of the disorides and increase the adherence of the coating.

Several of the prepared materials were submitted to Manlahs, inc. for determination of their high temperature air outdation behavior. These materials are identified in Table III-1. Outdation experiments were carried out as described in Section VIII. Briefly, cylinders having nominal dimensions of 0.35 inch diameter by 0.30 inch long were supported on ZrO₂ pads and heated to the test temperature in flowing argon. When the desired temperature was reached, air was admitted at a flow rate of 0.9 ft/sec (STP) for one hour, then argon was readmitted to displace the air and limitly the specimen was cooled to room temperature. The ZrB2 based specimens were endined at 1700 °C; the HiB2 and H'B2 based specimens were coldined at 1800 °C. After exidation, the quantifictive metallographic procedure was employed to measure the extent of conversion to oxide.

A summary of the suide conversion measurements to given in Table III-1. Representative photonic regraphs of the as-received and suidined specimens are presented in Figures III-1 through III-18. In all cases, the homeboride attitives were observed to suidine preferentially compared to the disoride phases.

Macrophotographs of the oxidized specimens are presented to Figures ill-1 and III-10. The ZrB2-base specimens all have rough, puckered outer oxides, whereas the hill ,-base specimens are grossly distorted to addition to having puckered, porous outer oxides. In comparison, ZrB2 and hill 2 yield emosth, adherent and dense outer oxides after one bour emposures at equivalent temperatures, the appearance of the hill 2 specimen in Figure III-10 is characteristic of the diborides.

The fellowing leatures were noted:

- i) preferential entitation of the hamboride phase, as evidenced by a band between the matrix and saids; this hand constate of the have deboride and voids.
- d) gross phase distribution (Figure II-12):
- 3) incidence of cracking (Figures III-F and III-101;
- di gross toccimen distortion (Figures III-9, III-14 and III-16).

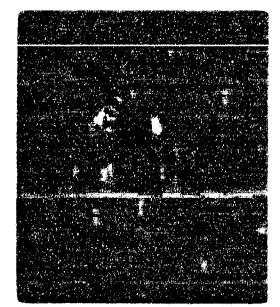
The matrix pictures exhibit comparable microstructures before and after the onidation exposure. The actable exceptions are the result of encocine occord plans; from during metallographic proparation (Figures III-Ib and III-Ib), ever-closing (Figures III-Ib and III-Ib) and lack of a representative initial structure (Figure III-Ib).

(III-1) Criscinus, J.M., et al., "High Temperature Protective Coatings of Graphite", ML-TDR-64-173, Part IV, November (1966).

The ZrB; and HfB; without additives enhibit one hour onide conversions of 12 to 13 mile at the temperatures of 1700° and 1600°, respectively. Maned upon a limited number of emperiments carried out ZrB; and HfB; shape structures containing selected benaboride additives, it is concluded that the resistance to enimetical in air at temperatures of 1700°C (ZrB; based) and 1800°C (MB; shaped is reduced by 1.5 to 6 times compared to the wealtered diborter structures.

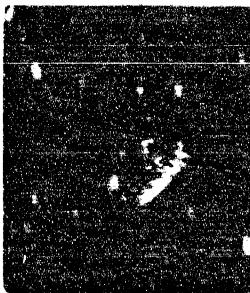


L1-1899



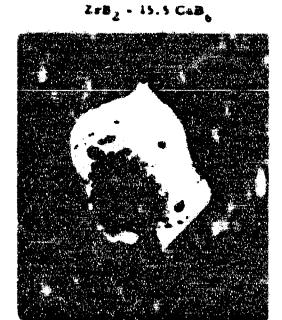
L1-2037

2r82 - 10.5 C486



L1-2626

ZrB2 - 22.5 CeB



L1-3023

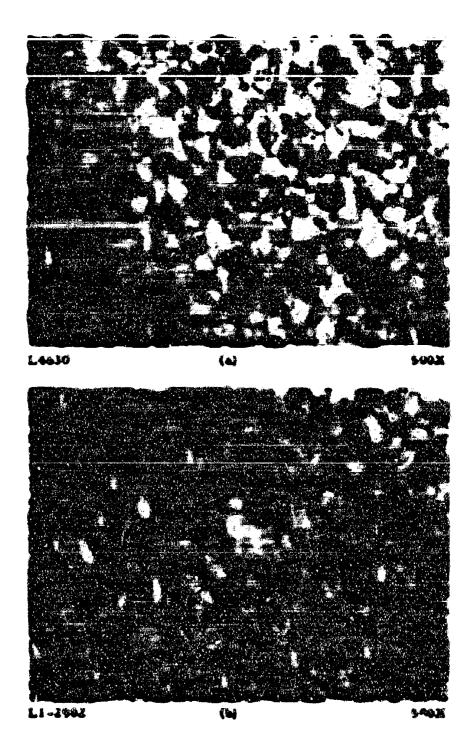
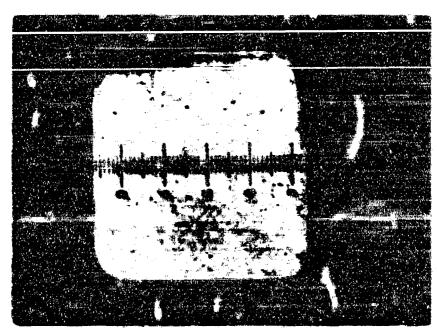
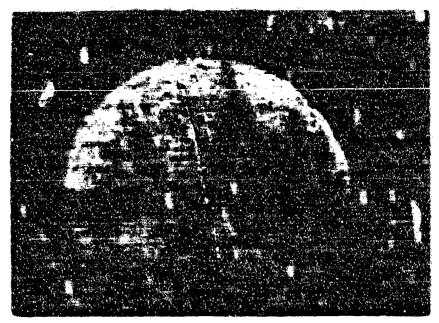


Figure Bi-1. Mairis Photomicrographs of Not Pressod Erny-10. SCall, a) As Pressod, b) Cashaed in Air for One Hour at 1700°C.



L1-1900

Lungitudino



L1-2943

Transverse

Figure III-). Resculs Photomicrographs of Not Present ZrB2-10.5 CaB6. Caduct in Air for One Hour at 1700°C (I Division = 4.86 Mile).

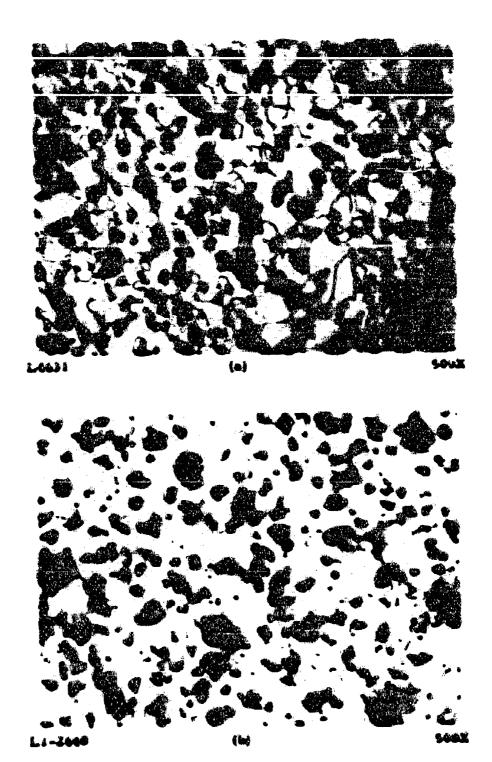
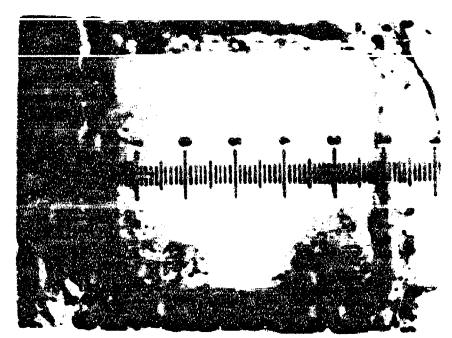


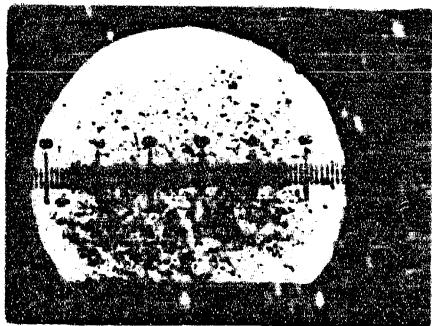
Figure Hi-t. Matrix Phatamic regraphs of Mot Provoce Erby-15.5 Capp.

a) As Provoce, b) Chickens in Air for One Hour at 1700°C.



L8-2616

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L1-1641

Tradiverse

Figure III-9. Reticule Plutemic regrephs of Set Present Zelly-19.5 Callis Outdood to Air for One Hour at 1780°C (1 Division = 6.86 bille).

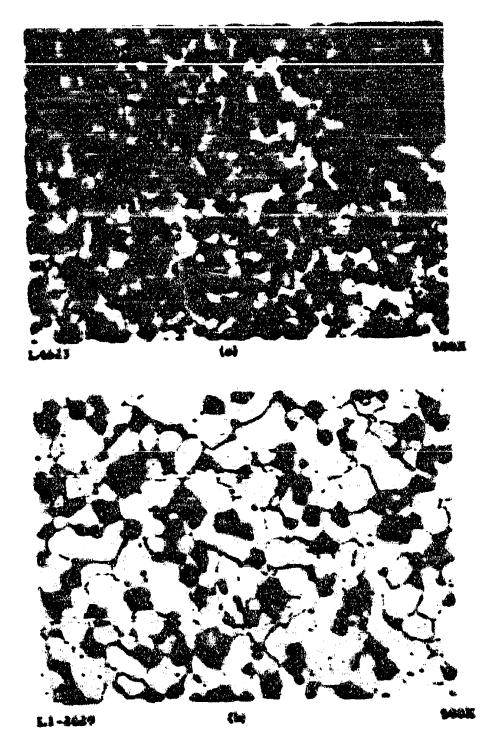


Figure 35-6. Martin Photomicrographs of this Process Erbz-\$2.5 Cobi a) Thermally epoles, b) Outlined to Air for One Hour at



L1-2627

Lungitudiani



L3-3434

Truccourses

Figure 125-7. Staticula Phananteragrapha at that Pryocod Eritz-22.5 California in Air for One Hour at 1769 C (1 Division a 4.86 bills).

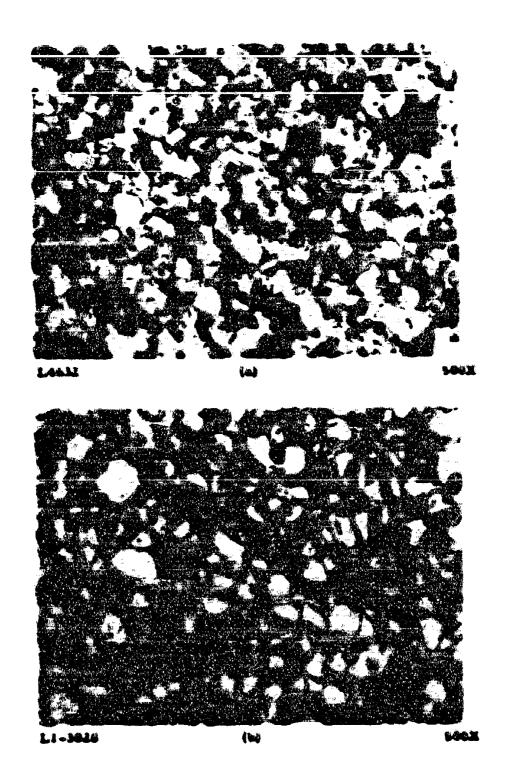
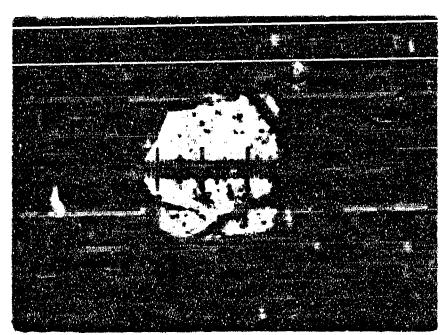
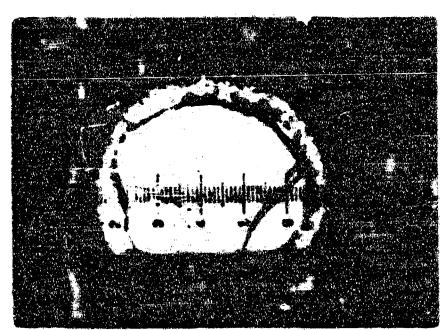


Figure 35.6. Matrix Photomicrographs of Not Pressed 2182-20.6 YB4 of Thormally Cycled. b) Onidized in Air for One Hour at 1700°C.



11-1014

Longitudinal



1.1-1019

Transperse

Figure III-9. Reticule Photomicrographs at Not Pressed 2:53-25.5 YB4: Oxidized in Air for One Hour at 1780°C (1 Division = 4.86 Mile).

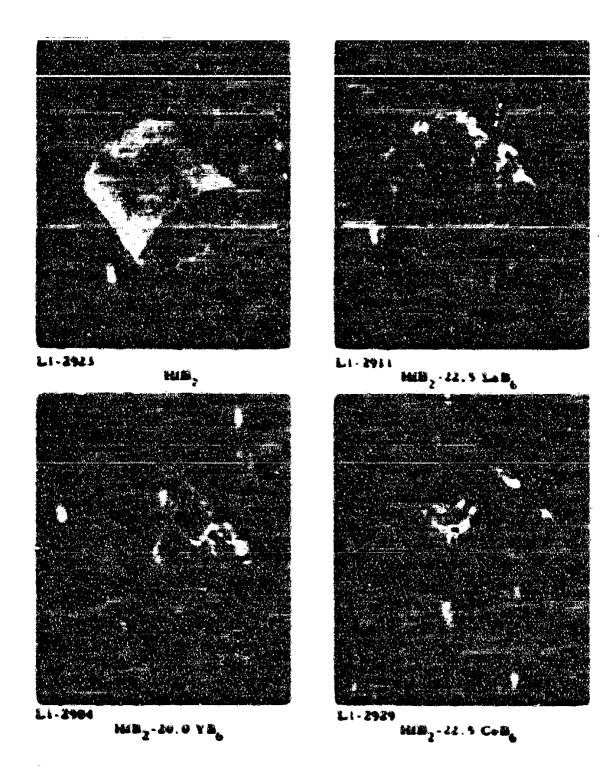
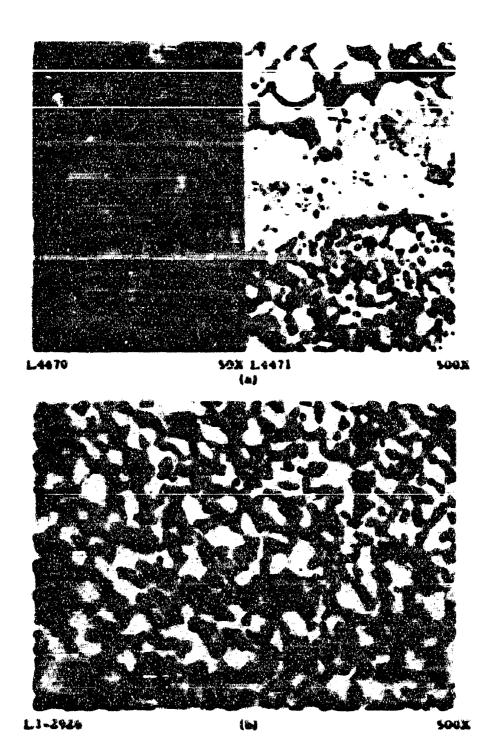
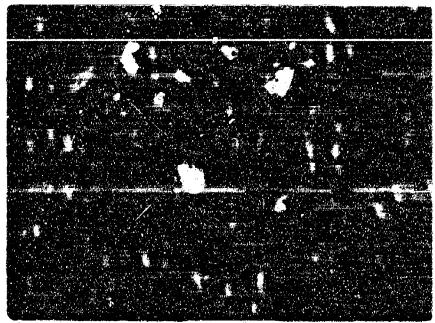


Figure III-10. Macrophotographo of H.B.-MoB. Hot Pressed Cylinders after Oxidation in Air for Oxidation at 1800°C.



Matrix Photomic regraphs of hist Pressed Hilb., a) Thermally Cycled, by Outdieed in Air for One Hour at 1850°C.



11-2924

Longitudinal



L1-2927

Transverse

Figure III-12. Reticule Photomicrographs et Het Present Milly, Quidanes to Air for One Hour at 1800°C (1 Deviates = 4.66 Mily.

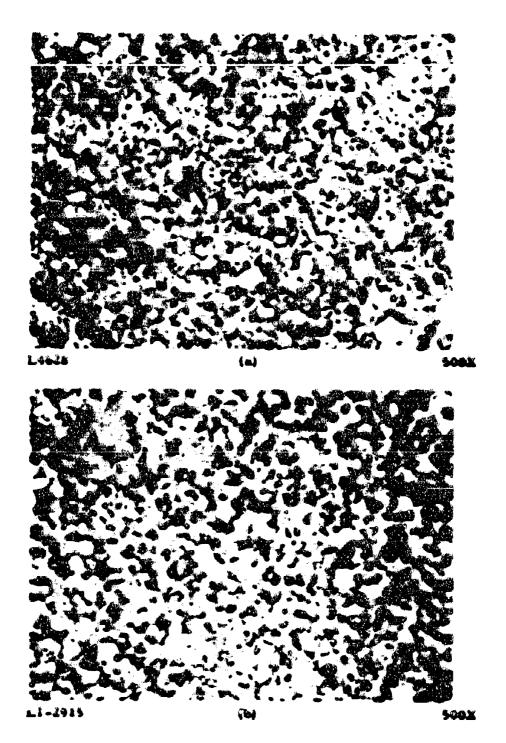
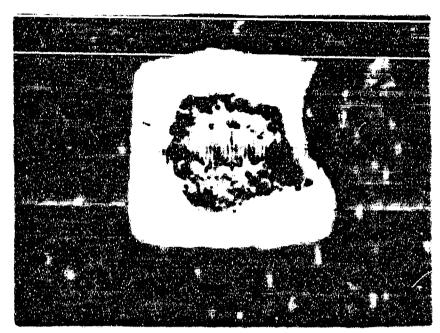
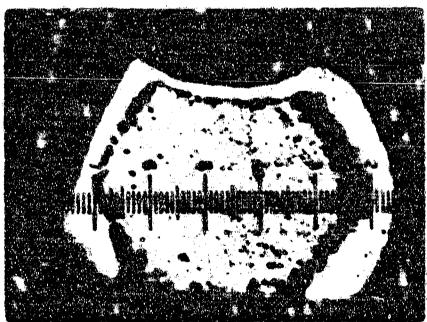


Figure III-13. Matrix Photomicrographs of Not Pressed MB2-22.5 Labo. at Thermally Cycled. b) Oxidized in Air for Oze Hour at 1800°C.



L1-2912

Longitudinal



6 1 - 7 to 1 -

Transverse

Figure III-14. Retu de Photomicrographe of Sot Presond Hilly-22.5 Lally; Occidend in Air for One Hour at 1860°C (1 Dévision = 0.86 Mile).

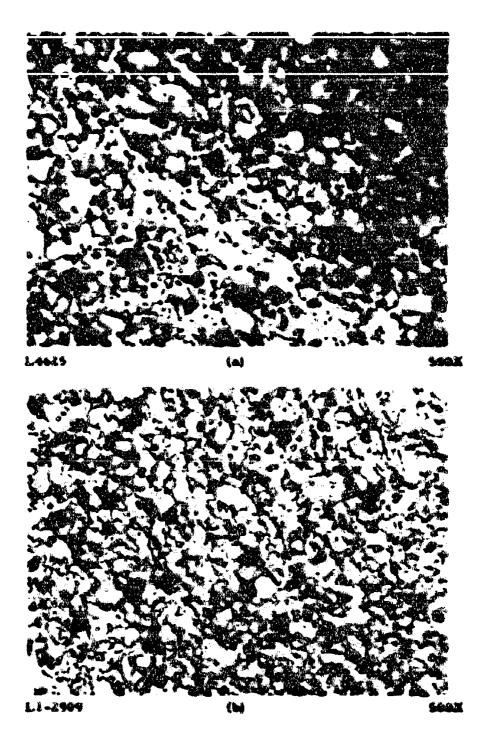
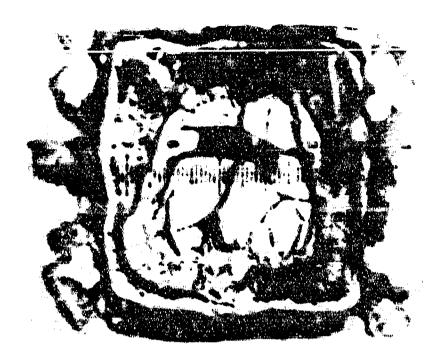
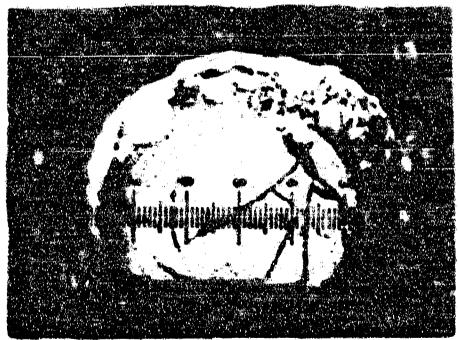


Figure III-15. Matrix Photomicrographs of Sot Pressed MB₂ - 39.9 YB₄
a) Thermally Cycled. b) Outdieed in Air for One Sour at
1866°C.



£1-2905

Longitudine



F1-5470

T consverse

Figure III- to. Materiale Photomic regraphs of Mas Pressed Militz - 20.0 Yilli.

Condition in Air for One Mous at 1800 C (1 Division = 4.86 Mile).

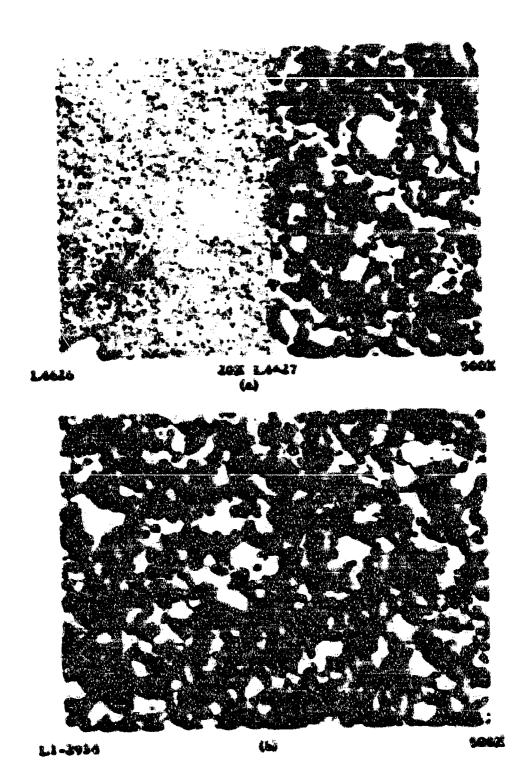
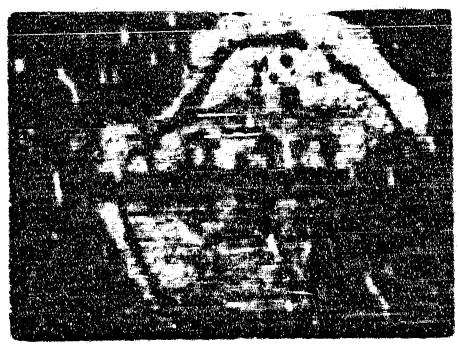


Figure M-17. Matrix Photomicrographs of Met Pressed Milly - 22.5 Calls.
a) Thermally Cycles, by Guidland in Air for Che Hour et
1800°C.



L1-2910

Leavining



Townson Lake

Figure 155-18. Settenio Pharemic regaugho of Mit Proposed Milly - 21.9 Cellis. Cuidined to Air for Can Mour at 1860°C (One Division = 4.86

TABLE III-I COMPOSITIONS AND DENSITIES OF HOT PRESSED DECREE + HERABORIDE RPECIMENS

Ideatification Ho.	Conditions	Neminal Cemposition	Dessity	C Theoretical Density
294-24-654	W	2 #82-10.5 Cas	5.47 g/cc	lav
292-24-50A	HP	2:52-15.5 GaB	5.25	169
294-28-1	TC	2 8 8 2 - 22 . 5 Call	4.50	100
292-28-9	TC	Z=2,-10.0 YB	5.04	100
141-14-91	TC	Man .	8.50	76
292-20-41	TC	Ma _z -lä. 5 Lab	6.93	100
191-15-51	TC	148 2-40.0 YE	6.46	100
292-29-54	TC	MEB22.5 CoB_	6.65	96

MF-as hat present. TC-affer a thormal cycle from room termorature to 1890*_2108*C.

*Geografican to make per cost.

TABLE BL-3 and the last parameter and a second second (the Year Oz in Air at 0.9 8/esc-STF)

	n		•			
.		· · · · · · · · · · · · · · · · · · ·				
			TABL	LE 85-3		
		mer se	and H	-		un Tübin i E
		(100 84	ner Oz (m A	lis et 0. 9	@/ sec-5TF)	
					Calde	Average One Hour
	Maderia		Tome.	Teme	Courochian m iis	Campo printer
	and the second s				Tage das	
	2:03,-18.5 Call,	461	1710	**	27. 3/ 33. 4	30.4
	Selly-10.5 Colly	696	1760	40	22.2/25.8	24.0
	2402-43.5 Coll.	484	1715	44	26.7/21.1	16.9
	246, -40.0 YB.	444	1706	60	63. 6/36. 4	45. 9
		461	2610	•	36. 6/19. 5	19.1
		484	1690	60	25. 3/25. 3	25.3
	-A. 0 VA	444	1610	##	30. 2/17. 9	14.0
	eme-11.9 Colle	444	3400	60	Specimen oc	racely disturbed
	· many					
	Congression in a		<u> څخه د د</u>			
			**			
				11 -11		

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manus to sum tent y - \$ - mg	UNC LASSIFIED
Zi Erse Mreet Cambridge, Mass.	N/A
distant viria	N/A
Tributal Da. Litteritry Report	t. March 1966 to Soptember 1967
Clougherty, Edward V., Ralie	t, March 1966 to Soptember 1967 sh. David and Peters, Edward T.
Tributal Da. Lineality Repor	i, March 1966 to Soptember 1967
Clougherty, Edward V., Rate	sh. David and Peters. Edward T. 19 *2*** of Peece These or mark 28
Clougherty, Edward V., Raise July Took	sh. David and Peters, Edward T.
Chougherty, Edward V., halis If 1008 17:30:1008	sh. David and Peters, Edward T. 19 *2*** of Factor 75 on or next 28
Clougherty, Edward V., Ralie July 1568	sh. David and Peters, Edward T. 19 *2" at the or made. The se or news. 28

The outdance, mechanical and physical properties of zero manus diboride and halinium diburids and composites propared from these diburides with approperate additives, have been determined as a function of composition, mit restructure and test temperature. The compressive were designed to enhance amidelion requisioner, strongth and thermal stress resistance without sacrificing high temperature stability, the prescript additives were allow carbide or graphies.

Several hundred dibertie billets, in cises from two saches dismeter to ass teches uquers, were inbricated by conventional hot pressing. All hot presse bilists were subjected to unionally modestructive testing correlations and time identification criteria. A unique role for ceremic additives has evalued in enhencing the inherentality of disposide materials and producing time grained crack irne billetë. Ali pewder mittertële ënd het present mëcrestructures subjected to proporties evaluations have undergone entensive characterization through quilitative and questilative chomecal implyors, phase analyses and grain size and disably measurements.

An employeery therecation atters was instanted to develop alternate w to hot presente for producing dissor diburide materials; but forging, plasma apreying and contering are boung excited. In addition, the but previous of diborres compositions confishing additives such as MC whisters, carbon tilentics or tringates filaments to being studied.

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